

# RL78 Family EEPROM Emulation Software RL78 Type 01 User's Manual

RENESAS Microcontrollers RL78/G2x

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### Corporate Headquarters

TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan

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# General Precautions in the Handling of Microprocessing Unit and Microcontroller Unit Products

The following usage notes are applicable to all Microprocessing unit and Microcontroller unit products from Renesas. For detailed usage notes on the products covered by this document, refer to the relevant sections of the document as well as any technical updates that have been issued for the products.

1. Precaution against Electrostatic Discharge (ESD)

A strong electrical field, when exposed to a CMOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop the generation of static electricity as much as possible, and quickly dissipate it when it occurs. Environmental control must be adequate. When it is dry, a humidifier should be used. This is recommended to avoid using insulators that can easily build up static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors must be grounded. The operator must also be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions must be taken for printed circuit boards with mounted semiconductor devices.

2. Processing at power-on

The state of the product is undefined at the time when power is supplied. The states of internal circuits in the LSI are indeterminate and the states of register settings and pins are undefined at the time when power is supplied. In a finished product where the reset signal is applied to the external reset pin, the states of pins are not guaranteed from the time when power is supplied until the reset process is completed. In a similar way, the states of pins in a product that is reset by an on-chip power-on reset function are not guaranteed from the time when power is supplied until the power reaches the level at which resetting is specified.

3. Input of signal during power-off state

Do not input signals or an I/O pull-up power supply while the device is powered off. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements. Follow the guideline for input signal during power-off state as described in your product documentation.

4. Handling of unused pins

Handle unused pins in accordance with the directions given under handling of unused pins in the manual. The input pins of CMOS products are generally in the high-impedance state. In operation with an unused pin in the open-circuit state, extra electromagnetic noise is induced in the vicinity of the LSI, an associated shoot-through current flows internally, and malfunctions occur due to the false recognition of the pin state as an input signal become possible.

5. Clock signals

After applying a reset, only release the reset line after the operating clock signal becomes stable. When switching the clock signal during program execution, wait until the target clock signal is stabilized. When the clock signal is generated with an external resonator or from an external oscillator during a reset, ensure that the reset line is only released after full stabilization of the clock signal. Additionally, when switching to a clock signal produced with an external resonator or by an external oscillator while program execution is in progress, wait until the target clock signal is stable.

6. Voltage application waveform at input pin

Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between  $V_{IL}$  (Max.) and  $V_{IH}$  (Min.) due to noise, for example, the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between  $V_{IL}$  (Max.) and  $V_{IH}$  (Min.).

7. Prohibition of access to reserved addresses

Access to reserved addresses is prohibited. The reserved addresses are provided for possible future expansion of functions. Do not access these addresses as the correct operation of the LSI is not guaranteed.

8. Differences between products

Before changing from one product to another, for example to a product with a different part number, confirm that the change will not lead to problems. The characteristics of a microprocessing unit or microcontroller unit products in the same group but having a different part number might differ in terms of internal memory capacity, layout pattern, and other factors, which can affect the ranges of electrical characteristics, such as characteristic values, operating margins, immunity to noise, and amount of radiated noise. When changing to a product with a different part number, implement a system-evaluation test for the given product.

# How to Use This Manual

### Readers

This manual is intended for users who wish to understand the features of the RL78 microcontrollers EEPROM Emulation and to use the EEPROM Emulation Software (EES) RL78 Type 01 in designing and developing application systems.

### Purpose

This manual is intended to give users an understanding of the methods for using the EEPROM Emulation Software (EES) RL78 Type 01 to reprogram the data flash memory in the RL78/G2x microcontroller (i.e. write constant data by the application).

### Organization

This manual is separated into the following sections.

- Overview
- System Configuration
- EEPROM Emulation
- Using EEPROM Emulation
- User Interface
- Sample Programs
- Creating a Sample Project for EES RL78 Type 01

### · How to Read this Manual

It is assumed that the readers of this manual have general knowledge in the fields of electrical engineering, logic circuits, microcontrollers, C language, and assemblers.

To understand the hardware functions of the RL78/G2x:

- Refer to the User's Manual of the target RL78/G2x device.

### Conventions

- Data significance: Higher digits on the left and lower digits on the right
- Active low representations:  $\overline{\times\times\times}$  (overscore over pin and signal name)
- Note: Footnote for item marked with Note in the text
- Caution: Information requiring particular attention
- Remark: Supplementary information
- Numeric representation:

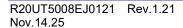
Binary: xxxx or xxxxB

Decimal: xxxx

Hexadecimal: xxxxH or 0xxxxx

- Prefixes indicating power of 2 (address space and memory capacity):

K (kilo) 
$$2^{10} = 1024$$
  
M (mega)  $2^{20} = 1024^2$ 





### • Related Documents

The related documents indicated in this publication may include preliminary versions. However, preliminary versions are not marked as such.

No	Document Title	Document Number
1	RL78/G23 User's Manual Hardware	R01UH0896EJ
2	RL78/G22 User's Manual Hardware	R01UH0978EJ
3	RL78/G24 User's Manual Hardware R01UH0961EJ	
4	RL78 Family Renesas Flash Driver RL78 Type 01	R20UT4830EJ
	User's Manual	
5	E1/E20/E2 Emulator, E2 Emulator Lite Additional Document for User's Manual (Notes on Connection of RL78)	R20UT1994EJ
6	Renesas Flash Driver, EEPROM Emulation Software	R20UT5631EJ
	Target MCU List for RL78	

# **Table of Contents**

1. Over	view	10
1.1 O	utline	10
1.1.1	Purpose	10
1.2 Co	ontents	10
1.3 Fe	eatures	11
1.4 O <sub>I</sub>	perating Environment	12
1.5 Pc	pints for Caution	13
1.6 C	Compiler Definitions	16
2 Syste	em Configuration	18
-	/stem Configuration	
•	ES Architecture	
2.2.1	EES Block	
2.2.2	EES Pool	
	e Structure	
2.3.1	Folder Structure	
2.3.2	List of Files	
	esources of RL78/G2x	
2.4.1	Memory Map	
2.4.2	Allocation of Blocks	
2.4.3	Flash Operation Mode	
2.5 Re	esources Used in EES RL78 Type 01	
2.5.1	Sections Used in EES RL78 Type 01	
2.5.2	Software Resources	26
2 EEDI	ROM Emulation	27
	pecifications of EEPROM Emulationutline of Functions	
	ES Pool	
3.3.1	EES Pool State	
3.3.2	Structure of EES Block	
3.3.3	EES Block Header	
3.3.4	Structure of Stored Data	
3.3.5	EES Block Overview	
0.0.0	LEG Block Gverview	
•	g EEPROM Emulation	
	umber of Stored User Data Items and Total User Data Size	
4.2 Ini	itial Values to be Set by User	36
5. User	Interface	39
	equest Structure (st ees request t) Settings	
5.1.1	User Write Access	
5.1.2	User Read Access	
_	st of API Functions and R_EES_Execute Function Commands for the EES	
5.2.1	API Functions for the EES	
5.2.2	Commands for R_EES_Execute Function	
5.2.3	RFD control API functions for EES	
	ate Transitions	
	asic Flowchart	
	ommand Operation Flowchart	
	ata Type Definitions	

5.6.1	Data Types	
5.6.2	Global Variables	
5.6.3 5.7 Spe	Enumerationsecifications of API Functions	
5.7 Spe	Specifications of API Functions for EES RL78 Type 01	
5.7.2	RFD Control API Functions for EES	
5.7.3	Internal Functions for the EES	
6. Samp	le Programs	67
6.1 File	Structure	67
6.1.1	Folder Structure	67
6.1.2	List of Files	68
6.2 Dat	a Type Definitions	68
6.2.1	Macro Defines	68
	nple Program Functions	
6.3.1	Sample Program for Controlling the EEPROM Emulation	
-	ecifications of Sample Program Functions	
6.4.1	Sample Program Functions for Controlling the EEPROM Emulation	
6.5 Pre	cautions in Case of Using Sample Program	77
7. Creati	ng a Sample Project for EES RL78 Type 01	78
7.1 Cre	ating a Project in the Case of Using a CC-RL Compiler	78
7.1.1	Example of Creating a Sample Project	
7.1.2	Example of Registration of Target Folders and Target Files	
7.1.3	Build Tool Settings	
7.1.4	Debug Tool Settings	
	ating a Project in the Case of Using IAR Compiler	
7.2.1	Example of Creating a Sample Project	
7.2.2	Example of Registration of Target Folders and Target Files	
7.2.3	Integrated Development Environment(IDE) Settings	
7.2.4	Linker Configuration File(.icf) Settings	
7.2.5	On-chip Debug Settings	
	nfigurations Modify Procedure for Changing Device	
7.3.1	CC-RL Compiler Environment Settings	
7.3.2	IAR Compiler Environment Settings	
7.3.3	Modifying the Sample Program (Common to CC-RL Compiler and IAR Compiler)	130
8. Revisi	on History	135
8.1 Mai	or Modifications in this Revision	135

# **Abbreviations**

Abbreviation	Description	
EES	EEPROM Emulation Software	
RFD	Renesas Flash Driver	
API	Application Program Interface	
BGO	Background Operation Instructions in the code flash memory can be executed during reprogramming of the data flash memory.	
RAM	Random Access Memory Randomly accessible volatile memory. It is memory for holding values that are to be changed during program execution.	
ROM	Read-Only Memory  Non-volatile memory. It is memory whose contents cannot be changed. The code flash memory may be called ROM.	

# **Terminology**

Terminology	Description
Code flash memory	Flash memory for storing application code and constant data.
	Note that this memory may be abbreviated as "CF" in this document.
Data flash memory	Flash memory for storing data.
	Note that this memory may be abbreviated as "DF" in this document.
Extra area	Generic name of the configuration setting area, security setting area,
	lock protection area, and boot swap setting area.
Flash memory sequencer	The RL78 microcontroller has a dedicated circuit for controlling the flash memory. This circuit is called the flash memory sequencer in this document. The flash memory sequencer consists of the code/data flash area sequencer, which reprograms the code flash area or data flash area, and the extra area sequencer, which reprograms the extra area.
Flash memory control mode	The flash memory sequencer has the following modes, which indicate the programming enabled or disabled state.
	- Code flash memory programming mode
	- Data flash memory programming mode
	- Non-programmable mode
Code flash memory programming mode	The code flash memory (and extra area) can be reprogrammed in this mode.
Data flash memory programming mode	The data flash memory can be reprogrammed in this mode.
Non-programmable mode	The flash memory (and extra area) cannot be reprogrammed in this mode.
Self-programming	A method of reprogramming the flash memory by executing a user program instead of using an external flash memory programming tool.
RFD function	A generic term for the functions offered by the RFD.
EES function	A generic term for the functions offered by the EES.
RFD control functions for EES	A generic term for the RFD control functions offered by the EES.
EES Block	An abbreviation of blocks that the EEPROM emulation software accesses. In this user's manual, EEPROM emulation blocks are hereafter referred to as EES block.

## 1. Overview

### 1.1 Outline

EEPROM emulation is a feature used to store data in the on-board flash memory in the same way as EEPROM. In EEPROM emulation, EEPROM Emulation Software RL78 Type 01 operates the Renesas Flash Driver (RFD) RL78 Type 01. And RFD writes and reads the data flash memory.

EEPROM Emulation Software RL78 Type 01 (hereafter called EES RL78 Type 01) is software for reprogramming the data flash memory in the RL78/G2x.

For information on Renesas Flash Driver (RFD) RL78 Type 01, refer to the RL78 Family Renesas Flash Driver RL78 Type 01 User's Manual.

### 1.1.1 Purpose

This manual is intended to give users an understanding of the methods for using the EEPROM Emulation Software (EES) RL78 Type 01 to reprogram the data flash memory in the RL78/G2x microcontroller. (i.e. write constant data by the application).

### 1.2 Contents

The API function of EES RL78 Type 01 is called from the user program. And reprogramming of the data in the EEPROM emulation block (EES block) placed into the data flash memory is possible.

The EES RL78 Type 01 package includes the following.

- · This user's manual
- Source code files of EES RL78 Type 01 for controlling the data flash memory incorporated in the RL78/G2x.
- Sample program for operating the EES RL78 Type 01.

### 1.3 Features

EES RL78 Type 01 calls API functions for RFD RL78 Type 01 to operate the flash memory sequencer. Each API function of EES RL78 Type 01 consists of a single sub-function or two or more sub-functions, and the necessary processing is implemented by combinations of individual sub-functions and user processing. Such a configuration is adopted so as to flexibly handle processing dependent on the user application, such as, timeout processing in which the timeout value varies with the conditions of user application program execution.

Figure 1-1 shows the flash memory control by the user application using the API functions of EES RL78 Type 01.

EES RL78 Type 01 provides sample programs of the processing that is implemented by combinations of two or more API functions and user programs. Refer to the sample programs when embedding EEPROM emulation processing in the user application.

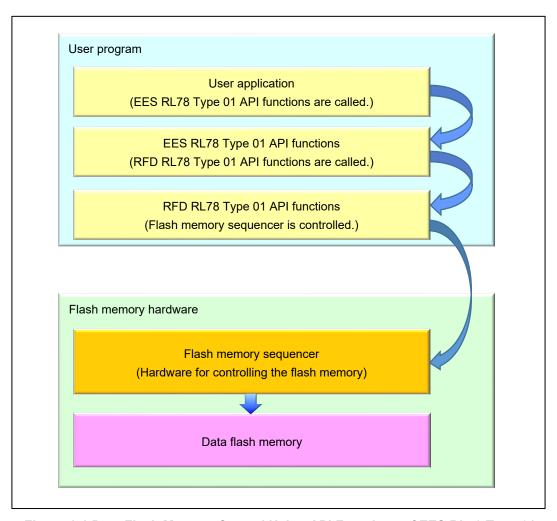


Figure 1-1 Data Flash Memory Control Using API Functions of EES RL78 Type 01

### 1.4 Operating Environment

### Host Computer

The operation of EES RL78 Type 01 does not depend on the host computer but the appropriate environment for the C compiler package, debugger and emulator must be prepared. (EES RL78 Type 01 was developed and tested on Windows10 Enterprise.)

### • C Compiler Package

Table 1-1 shows the target C compiler packages for EES RL78 Type 01.

Table 1-1 The Target C Compiler Packages for EES RL78 Type 01

Compiler	IDE (Integrated Development Environment)	Manufacturer	Version
CC-RL	CS+ or e <sup>2</sup> studio	Renesas Electronics	V1.10 or later
IAR	IAR Embedded Workbench <sup>®</sup> for Renesas RL78	IAR Systems®	V4.21 or later
LLVM	e <sup>2</sup> studio	(Open Source Software)	V10.0.0.202306 or later

Note. Integrated development environment(IDE) and compiler must support the target device.

### Emulator

Table 1-2 shows the emulator on which the operation of EES RL78 Type 01 was confirmed.

Table 1-2 Emulator on which EES RL78 Type 01 Operation was Confirmed

Emulator	Manufacturer
E2 emulator	Renesas Electronics
E2 emulator Lite	Renesas Electronics

# Target MCU

RL78/G23, RL78/G22, RL78/G24

### • EEPROM Emulation Software (EES)

Table 1-3 shows the EEPROM Emulation Software (EES) supported by this manual.

Table 1-3 The EEPROM Emulation Software (EES) Supported by this Manual

Package	Manufacturer	Package Version
EES RL78 Type 01	Renesas Electronics	V1.21

Note. Use the version of RFD RL78 Type 01 listed in Table 1-4.

### Renesas Flash Driver (RFD)

Table 1-4 shows the Renesas Flash Driver (RFD) used for EES RL78 Type 01.

Table 1-4 The Renesas Flash Driver (RFD) Used for EES RL78 Type 01

Package	Manufacturer	Package Version
RFD RL78 Type 01	Renesas Electronics	V1.21

### 1.5 Points for Caution

EEPROM emulation is achieved by using a feature for manipulating the RL78/G2x microcontroller data flash memory. Therefore, it is necessary to note the following.

- (1) All EES code and constants must be placed in the same 64 KB flash block such that EES code and constants do not extend across a 64-KB boundary. (It dependent on each compiler.)
- (2) The EES must be initialized by the R\_EES\_Init function before any EES function is executed.
- (3) The data flash memory cannot be read during data flash memory operation by the EES.
- (4) It is not allowed to call any RFD function during a command execution of the EES.
- (5) It is not allowed to call any RFD control functions for EES directly from other than the EES.
- (6) Do not execute STOP mode or HALT mode processing while the EEPROM emulation is being used. If it is necessary to execute STOP mode or HALT mode processing, be sure to execute all of the processing up to and including the R\_EES\_Close function to finish EEPROM emulation.
- (7) The watchdog timer does not stop during execution of the EES.
- (8) Do not destroy the request structure (st\_ees\_request\_t) during command execution.
- (9) Initialize the argument (RAM) that is used by the EEPROM emulation software function. When not initialized, a RAM parity error is detected and the RL78/G2x microcontroller might be reset. For a RAM parity error, refer to "User's Manual: Hardware" of a target device.
- (10) All members of the request structure (st\_ees\_request\_t) must be initialized once before a EES command is executed. If any unused member exists in the request structure (st\_ees\_request\_t), set a desired value for the member. If any member is not initialized, the RL78/G2x microcontroller may be reset due to a RAM parity error. For details, refer to "User's Manual: Hardware" of a target device.
- (11) The EES does not support multitask execution. Do not execute the EES functions during interrupt processing.
- (12) After the R\_EES\_Close function have been executed, the requested command and ongoing command stop and cannot be resumed. Before calling the R\_EES\_Close function, finish all ongoing commands.
- (13) Do not operate the code flash memory by RFD RL78 Type 01 while the EEPROM emulation is executed. Before the code flash memory is operated, be sure to execute a "R\_EES\_Close function" necessary in order to finish the EEPROM emulation. When using EEPROM emulation after executing the code flash memory operations using the RFD RL78 Type 01, it is necessary to start processing from the initializing function (the R\_EES\_Init function).
- (14) Before starting the EEPROM emulation, be sure to start up the high-speed on-chip oscillator first. The high-speed on-chip oscillator must also be activated when using the external clock.

(15) No checksum is added to user data. If a checksum is needed, add it to user data and check through the user program.

- (16) Do not operate the data flash control register (DFLCTL) during execution of the EES.
- (17) To use the data flash memory for EEPROM emulation, it is necessary to execute the R\_EES\_ENUM\_CMD\_FORMAT command upon first starting up to initialize the data flash memory and make it usable as EES blocks.
- (18) In order to use the EES, it is recommended to set at least 3 blocks in the EES block (virtual block).
- (19) Do not destroy the EES blocks (virtual block) by the user program operating the data flash memory using the RFD from other than the EES.
- (20) EES descriptor is changed, the EEPROM emulation can no longer be executed. In that case, the EES pool must be formatted by the R\_EES\_ENUM\_CMD\_FORMAT command in addition to initialization of EES. When adding data, however, the EEPROM emulation can be continuously executed.
- (21) About an operating frequency of RL78/G2x microcontroller and an operating frequency value set by the initializing function (R\_EES\_Init), be aware of the following points:
  - When using a frequency lower than 4 MHz as an operating frequency of RL78/G2x microcontroller, only 1 MHz, 2 MHz and 3 MHz can be used (frequencies other than integer values like a 1.5 MHz cannot be used). Also, set an integer value 1, 2, or 3 to the operating frequency value set by the initializing function.
  - When using a frequency of 4 MHz or higher Note as an operating frequency of RL78/G2x microcontroller, a certain frequency can be used as an operating frequency of RL78/G2x microcontroller.
  - This operating frequency is not the frequency of the high-speed on-chip oscillator. Note: For a maximum frequency, refer to "User's Manual: Hardware" of a target device.
- (22) The precautions in the case of debugging self-programming with an on-chip debugger In the case which debugs self-programming with an on-chip debugger, because 128 bytes of area is used from the top address of RAM when a debugger is executed, it is necessary to vacate this area. Additionally, in case CS+ or e² studio is used as the development environment, the debugger settings need to be configured to use flash self-programming.
  - Example settings for CS+:

    On the project, select "Connect Settings" tab from "RL78 E2 [Lite] (Debug Tool)", and set "Yes" to "Flash" "Using the flash self-programming".
  - Example settings for e² studio:
     On the project, select "Property" "Run/Debug Settings", and edit the target "HardwareDebug" setting.
     On the displayed screen, select "Debugger" tab "Connection Settings" tab, and set "Yes" to "Flash" "Program uses flash self-programming".
  - Example settings for IAR Embedded Workbench:

    Put a check mark on "Hardware Setup" of the "Emulator" menu. Select "Download and Debug" from

    "Project" menu. And if "E2/E2Lite Hardware Setup" screen is displayed, check to "Use flash self

    programming" of the item of "Flash".

(23) The precautions in the case of executing the data copy from ROM to RAM, when using CC-RL compiler. When using CC-RL compiler, the Sample\_INITSCT\_EES function is called from the main function of main.c file. This function copies the data for EES RL78 Type01 to RAM from ROM.

However, the following setting will be necessary if this processing is executed by the start-up routine in the cstart.asm file which is a CC-RL compiler function.

(CC-RL compiler function: "Initialization of RAM area sections by using an initialization table [V1.12 or later]")

- Set "-ram\_init\_table\_section" by linker.
- Set "\_\_USE\_RAM\_INIT\_TABLE" to the column which defines the macro of assemble options.
- \* For details, please refer to the user's manual of CC-RL compiler.

Because "copy processing from ROM to RAM" of a Sample\_INITSCT\_EES function duplicates in this case, It is necessary to set same [Macro definition] as "Compiler Option", and to cancel processing of a Sample\_INITSCT\_EES function.

- Set "\_\_USE\_RAM\_INIT\_TABLE" to the column which defines the macro of compiler options.

### 1.6 C Compiler Definitions

The definitions of the target compiler written in the header file (r\_ees\_compiler.h) for EES RL78 Type 01 are shown below.

The definitions differ between compilers. The "r\_ ees\_compiler.h" file is used to identify the current compiler and the definitions for the target compiler are used.

```
Definition of CC-RL compiler:
    "__CCRL__" is defined.
    #define EES_COMPILER_CC (1)
Definition of IAR compiler:
    "__IAR_SYSTEMS_ICC__" is defined.
    #define EES_COMPILER_IAR (2)
Definition of LLVM compiler:
    "__Ilvm__" is defined.
    #define EES_COMPILER_LLVM (3)
```

< Descriptions in the r\_ees\_compiler.h file >

```
/* Compiler definition */
#define EES_COMPILER_CC
                                (1)
#define EES COMPILER IAR
                                (2)
#define EES COMPILER LLVM
                                (3)
#if defined ( llvm )
    #define EES COMPILER EES COMPILER LLVM
#elif defined (__CCRL__)
    #define EES COMPILER EES COMPILER CC
#elif defined ( IAR SYSTEMS ICC )
    #define EES_COMPILER EES_COMPILER_IAR
#else
   /* Unknown compiler error */
    #error "Non-supported compiler."
#endif
/* Compiler dependent definition */
#if (EES COMPILER CC == EES COMPILER)
    #define R EES FAR FUNC
                                                       far
#elif (EES_COMPILER_IAR == EES_COMPILER)
    #define R EES FAR FUNC
                                                        far func
#elif (EES COMPILER LLVM == EES COMPILER)
    #define R_EES_FAR_FUNC
                                                       __far
#else
    /* Unknown compiler error */
    #error "Non-supported compiler."
#endif
```

### C Compiler Options

The contents of the C compiler option setup which normal operation can be checking are shown below.

- [CC-RL(CS+)]

Major compile options: -cpu=S3 -g -g\_line -lang=c99

- [IAR(IAR Embedded Workbench)]

Major compile options:

- --core s3 --calling\_convention v2 --code\_model far --data\_model near -e -OI --no\_cse --no\_unroll --no\_inline --no\_code\_motion --no\_tbaa --no\_cross\_call --no\_scheduling --no\_clustering --debug
- [LLVM(e<sup>2</sup> studio)]

Major compile options:

- -Og -ffunction-sections -fdata-sections -fdiagnostics-parseable-fixits -Wunused -Wuninitialized -Wall
- -Wmissing-declarations -Wconversion -Wpointer-arith -Wshadow -Waggregate-return -g -mcpu=s3

# 2. System Configuration

# 2.1 System Configuration

The EES offers interface for accessing the data flash area(the EES pool) defined by the user. The API functions provided by EES accesses the EES pool via the RFD control functions for EES, or RFD.

The arrows shown in the Figure 2-1 below indicate the flow of processing.

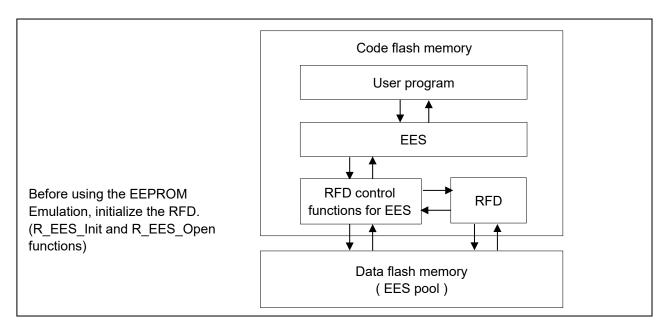


Figure 2-1 System Configuration

### 2.2 EES Architecture

This chapter describes the EES architecture required for the user to rewrite data flash memory (the EES pool) by using the EES.

### 2.2.1 EES Block

EES uses multiple blocks of the data flash memory as one virtual block. This area is called an EES block. The size of a block of the data flash memory mounted in RL78/G2x is 256 bytes. When EES block size is set to a 1K-byte, 4 blocks of the data flash memory are gathered, and EES handles as a 1K-byte's virtual block. Moreover, when EES block size is set to a 2K-byte, 8 blocks of the data flash memory are gathered, and EES is handled as a 2K-byte's virtual block.

Be sure to set the size of an EES block in consideration of the size and the total number of blocks of the data flash memory mounted in the target device. Refer to "4.2 Initial Values to be Set by User" for the setting method. The schematic diagram for the EES block 0 when 1 K-byte or 2 K-byte are set by EES block is shown in "Figure 2-2 Schematic diagram of EES block 0".

Maximum number of blocks that can be set in the EES block of a product equipped with 8 Kbytes of data flash memory:

When the EES block size is set to 1 K-byte, the maximum number of blocks is 8.

When the EES block size is set to 2 K-byte, the maximum number of blocks is 4.

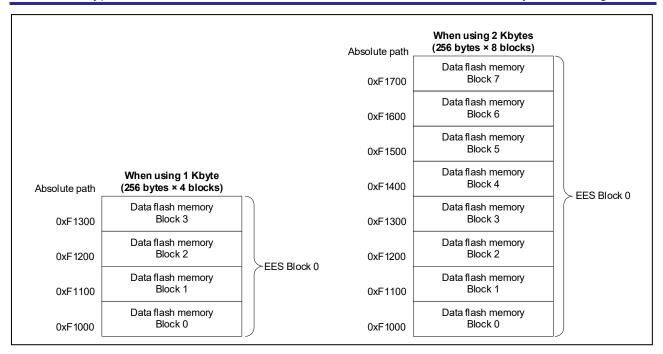


Figure 2-2 Schematic diagram of EES block 0

### 2.2.2 EES Pool

The EES pool is a user-defined data flash area that is accessible by the EES. The user program can access the data flash only by using this EES pool in the data flash via the RFD control functions for EES and the EES. The EES pool size must be specified with the number of size in the data flash of the target device. For the procedure to specify the number of blocks, see section 4.2 Initial Values to be Set by User.

Figure 2-3 shows an example of pool configuration for a device with 8 Kbytes data flash memory.

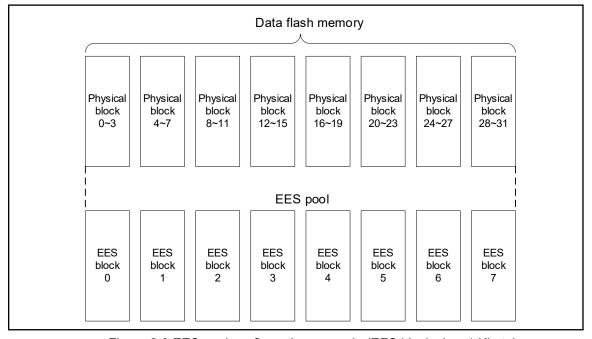


Figure 2-3 EES pool configuration example (EES block size: 1 Kbyte)

### 2.3 File Structure

### 2.3.1 Folder Structure

Figure 2-4 shows the folder structure of EES RL78 Type 01.

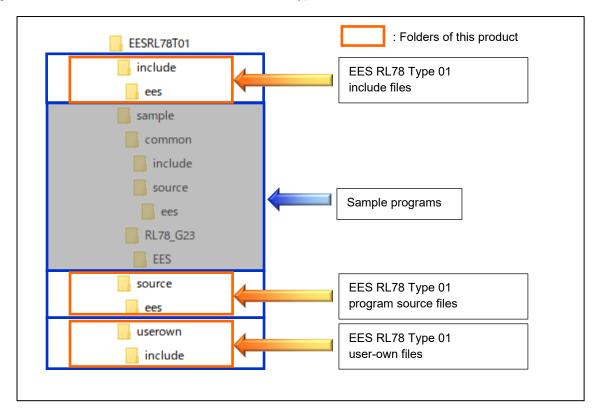


Figure 2-4 Folder Structure of EES RL78 Type 01

Note: Figure 2-4 shows an example of using RL78/G23. The installed "sample" folder contains a folder for each device group (e.g. RL78\_G23, RL78\_G24). Refer to "6.1.1 Folder Structure" for the sample folder for each device group.

### 2.3.2 List of Files

### 2.3.2.1 List of Source Files

Table 2-1 shows the program source files in the "source\ees\" folder.

Table 2-1 Program Source Files in the "source\ees\" Folder

No.	Source File Name	Description
1	r_ees_api.c	This file contains the API functions for EEPROM emulation control.
2	r_ees_exrfd_api.c	This file contains the API functions RFD control functions for EES
3	r_ees_sub_api.c	This file contains API functions that are used as internal functions for EEPROM emulation control.

Table 2-2 shows the program source file in the "userown\" folder.

Table 2-2 Program Source File in the "userown\" Folder

No.	Source File Name	Description
1	r_ees_descriptor.c	EES descriptor source file.

### 2.3.2.2 Header File List of Header Files

Table 2-3 shows the program header files in the "include\" folder.

Table 2-3 Program Header Files in the "include\" Folder

No.	Header File Name	Description
1	r_ees_api.h	This file defines the prototypes used in EEPROM control functions.
2	r_ees_exrfd_api.h	This file defines the prototypes used in RFD control functions for EES.
3	r_ees_sub_api.h	This file defines the prototypes for internal functions used in EEPROM emulation control functions.

Table 2-4 shows the program header files in the "userown\include\" folder.

Table 2-4 Program Header Files in the "userown\include\" Folder

No.	Header File Name	Description
1	r_ees_descriptor.h	EES descriptor header file.
2	r_ees_user_types.h	This file defines the types of user data used in EES.

Table 2-5 shows the program header files in the "include\ees" folder.

Table 2-5 Program Header Files in the "include\ees" Folder

No.	Header File Name	Description
1	r_ees.h	Common header file.
2	r_ees_compiler.h	This file defines the compiler-dependent macros used in EES RL78 Type 01.
3	r_ees_defines.h	This file describes the definitions that differ between compilers used in EES RL78 Type 01.
4	r_ees_device.h	This file defines the hardware-specific macros used in EES RL78 Type 01.
5	r_ees_memmap.h	This file defines macros to describe sections used in EES RL78 Type 01.
6	r_ees_types.h	This file defines the types of variables used in EES RL78 Type 01.
7	r_typedefs.h	This file defines the types of data used in EES RL78 Type 01.

### Resources of RL78/G2x 2.4

### 2.4.1 **Memory Map**

Table 2-6 shows the memory map (code flash memory: CF[1 block = 2 Kbytes], data flash memory: DF [1 block = 256 bytes], and RAM) of the RL78/G23, RL78/G22 and RL78/G24.

Table 2-6 Memory Map (ROM, Data Flash, and RAM)

RL78	Device	Code Flash Memory: CF	RAM
G23	R7F100GxF (x = A, B, C, E, F, G, J, L)	96 Kbytes (00000H to 17FFFH)	12 Kbytes (FCF00H to FFEFFH)
	R7F100GxG (x = A, B, C, E, F, G, J, L, M, P)	128 Kbytes (00000H to 1FFFFH)	16 Kbytes (FBF00H to FFEFFH)
	R7F100GxH (x = A, B, C, E, F, G, J, L, M, P)	192 Kbytes (00000H to 2FFFFH)	20 Kbytes (FAF00H to FFEFFH)
	R7F100GxJ (x = A, B, C, E, F, G, J, L, M, P, S)	256 Kbytes (00000H to 3FFFFH)	24 Kbytes (F9F00H to FFEFFH)
	R7F100GxK (x = F, G, J, L, M, P, S)	384 Kbytes (00000H to 5FFFFH)	32 Kbytes (F7F00H to FFEFFH)
	R7F100GxL (x = F, G, J, L, M, P, S)	512 Kbytes (00000H to 7FFFFH)	48 Kbytes (F3F00H to FFEFFH)
	R7F100GxN (x = F, G, J, L, M, P, S)	768 Kbytes (00000H to BFFFFH)	48 Kbytes (F3F00H to FFEFFH)
	Data Flash Memory: DF	8 Kbytes (F1000H to F2FF All RL78/G23 devices	FFH)
G22	R7F102GxC (x = 4, 6, 7, 8, A, B, C, E, F, G)	32 Kbytes (00000H to 07FFFH)	4 Kbytes (FEF00H to FFEFFH)
	R7F102GxE (x = 4, 6, 7, 8, A, B, C, E, F, G)	64 Kbytes (00000H to 0FFFFH)	4 Kbytes (FEF00H to FFEFFH)
	Data Flash Memory: DF	2 Kbytes (F1000H to F17F All RL78/G22 devices	FH)
G24	R7F101GxE (x=6,7,8,A,B,E,F,G,J,L)	64 Kbytes (00000H to 0FFFFH)	12 Kbytes (FCF00H to FFEFFH)
	R7F101GxG (x=6,7,8,A,B,E,F,G,J,L)	128 Kbytes (00000H to 1FFFFH)	12 Kbytes (FCF00H to FFEFFH)
	Data Flash Memory: DF	4 Kbytes (F1000H to F1FF All RL78/G24 devices	FFH)

### 2.4.2 **Allocation of Blocks**

Figure 2-5, and Figure 2-6 shows the allocation of blocks in code flash memory (CF), and data flash memory (DF). Refer to the user's manual of a target device for allocation of blocks for other devices.

(1) R7F100GxN (Code flash memory: 768 Kbytes)

(2) R7F100GxF (Code flash memory: 96 Kbytes)

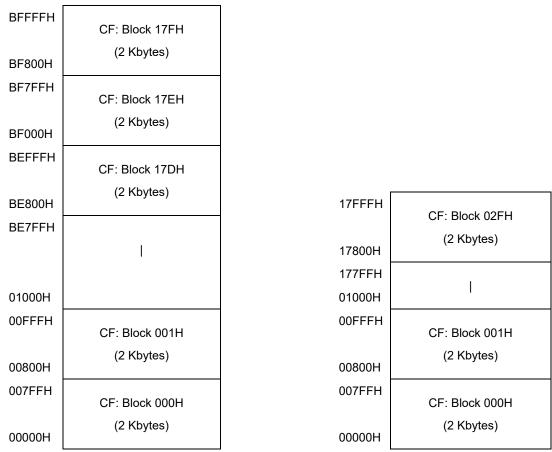


Figure 2-5 Blocks in the Code Flash Memory

(1) All RL78/G23 devices (Data flash memory: 8 Kbytes)

F2FFFH	DF: Block 01FH
F2F00H	(256 bytes)
F1200H	I
F11FFH	DF: Block 001H
F1100H	(256 bytes)
F10FFH	DF: Block 000H
F1000H	(256 bytes)

Figure 2-6 Blocks in the Data Flash Memory

### 2.4.3 Flash Operation Mode

### (1) The range of operating frequency in each flash operation mode of RL78/G23.

Table 2-7 shows the range of operating frequency in each flash operation mode of RL78/G23.

Table 2-7 Operating Frequency Ranges for Individual Flash Operation Modes and Power Supply Voltages

Power Supply Voltage (V <sub>DD</sub> )	Flash Operation Mode	Operating Frequency
$1.8~V \leq V_{DD} \leq 5.5~V$	HS (high-speed main) mode	1 MHz to 32 MHz
	LS (low-speed main) mode	1 MHz to 24 MHz
$1.6 \text{ V} \le \text{V}_{DD} \le 1.8 \text{ V}$	HS (high-speed main) mode	1, or 2 MHz
	LS (low-speed main) mode	1, or 2 MHz

Note: The flash memory cannot be reprogrammed in the LP (low-power main) mode.

### (2) The range of operating frequency in each flash operation mode of RL78/G22.

Table 2-8 shows the range of operating frequency in each flash operation mode of RL78/G22.

Table 2-8 Operating Frequency Ranges for Individual Flash Operation Modes and Power Supply Voltages

Power Supply Voltage (VDD)	Flash Operation Mode	Operating Frequency
$1.8~V \leq V_{DD} \leq 5.5~V$	HS (high-speed main) mode	1 MHz to 32 MHz
	LS (low-speed main) mode	1 MHz to 24 MHz

Note: The flash memory cannot be reprogrammed in the LP (low-power main) mode.

### (3) The range of operating frequency in each flash operation mode of RL78/G24.

Table 2-9 shows the range of operating frequency in each flash operation mode of RL78/G24.

Table 2-9 Operating Frequency Ranges for Individual Flash Operation Modes and Power Supply Voltages

Power Supply Voltage (VDD)	Flash Operation Mode	Operating Frequency
$2.4~V \leq V_{DD} \leq 5.5~V$	HS (high-speed main) mode (with prefetching on)	48 MHz
$1.8~V \leq V_{DD} \leq 5.5~V$	HS (high-speed main) mode (with prefetching off)	1 MHz to 32 MHz
	LS (low-speed main) mode	1 MHz to 24 MHz

Notes 1: The flash memory cannot be reprogrammed in the LP (low-power main) mode.

2: It is necessary to enable a prefetch buffer peculiar to RL78/G24 in the mode of HS (high-speed main) mode (with prefetching on).

# 2.5 Resources Used in EES RL78 Type 01

# 2.5.1 Sections Used in EES RL78 Type 01

Table 2-10 shows the sections used for EES and allocations of the sections.

Table 2-10 Sections Used in EES

Section Name	Description	Allocation
EES_CODE	Program section of API functions for EES control	ROM
EES_CNST	Constant variables section for EES initialized variables.	ROM
EES_VAR	Variables section for EES control	RAM
SMP_EES	Program section of sample functions for EES control	ROM
SMP_VAR	Variables section of sample functions for EES control	RAM

### 2.5.2 Software Resources

Table 2-11 shows software resources (Reference value).

Table 2-11 Software Resources<sup>Notes1,2</sup> (Reference value)

Item	Size (Byte)		
item	CC-RL	IAR	LLVM
Stack	44	48	44
Code size <sup>Note3</sup>	4624	5177	5830

Notes 1: These values are when using the compiler options described in "1.6 C Compiler Definitions".

- 2: Does not include the stack and code size of the sample program.
- 3: Does not include code size of the RFD RL78 Type 01.

# 3. **EEPROM Emulation**

# 3.1 Specifications of EEPROM Emulation

By calling the EES functions provided by the EES RL78 Type 01 from a user-created program, use is possible without the awareness of data flash memory operations.

For the EES RL78 Type 01, an one-bye identifier (data ID: 1 to 254) is assigned by the user for each data item, and reading and writing using any unit from 1 to 255 bytes are possible on an assigned identifier basis. (The EES can handle up to 254 identifiers.)

Also, EES blocks (virtual block) for storing data use more than three blocks of area (recommended) Note. These blocks are called EES blocks. Data written by EEPROM emulation is divided into reference data and user-specified data, and the reference data is written to the target blocks from the lower block address, while the user data is written from the higher block address.

Note: At least two blocks are necessary for EEPROM emulation. When two blocks are specified, if a write error occurs even once, only reading of normally written data is possible but writing is no longer possible. After that, the two target blocks must be formatted when the EES is used to write data. Written data is erased completely. Since a contingency (such as voltage drop) may occur in the system, we recommend that you specify at least three blocks.

### 3.2 Outline of Functions

The EES provides basic read/write functions having the following features.

- The value to set for the size of the EES block:

RL78/G23 and RL78/G24: 1024 or 2048 bytes

RL78/G22: 512 bytes

- Up to 254 data items settable
- A data size of 1 to 255 bytes settable
- Supporting the background operation (BGO)
- Memory consumption of data for EES management (Block header, Separator):

10 bytes per EES block

- Memory consumption of reference data: 3 bytes per EES block write data
- Restoration by R\_EES\_ENUM\_CMD\_REFRESH when execution is stopped by a CPU reset while
   R EES ENUM CMD WRITE or R EES ENUM CMD REFRESH is running
- Block rotation (averaging data flash use frequency)

Table 3-1 shows the range of settings when the EES functions are used.



Item Range RL78/G22: 512 (bytes) EES block size RL78/G23 and RL78/G24: 1024 or 2048 (bytes) 1 to 255 User data length Amount of stored user data Note 1 1 to 254 Data ID range 1 to 254 (The numbers assigned are from 1 to 254 in the order of registration, and the selection of settings is not possible.) Number of EES blocks Note 2 3 to 255 The EES block size is set to 512 bytes: 502 / 2 (bytes) or less Recommended user data size Note 1 The EES block size is set to 1024 bytes: 1014 / 2 (bytes) or less The EES block size is set to 2048 bytes. 2038 / 2 (bytes) or less

Table 3-1 Range of Settings when the EES Functions are Used

Notes: 1. The total size of user data must be within 1/2 of each block when all user data are written to an EES block. Therefore, the range used for the number of stored user data items differs depending on the size of the stored user data. It is also necessary to consider the size of the reference data provided for each data item for management use when determining the total size. For details about the number of stored user data items and total size, see "4.1 Number of Stored User Data Items and Total User Data Size".

2. EES blocks cannot be set more than the maximum number of blocks of on-board data flash memory.

### 3.3 EES Pool

This chapter describes the EES architecture required for the user to rewrite data flash memory (the EES pool) by using the EES.

### 3.3.1 EES Pool State

Each block has a state which indicates the current usage of the block. Table 3-2 shows States of the EES Blocks.

State	Description	
Active	Only a single EES block is active at a time to store defined data. The active block	
	circulates in data flash blocks allocated in the EES pool.	
Invalid	No data is stored in invalid blocks. EES blocks are marked as invalid by the EES or	
	become invalid in the case of erasure blocks.	
Excluded	If functional operation failed and possibility of a data flash failure is clarified, the EES	
	excludes the relevant block and the block is no longer used for EEPROM emulation.	

Table 3-2 States of the EES Blocks

When no writable area is remaining in the active block (EES block 1 in the example) and data can no longer be stored (failure in write command), a new active block is selected in a cyclic manner and the current valid data set is copied to this new active block. This process is referred to as refresh. After the

R\_EES\_ENUM\_CMD\_REFRESH command is executed, the previous active block becomes invalid and only a single active block exists. Excluded blocks (like block 7 in the example) are ignored during this process and not considered as candidates for the selection of the next active block.

Figure 3-1 shows an example of pool states (EES block size is set to 1 Kbyte).

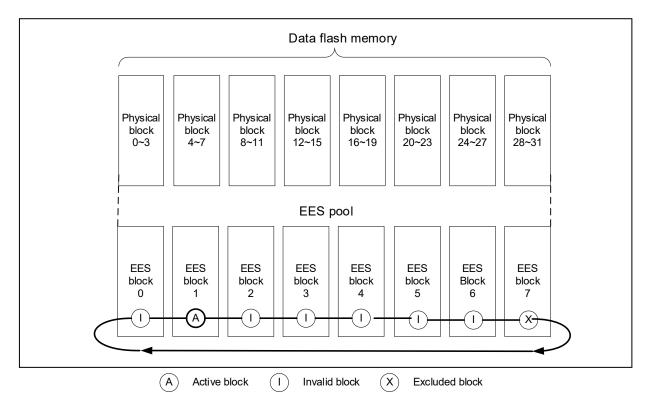


Figure 3-1 EES Pool States Example (The EES block size is set to 1 Kbyte)

The overall life cycle of a block in the EES pool is shown in Figure 3-2. During normal operation, the block switches between active and invalid state. When an error occurs during an access to the EES block, the error EES block is marked as excluded. This block will not enter the lifecycle again. However, the user can try to restore the block by a format of the complete pool which also erases all existing data content.

Caution: An EES block is a virtual block. If at least 1 block of erase blocks (physical block of a 256-byte unit) of the data flash memory included in an EES block cannot be used by failure, the EES block including the erase block will be judged to be "Excluded block".

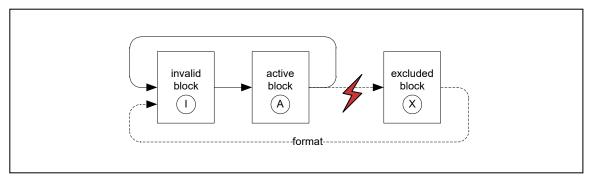


Figure 3-2 Life Cycle of an EES Block

The EES pool has the four states shown below.

Table 3-3 States of the EES Pool

State	Description
Pool operational	This is the usual case during EES operation. All commands are available and can be executed.
Pool full	Free space for data write is insufficient in the active block in use. This state indicates that a refresh needs to be executed.
Pool exhausted	No continuously usable EES block is left. (At least two blocks that are not excluded are necessary for EES operations.)
Pool inconsistent	There is a mismatch in the pool state and the data structure in the EES block does not match the user-set data structure. The EES block is in the undefined state (e.g. no active block is present).

### 3.3.2 Structure of EES Block

The detailed block structure used by the EES is shown in . In general, an EES block is divided into three utilized areas: the block header, the reference area, and the data area.

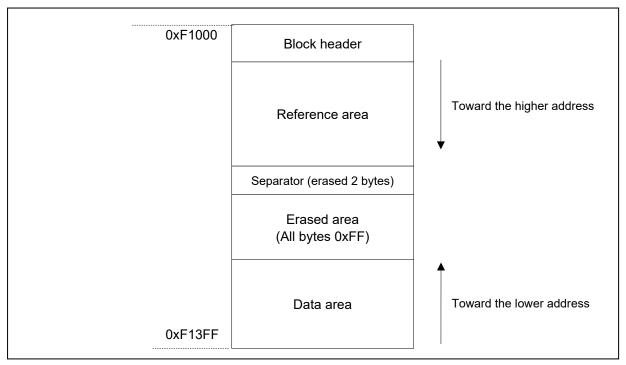


Figure 3-3 EES Block Structure(1 Kbyte)

Table 3-4 Configuration of Each EES Block

Name	Description	
Block header	The block header contains all block status information needed for the block management within the EES-pool. It has a fixed size of 8 bytes.	
Reference area ontains reference data which are required for the manage of data. When data are written, this area expands in the direction of haddresses.		
Data area	The data area contains user data. When data are written, this area expands in the direction of lower addresses.	

Between reference area and data area, there is an erased area. With each EES data update (i.e. the data is written), this area is reduced successively. However, at least 2 bytes of space always remain between reference area and data area for management and separation of these areas. This is indicated by the separator in Figure 3-3.

The EES block header is detailed in section "3.3.3 EES Block Header", while the structure of data stored in the reference and data area are described in section "3.3.4 Structure of Stored Data".

### 3.3.3 EES Block Header

The structure of the block header is depicted in Figure 3-4. It is composed of 8 bytes, three of which are reserved for the system.

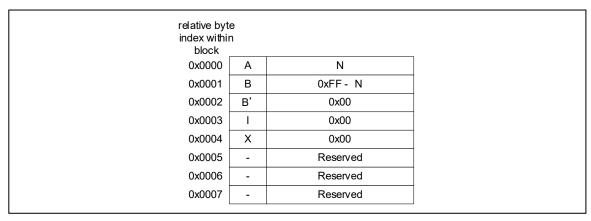


Figure 3-4 Structure of EES Block Header

The block status flags start at the beginning of the block and include the A flag, B flag, B' flag, I flag, and X flag, each of which is 1 byte, for a total of 5 bytes of data. The combination of flags indicates the EES block status

Figure 3-4 shows the placement status of flags, and Table 3-5 shows the combination status of flags.

Table 3-5 Overviews of Block Status Flags

Block Status Flag					01.1	5
A Flag	B Flag	B' Flag	I Flag	X Flag	State	Description
0x01	0xFE	0x00	0xFF	0xFF		Currently used block After the R_EES_ENUM_CMD_REFRESH command is executed, the A flag of a new active block is set to 0x02.
0x02	0xFD	0x00	0xFF	0xFF	Active	Currently used block After the R_EES_ENUM_CMD_REFRESH command is executed, the A flag of a new active block is set to 0x03.
0x03	0xFC	0x00	0xFF	0xFF		Currently used block After the R_EES_ENUM_CMD_REFRESH command is executed, the A flag of a new active block is set to 0x01.
0x01	0xFE	0x01 – 0xFE	0xFF	0xFF	Active	Currently used block. However, new data cannot be added because the writing for B' flag is not completed. (Read is possible.)
0x02	0xFD		0xFF	0xFF		After executing the R_EES_ENUM_CMD_REFRESH command, the A flag of a new active block is set in the order of 0x01, 0x02, 0x03, 0x01,
0x03	0xFC		0xFF	0xFF		
		0xFF	0xFF	0xFF		
		other than 0xFF	0xFF	Invalid	Invalid block	
				other than 0xFF	Excluded	Excluded block

### 3.3.4 Structure of Stored Data

The structure of stored data when user data is written to an EES block is shown in the figure below. A data is composed of three parts: the start-of-record (SoR) field and the end-of-record (EoR and EpR') field and the data field. The EES descriptor table can be used to set data for use in the EES. Each data is referred to by an identification number (ID) and can have a size between 1 and 255 bytes. (The exact specification of the format of the EES descriptor can be found in section "4.2 Initial Values to be Set by User".)

Each time data is written, stored data increase in the EES block and multiple units of stored data exist in the EES block, but only the most recent stored data is referenced.

SoR,EoR and EoR' build up the so-called reference data which is required for the management of the data. The reference data and user data values are stored in different sections of the active block, namely the reference area and the data area, respectively. Figure 3-6 shows the overview of the entire structure of stored data.

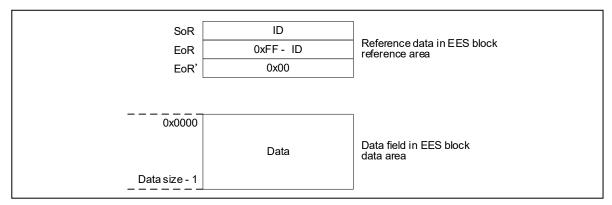


Figure 3-5 Structure of Stored Data

Table 3-6 Description of Each Field of Data Area

Name	Description
SoR field (Start of Record)	The 1 byte SoR field contains the ID of data. This field indicates the start of write processing. Data IDs 0x00 and 0xFF are not used to avoid patterns of erased cells.
EoR field (End of Record)	The 1 byte EoR field contains a 0xFF - data ID value.  This field indicates successful end of write processing. If writing does not end normally due to a device reset or other reasons, the corresponding stored data is ignored by the EES.
EoR' field (End of Record')	The 1 byte EoR' field contains the completion of the write process to the EoR field. This field is written to 0x00 after the EoR field has been written.  - When the value is between 0x01 - 0xFE, the stored data is valid, but the writing has not been completed. Therefore, the block is treated as a block to which data cannot be added.  - When the value is 0xFF, EES judges with the execution result of the writing for the EoR field not having been a normal end.
Data field	The data field contains the user data. The size of user data is 1 to 255 bytes. When data of 2 bytes or more is stored, the smallest address of the data is allocated to the smallest address of the data field (as shown in Figure 3-6).

Data is written to the EES block in the order of SoR -> data field -> EoR -> EoR'. If the value of the EoR field is not written correctly, the immediately previous data becomes valid.

Notes: 1. The total size of the reference data consumed by each stored data is 3 bytes. This should be considered when evaluating the free space in a block before writing the data through the R\_EES\_GetSpace function.

2. No checksum is added to user data. If a checksum is needed, add it to user data and check through the user program.

### 3.3.5 EES Block Overview

Figure 3-6 shows an example of an EES block that contains multiple units of stored data:

- Data ID 0x01 with size = 0x04
- Data ID 0x02 with size = 0x01
- Data ID 0x03 is defined but not written here.
- Data ID 0x04 with size = 0x02

The data have been written in the sequence ID 0x01 -> ID 0x04 -> ID 0x02.

In this example, the data with ID 0x03 has not been written yet.

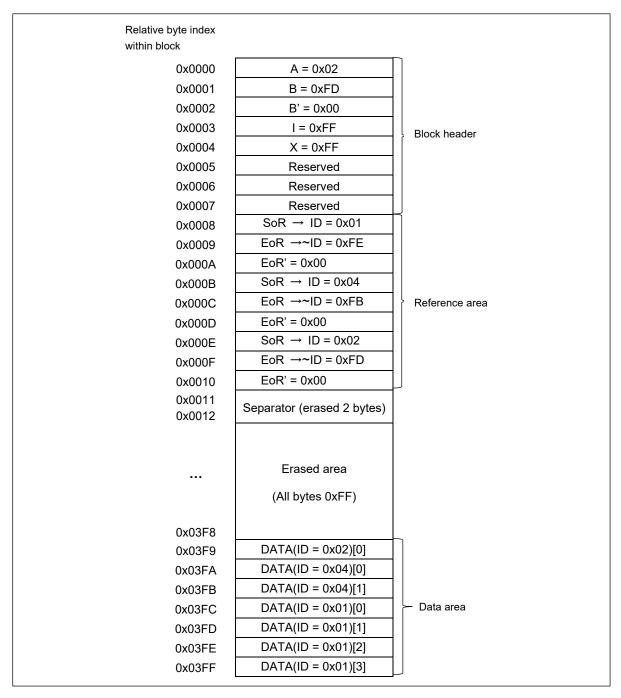


Figure 3-6 Example of an Active EES Block

# 4. Using EEPROM Emulation

EEPROM emulation can store a maximum of 254 data items each consisting of 1 to 255 bytes in the flash memory by using three or more blocks (recommended) of flash memory.

EEPROM emulation can be executed by incorporating the EES into a user-created program and executing that program.

### 4.1 Number of Stored User Data Items and Total User Data Size

The total size of user data that can be used in the EEPROM emulation is limited. The size required for writing all user data to an EES block must be within 1/2 of the block. Therefore, the number of stored data items that can be used differs depending on the size of user data that is actually stored. The following shows how to calculate the size that can be used when actually writing user data, as well as the total user data size.

[Maximum usable size of one block that can be used to write the user data]

Size required for EEPROM emulation block management: 8 bytes Free space necessary as termination information (separator): 2 bytes

- EES Block size: 1024 bytes

EES block size: 256 bytes \* 4 = 1024 bytes

Maximum usable size of one block = 1024 bytes - (8 bytes + 2 bytes) = 1014 bytes

- EES Block size: 2048 bytes

EES block size: 256 bytes \* 8 = 2048 bytes

Maximum usable size of one block = 2048 bytes - (8 bytes + 2 bytes) = 2038 bytes

[Calculating the size for writing each user data item] Note

Size of each written user data item = data size + reference data size (3 bytes)

Note: For details, see 3.3.4 Structure of Stored Data.

[Calculating the basic total user data size]

```
Basic total size = (user data 1 + 3) + (user data 2 + 3) ... + (user data n + 3)
```

[Maximum size and recommended size]

Data must be held in one block. Therefore, the maximum size is the maximum usable size of one block but the following relational expression should be met. To enable all data to be updated at least once, we recommend that the data be within the half size of the maximum usable size of one block.

Maximum size: Assumed that the largest data can be updated once after all data have been written. Recommended size: Assumed that all data can be updated once after all data have been written.

- EES Block size: 1024 bytes

  Maximum size = the basic total user data size + maximum data size + 2 ≤ 1014

  Recommended size = 1014 / 2 = 507 bytes or less
- EES Block size: 2048 bytes

  Maximum size = the basic total user data size + maximum data size + 2 ≤ 2038

  Recommended size = 1038 / 2 = 1019 bytes or less



# 4.2 Initial Values to be Set by User

As the initial values for the EES, be sure to set the items indicated below. In addition, before executing the EES, be sure to execute the high-speed on-chip oscillator. The high-speed on-chip oscillator must also be activated when using the external clock.

- · Number of stored data items, and data size of the identifier (data ID)
  - < EEPROM emulation soft wear user include file (r\_ees\_descriptor.h) > Notes 2, 3

```
#define R_EES_EXRFD_VALUE_U16_PHYSICAL_BLOCK_SIZE (256u)

: (1) The size of one block of data flash memory (Physical block size).

#define R_EES_EXRFD_VALUE_U08_PHYSICAL_BLOCKS_PER_VIRTUAL_BLOCK (4u)

: (2) The number of data flash memory blocks (Number of physical blocks) to set in the EES block(Per virtual block). Notes 1

#define R_EES_EXRFD_VALUE_U08_POOL_VIRTUAL_BLOCKS (4u)

: (3) EES pool size (Number of virtual blocks)

#define R_EES_VALUE_U08_VAR_NO (8u) : (4) Number of stored data items
```

Notes 1: The number of data flash memory blocks to set in the EES block (Per virtual block): RL78/G22: 2u RL78/G23 and RL78/G24: 4u or 8u

< EEPROM emulation software user data definition file (r ees user types.h) > Notes 3

```
typedef uint8_t type_A[2]; : (5) Data size definition of each data identifier typedef uint8_t type_B[3]; typedef uint8_t type_C[4]; typedef uint8_t type_D[5]; typedef uint8_t type_E[6]; typedef uint8_t type_F[10]; typedef uint8_t type_X[20]; typedef uint8_t type_Z[255];
```

< EEPROM emulation software user program file (r ees descriptor.c) > Note 3

```
_far const uint8_t g_ar_u08_ees_descriptor
                                                             : (6) Data size of each data identifier
[R\_EES\_VALUE\_U08\_VAR\_NO + 2u] =
                                                                (data ID).
 (uint8_t)( R_EES_VALUE_U08_VAR_NO), /* variable count
                                                                    */ \
                                                     */ \
                               /* id=1
 (uint8_t)(sizeof(type_A)),
 (uint8 t)(sizeof(type B)),
                               /* id=2
                                                     */ \
                                                     */ \
 (uint8_t)(sizeof(type_C)),
                               /* id=3
                                                     */ \
 (uint8_t)(sizeof(type_D)),
                               /* id=4
 (uint8_t)(sizeof(type_E)),
                               /* id=5
                                                     */ \
                                                     */ \
 (uint8 t)(sizeof(type F)),
                               /* id=6
 (uint8_t)(sizeof(type_X)),
                               /* id=7
                                                     */ \
                                                     */ \
                               /* id=8
 (uint8_t)(sizeof(type_Z)),
 (uint8_t)(0x00),
                               /* zero terminator
                                                    */ \
};
```

- Notes 2: The macros that are being used are parameters which are common to the whole EES, so any changes should only be to numerical values.
  - 3: After initializing the EEPROM emulation blocks (after executing the R\_EES\_ENUM\_CMD\_FORMAT command), do not change the values. If the values are changed, reinitialize the EES blocks (by executing the R\_EES\_ENUM\_CMD\_FORMAT command).
- (1) The size of one block of data flash memory (Physical block size). Set the size of one block of data flash memory installed (mounted) in the target device.
- (2) The number of data flash memory blocks (Number of physical blocks) to set in the EES block. Sets the number of data flash memory blocks to use for the EES block.
- (3) EES pool size. Note

The number of blocks in the data flash memory of the target device must be specified as the number of blocks in the EES pool.

Note: Specify 3 (3 blocks) or a greater value (recommended).

- (4) Number of stored data items
  - Specify the number of data items to be used in the EEPROM emulation. A value of 1 to 254 can be set.
- (5) Data size definition of each data identifier (data ID). Defines the data type name for the byte size of each user data. The EES descriptor table reflects the byte size of each user data.

### (6) Data size of each data identifier (data ID)

A table to define the data size of each identifier is provided below. This is called an EES descriptor table. Data to be written must be registered in the EES descriptor table in advance.

\_\_far const uint8\_t g\_ar\_u08\_ees\_descriptor [Number of stored data items + 2]

R_EES_VALUE_U08_VAR_NO
Byte size of data ID1
Byte size of data ID2
Byte size of data ID3
Byte size of data ID4
Byte size of data ID5
Byte size of data ID6
Byte size of data ID7
Byte size of data ID8
0x00

Figure 4-1 EES Descriptor Table (When there are eight different data items)

### R\_EES\_VALUE\_U08\_VAR\_NO

User-specified number of data items used in the EES

- Byte size of data IDx
   User-specified size of user data (in bytes)
- Termination area (0x00)
   Specify 0 as the termination information.

## 5. User Interface

## 5.1 Request Structure (st\_ees\_request\_t) Settings

Basic operations such as reading from and writing to the data flash memory are performed by a single function. The function transfers commands and data ID to the EES via the request structure (st\_ees\_request\_t). Furthermore, the EES state and error information are acquired via the request structure (st\_ees\_request\_t).

In subsequent sections, write access to the request structure (st\_ees\_request\_t) from the user is called user write access, and read access to it from the user is called user read access.

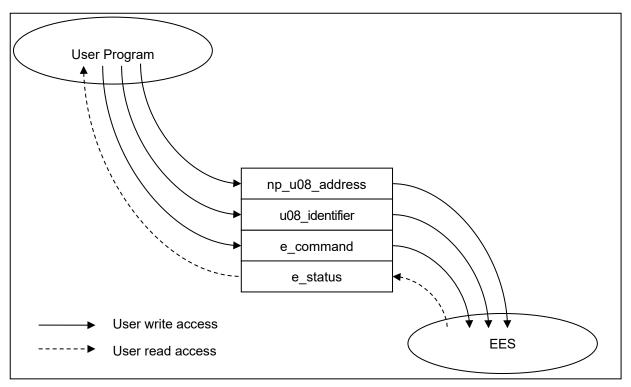


Figure 5-1 Request Structure (st\_ees\_request\_t)

The request structure (st\_ees\_request\_t) is defined in the r\_ees\_types.h file. It should not be changed by the user.

[Definition of the request structure (st\_ees\_request\_t)]

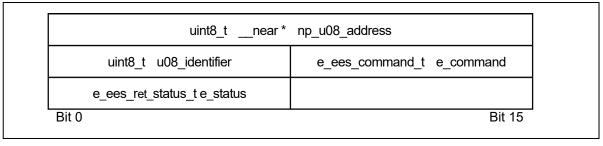


Figure 5-2 Alignment of Variables of the Request Structure (st\_ees\_request\_t)

#### 5.1.1 User Write Access

### (1) np\_u08\_address

Specifies a pointer to the start address of the data buffer used for R\_EES\_ENUM\_CMD\_WRITE command and R\_EES\_ENUM\_CMD\_READ command execution.

Associated command (macro name)	Setting	
R_EES_ENUM_CMD_WRITE	Pointer to the start address of the data buffer. Note 1	
R_EES_ENUM_CMD_READ	Pointer to the start address of the data buffer. Note 2	

Notes 1: Buffer which contains data written by the user

2: Buffer which contains data read from the data flash memory

### (2) u08\_identifier

Specify the data ID used for each command. For more information about how to do this, see the description of the R\_EES\_Execute function in section "5.7 Specifications of API Functions".

Associated command (macro name)	Setting	
R_EES_ENUM_CMD_WRITE	ID of write data	
R_EES_ENUM_CMD_READ	ID of read data	

### (3) e\_command

Commands to be set in the common executable function.

Associated command (macro name)	Description
R_EES_ENUM_CMD_UNDEFINED	Undefined command
	(Initial value: It is used only for initialization.)
R_EES_ENUM_CMD_STARTUP	Startup processing
R_EES_ENUM_CMD_WRITE	Write processing
R_EES_ENUM_CMD_READ	Read processing
R_EES_ENUM_CMD_REFRESH	Refresh processing
R_EES_ENUM_CMD_FORMAT	Format processing
R_EES_ENUM_CMD_SHUTDOWN	Shutdown processing

### 5.1.2 User Read Access

### - e\_status

EES status and error information. For information about the status and errors which might occur during execution of the functions, see the description of the R\_EES\_Execute function in section "5.7 Specifications of API Functions".

## 5.2 List of API Functions and R\_EES\_Execute Function Commands for the EES

### 5.2.1 API Functions for the EES

Table 5-1 shows the API functions for EES RL78 Type 01.

Table 5-1 API Functions for EES RL78 Type 01

	API Name	Overview
1	R_EES_Init	Initializes internal data and variables and checks the descriptor configuration.
2	R_EES_Open	EEPROM emulation preparation processing. This function makes the EEPROM emulation executable.
3	R_EES_Close	EEPROM emulation end processing. This function makes the EEPROM emulation un-executable.
4	R_EES_Execute	EEPROM emulation execution function.  Each type of processing for performing EEPROM emulation operations is specified for this function as an argument in the command format, and the processing is executed.
5	R_EES_Handler	Continuous EEPROM emulation execution processing. This function is used to check for the completion of processing while allowing processing of EEPROM emulation specified by the R_EES_Execute function to continue.
6	R_EES_GetSpace	Gets the free space of the active block.

## 5.2.2 Commands for R\_EES\_Execute Function

**Table 5-2** shows commands for R\_EES\_Execute.

Table 5-2 List of Commands for R\_EES\_Execute.

	Command Name	Outline
1	R_EES_ENUM_CMD_STARTUP	[Startup Processing] This command checks the block status and sets the system to the EEPROM emulation (data access) valid state (Full Access). If two active blocks exist, the incorrect block is changed to an invalid block.  Be sure to execute this command before executing commands other than the R_EES_ENUM_CMD_FORMAT command and make sure that the command finishes normally.
2	R_EES_ ENUM_CMD_WRITE Note1	[Write Processing] This command writes the specified data to the EES blocks.  * The following arguments must be specified prior to execution.  - np_u08_ees_address: Specifies a pointer to the start address of the RAM area where the write data is stored.  - u08_ees_identifier: Specifies the data ID of the write data.
3	R_EES_ ENUM_CMD_READ Note1	[Read Processing]  Read the specified data from an EES block.  * The following arguments must be specified prior to execution.  - np_u08_ees_address: Specifies a pointer to the start address of the RAM area where the read data is stored.  - u08_ees_identifier: Specifies the data ID of the read data.
4	R_EES_ ENUM_CMD_REFRESH Note1,2	[Refresh Processing] Copy the latest stored data from the active block (copy source EES block) to the next block (copy destination EES block) in the EES pool after the erase processing. This makes the copy destination block active.
5	R_EES_ ENUM_CMD_FORMAT	[Format Processing] Initialize (erase) everything, including the data recorded in the whole EES pool. Be sure to use this command before using EEPROM emulation for the first time. Note that issuing this command is also necessary to initialize all blocks if a malfunction occurs in an EES block (such as an active block disappearing) or the values in the descriptor table (those which are fixed values that cannot be changed) are modified.  Because EEPROM emulation switches to the stopped state (opened) regardless of the results after the processing finishes, execute the R_EES_ENUM_CMD_STARTUP command to continue using EEPROM emulation.
6	R_EES_ ENUM_CMD_SHUTDOWN Note1	[Shutdown Processing] Set the EEPROM emulation operation to the stopped state (opened).

Notes 1: Do not execute this command until the R\_EES\_ENUM\_CMD\_STARTUP command has finished normally.

2: The erase processing is performed by executing the R\_EES\_ ENUM\_CMD\_REFRESH command.

### 5.2.3 RFD Control API Functions for EES

Table 5-3 shows RFD control API functions for EES.

This function is used internally by EES. It does not need to be used directly by the user.

Table 5-3 List of RFD Control API Functions for EES

	API Name	Overview	
1	R_EES_EXRFD_Init	Initializes RFD RL78 Type 01.	
2	R_EES_EXRFD_Open	Set the data flash control register (DFLCTL) to the state where accessing the data flash memory is permitted(DFLEN = 1).	
3	R_EES_EXRFD_Close	Set the data flash control register (DFLCTL) to the state where access to the data flash memory is inhibited (DFLEN = 0). All ongoing EES processing stop.	
4	R_EES_EXRFD_Erase	Start erasing the EES block(one virtual block).	
5	R_EES_EXRFD_Write	Starts writing to the specified the data flash memory address(one byte).	
6	R_EES_EXRFD_BlankCheck	Starts Blank check to the specified the data flash memory address.	
7	R_EES_EXRFD_Read	Reads the specified address in the data flash memory.	
8	R_EES_EXRFD_Handler	Continues processing of the RFD control function for EES that is executing, and confirms termination.	

### 5.3 State Transitions

To use EEPROM emulation from a user-created program, it is necessary to initialize the EES and execute functions that perform operations such as reading and writing on EES blocks. **Figure 5-3** shows the overall state transitions, and **Figure 5-4** shows an operation flow for using basic features. When using EEPROM emulation, incorporate EEPROM emulation into user-created programs by following this flow.

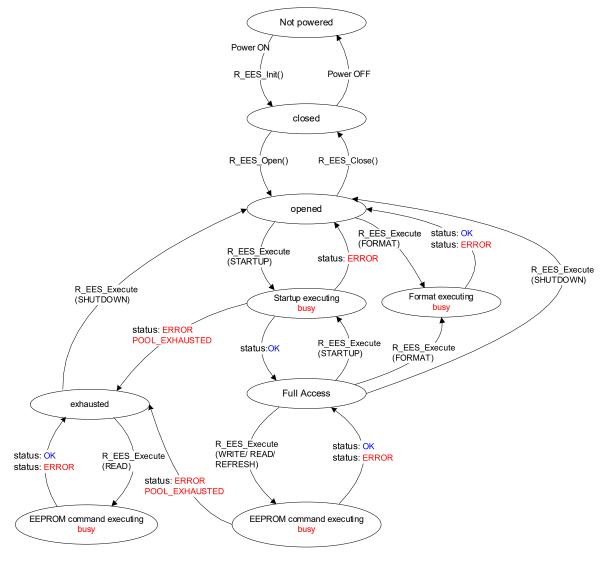


Figure 5-3 State Transitions Diagram

Note: Once the R\_EES\_ENUM\_CMD\_FORMAT command has started running, execute the R\_EES\_Handler function to check for its completion.

### [Overview of state transitions diagram]

To use EES to manipulate the data flash memory, it is necessary to execute the provided functions in order to advance the processing.

## (1) Not powered

Status is Power Off.

### (2) closed

This is the state in which the data to perform EEPROM emulation is initialized by executing the R\_EES\_Init functions (no ongoing operation to the data flash memory).

Do not execute "operation of the code flash memory", STOP mode or HALT mode while the EEPROM emulation is executing. In the case where they are executed, execute R\_EES\_Close function and change to a Closed state.

#### (3) opened

This state is switched to by executing R\_EES\_Open in the closed state and makes it possible to perform operations on the data flash memory. Even if the R\_EES\_Close function is executed, do not execute "operation of the code flash memory", STOP mode, or HALT mode until a state changes to "closed".

### (4) started

This state is switched to by executing the R\_EES\_ENUM\_CMD\_STARTUP command in the opened state and makes it possible to execute EEPROM emulation. Writes and reads that use EEPROM emulation are performed in this state.

### (5) exhausted

This state is made from the opened or started state when continuously usable EES blocks have been exhausted during command execution. In this state, only R\_EES\_ENUM\_CMD\_READ, and R\_EES\_ENUM\_CMD\_SHUTDOWN commands are executable.

### (6) busy

This is the state used when executing a specified command. The state that is switched to differ depending on which command is executed and how it terminates.

### 5.4 Basic Flowchart

Figure 5-4 below shows the basic procedure to perform read and write operations for the data flash by using the EES.

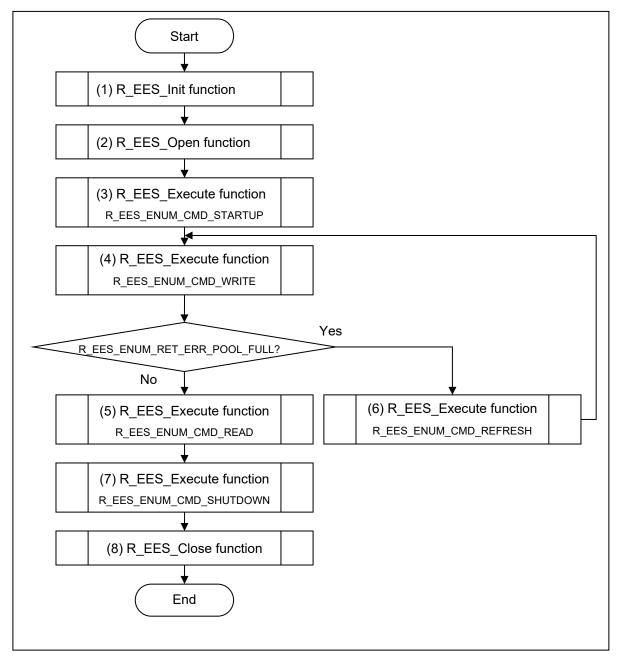


Figure 5-4 Basic Flowchart of EES

Notes 1: When using the EEPROM emulation for the first time, be sure to execute the

R\_EES\_ENUM\_CMD\_FORMAT command.

2: This flowchart omits error handling and R\_EES\_Handler processing after command execution.

[Overview of basic operation flow]

- EES initialization processing (R\_EES\_Init)
   Initialize the parameters used by the EES.
- (2) EEPROM emulation preparation processing (R\_EES\_Open)
  Set the data flash memory to a state (opened) for which control is enabled to execute EEPROM emulation.
- (3) EEPROM emulation execution start processing (R\_EES\_Execute: R\_EES\_ENUM\_CMD\_STARTUP command)
  Set the system to a state (Full Access) in which EEPROM emulation can be executed.
- (4) EEPROM emulation data write processing (R\_EES\_Execute: R\_EES\_ENUM\_CMD\_WRITE command) Write the specified data to an EES block.
- (5) EEPROM emulation data read processing (R\_EES\_Execute: R\_EES\_ENUM\_CMD\_READ command) Read the specified data from an EES block.
- (6) EEPROM emulation refresh processing (R\_EES\_Execute: R\_EES\_ENUM\_CMD\_REFRESH command)
  The latest stored data is copied from the active block (source block) to the next block (destination block)
  in the EES pool after the erase processing. This makes the copy destination block active.
- (7) EEPROM emulation execution stop processing (R\_EES\_Execute: R\_EES\_ENUM\_CMD\_SHUTDOWN command)
  Set the EEPROM emulation operation to the stopped state (opened).
- (8) EEPROM emulation end processing (R\_EES\_Close)

  Set the data flash memory to a state (closed) for which control is disabled to stop EEPROM emulation.

### 5.5 Command Operation Flowchart

The figure below shows the basic procedure to perform read and write operations for data flash by using the EES.

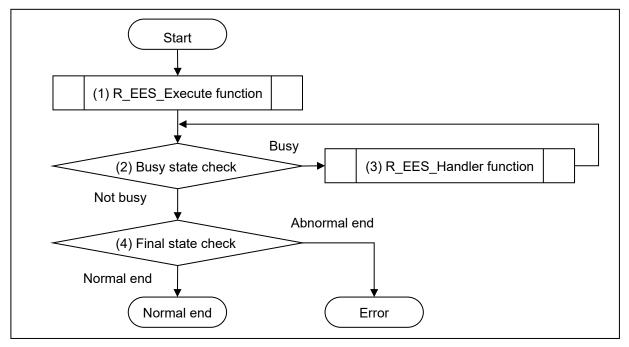


Figure 5-5 Command Operation Flowchart

### (1) R EES Execute function

Perform operations for the data flash memory.

#### (2) Busy state check

Check e\_status of the request structure (st\_ees\_request\_t).

When e\_status is R\_EES\_ENUM\_RET\_STS\_BUSY, continue the data flash operation. If the value of e\_status is other than R\_EES\_ENUM\_RET\_STS\_BUSY, check the final state.

### (3) R EES Handler function

Control the EES while it is running. By repeating the execution of the R\_EES\_Handler function, continue the data flash operation.

### (4) Final state check

If the final state is R\_EES\_ENUM\_RET\_STS\_OK, the operation ends normally. Otherwise, it will be terminated with an error.

## 5.6 Data Type Definitions

### 5.6.1 Data Types

Table 5-4 shows the data type definitions in EES RL78 Type 01.

Table 5-4 Data Type Definitions in EES RL78 Type 01

Macro Value	Туре	Description	
int8_t	signed char	1-byte signed integer	
uint8_t	unsigned char	1-byte unsigned integer	
int16_t	signed short	2-byte signed integer	
uint16_t	unsigned short	2-byte unsigned integer	
int32_t	signed long	4-byte signed integer	
uint32_t	unsigned long	4-byte unsigned integer	
bool	unsigned char	Boolean value (false = 0, true = 1)	

Remark: In the C language standard C 99 and later, these data types are defined in "stdint.h" and "stdbool.h".

### 5.6.2 Global Variables

The following shows the global variables used in EES RL78 Type 01.

(1) g\_ar\_u08\_ees\_descriptor[R\_EES\_VALUE\_U08\_VAR\_NO + 2u]

Type/Name	uint8_t g_ar_u08_ees_descriptor[]	
Default value	(uint8_t)(R_EES_VALUE_U08_VAR_NO), /* variable count */	
	(uint8_t)(sizeof(type_A)), /* id=1 */	
	(uint8_t)(sizeof(type_B)), /* id=2 */	
	(uint8_t)(sizeof(type_C)), /* id=3 */	
	(uint8_t)(sizeof(type_D)), /* id=4 */	
	(uint8_t)(sizeof(type_E)), /* id=5 */	
	(uint8_t)(sizeof(type_F)), /* id=6 */	
	(uint8_t)(sizeof(type_X)), /* id=7 */	
	(uint8_t)(sizeof(type_Z)), /* id=8 */	
	(uint8_t)(0x00u) /* zero terminator */	
Description	Stores the data size of each data identifier (Data ID).	
Definition file	r_ees_descriptor.c	

## (2) g\_st\_ees\_exrfd\_descriptor

Type/Name	st_ees_exrfd_descriptor_t g_st_ees_exrfd_descriptor		
Default value	(uint16_t) R_EES_EXRFD_VALUE_U16_PHYSICAL_BLOCK_SIZE		
	(uint8_t) R_EES_EXRFD_VALUE_U08_PHYSICAL_BLOCKS_PER_VIRTUAL_BLOCK		
	(uint8_t) R_EES_EXRFD_VALUE_U08_POOL_VIRTUAL_BLOCKS		
Description	Contains settings that configure the EES pool		
	<ul><li>uint16_t u16_ees_physical_block_size;</li></ul>		
	The size of one block of data flash memory (Physical block size).		
	Example: This value is fixed for RL78/G2x. (256u)		
	• uint8_t u08_ees_physical_blocks_per_virtual_block;		
	The number of data flash memory blocks to set in the EES block (Number of physical blocks).		
	Example: When setting 512 bytes for EES block. Number of data flash memories. (2u)		
	Example: When setting 1024 bytes for EES block. Number of data flash memories. (4u)		
	• uint8_t u08_ees_pool_virtual_blocks;		
	EES pool size (Number of virtual blocks)		
	Example: Total EES blocks. (4u)		
Definition file	r_ees_descriptor.c		

## (3) g\_ar\_u16\_ram\_ref\_table[R\_EES\_VALUE\_U08\_VAR\_NO]

Type/Name	uint16_t g_ar_u16_ram_ref_table[]
Default value	-
Description	Contains reference data for each data identifier (Data ID).
Definition file	r_ees_descriptor.c

### 5.6.3 Enumerations

e\_ees\_command (enumerated-type variable name: e\_ees\_command\_t)
 EES executable command

Symbol Name	Value	Description
R_EES_ENUM_CMD_UNDEFINED	0x00	Undefined command (Initial value)
R_EES_ENUM_CMD_STARTUP	0x01	Startup processing
R_EES_ENUM_CMD_WRITE	0x02	Write processing
R_EES_ENUM_CMD_READ	0x03	Read processing
R_EES_ENUM_CMD_REFRESH	0x04	Refresh processing
R_EES_ENUM_CMD_FORMAT	0x06	Format processing
R_EES_ENUM_CMD_SHUTDOWN	0x07	Shutdown processing

- e\_ees\_ret\_status (enumerated-type variable name: e\_ees\_ret\_status\_t)
- EES return values

Symbol Name	Value	Description
R_EES_ENUM_RET_STS_OK	0x00	Normal end
R_EES_ENUM_RET_STS_BUSY	0x01	Busy
R_EES_ENUM_RET_ERR_CONFIGURATION	0x82	EES configuration error
R_EES_ENUM_RET_ERR_INITIALIZATION	0x83	EES initialization error
R_EES_ENUM_RET_ERR_ACCESS_LOCKED	0x84	EEPROM emulation lock error
R_EES_ENUM_RET_ERR_PARAMETER	0x85	Parameter error
R_EES_ENUM_RET_ERR_WEAK	0x86	Weak error
R_EES_ENUM_RET_ERR_REJECTED	0x87	Reject error
R_EES_ENUM_RET_ERR_NO_INSTANCE	0x88	No instance
R_EES_ENUM_RET_ERR_POOL_FULL	0x89	Pool full error
R_EES_ENUM_RET_ERR_POOL_INCONSISTENT	0x8A	EES block Inconsistency error
R_EES_ENUM_RET_ERR_POOL_EXHAUSTED	0x8B	EES block exhaustion error
R_EES_ENUM_RET_ERR_INTERNAL	0x8C	Internal error
R_EES_ENUM_RET_ERR_FLASH_SEQ	0x8D	Flash sequencer error

• e\_ees\_exrfd\_ret\_status (enumerated-type variable name: e\_ees\_exrfd\_ret\_status\_t)

These enumeration types are used internally by EES. It does not need to be used directly by the user.

RFD control functions for EES return values

Symbol Name	Value	Description
R_EES_EXRFD_ENUM_RET_STS_OK	0x00	Normal end
R_EES_EXRFD_ENUM_RET_STS_BUSY	0x01	Busy
R_EES_EXRFD_ENUM_RET_ERR_CONFIGURATION	0x10	Configuration error
R_EES_EXRFD_ENUM_RET_ERR_INITIALIZATION	0x11	Initialization error
R_EES_EXRFD_ENUM_RET_ERR_REJECTED	0x12	Reject error
R_EES_EXRFD_ENUM_RET_ERR_PARAMETER	0x13	Parameter error
R_EES_EXRFD_ENUM_RET_ERR_INTERNAL	0x14	Internal error
R_EES_EXRFD_ENUM_RET_ERR_MODE_MISMATCHED	0x20	Mode mismatch error
R_EES_EXRFD_ENUM_RET_ERR_CFDF_SEQUENCER	0x21	Code/data flash area sequencer error
R_EES_EXRFD_ENUM_RET_ERR_ERASE	0x22	Erase operation error
R_EES_EXRFD_ENUM_RET_ERR_BLANKCHECK	0x23	Blank check operation error
R_EES_EXRFD_ENUM_RET_ERR_WRITE	0x24	Write operation error

## 5.7 Specifications of API Functions

This section describes the detailed specifications of the API functions of EEPROM Emulation Software (EES) RL78 Type 01.

There are some prerequisites for using the API functions of EES RL78 Type 01 to reprogram the data flash memory. If the prerequisites are not satisfied, execution of the API functions may result in indeterminate operation.

### Prerequisites:

- Execute the R\_EES\_Init function once before starting the use of EES functions.
- The high-speed on-chip oscillator must be active while self-programming is in progress. Execute API functions of EES RL78 Type 01 only while the high-speed on-chip oscillator is active.
- To control the data flash memory, execute API functions of EES RL78 Type 01 while access to the data flash memory is enabled. For the method of enabling access to the data flash memory, refer to "User's Manual: Hardware" of a target device.

The following shows the format for describing the specifications of API functions.

#### **Description format:**

#### Information:

Syntax	Syntax for calling this function from a C-language program		
Reentrancy	Reentrant or Non-reentrant		
Parameters (IN)	Input parameters for this function	Parameter [Value, range, meaning of the parameter, etc.]	
Parameters (IN/OUT)	Input/output parameters for this function	Parameter [Value, range, meaning of the parameter, etc.]	
Parameters (OUT)	Output parameters for this function	Parameter [Value, range, meaning of the parameter, etc.]	
Return Value	Type of the return value from this function	Enumerator (constant value) of the return value: Value	
	(Enumerated type, pointer type, etc.)	[Meaning of the constant: Detailed description]	
		Enumerator (constant value) of the return value: Value	
		[Meaning of the constant: Detailed description]	
Description	Overview of function		
Preconditions	Overview of preconditions		
Remarks	Special notes on this function		

### **Details of Specifications:**

The operation of this function is described.

#### Notes:

Conditions of usage or restrictions on this function are described.



### 5.7.1 Specifications of API Functions for EES RL78 Type 01

This section describes the API functions used for EES RL78 Type 01.

### 5.7.1.1 R\_EES\_Init

#### Information:

Syntax	R_EES_FAR_FUNC e_ees_ret_status_t R_EES_Init(uint8_t i_u08_cpu_frequency);	
Reentrancy	Non-reentrant	
Parameters	uint8_t	CPU operating frequency
(IN)	i_u08_cpu_frequency	[1 - 32(MHz)] (Target: All devices)
		[48 (MHz)] (Target: RL78/G24)
Parameters	N/A	
(IN/OUT)		
Parameters	N/A	
(OUT)		
Return Value	e_ees_ret_status_t	R_RFD_ENUM_RET_STS_OK: 0x00
		[Normal end]
		R_EES_ENUM_RET_ERR_CONFIGURATION: 0x82
		[EES configuration error]
Description	Initializes internal data and variables and checks the descriptor configuration.	
Preconditions	Execute this function while the high-speed on-chip oscillator is active.	
Remarks	Execute this function once before starting the use of EES functions.	

### **Details of Specifications:**

· Set the parameter (CPU operating frequency) to the R EES EXRFD Init function and execute it.

#### Notes:

- When the configuration for executing the EEPROM emulation such as EES pool or EES block size is abnormal, the return value will return a EES configuration error (R EES ENUM RET ERR CONFIGURATION).
- The high-speed on-chip oscillator needs to be kept active while EEPROM emulation is in progress. Execute this function while the high-speed on-chip oscillator is active.
  - \* EES RL78 Type 01 does not activate or check the high-speed on-chip oscillator.
- For the parameter (i\_u08\_cpu\_frequency), specify the integer obtained by rounding up the fraction of the CPU operating frequency that is actually used in the microcontroller.
  - (Example: When the CPU operates at 4.5 MHz, specify 5 in this initialization function.)
  - When the CPU operates at a frequency lower than 4 MHz, a value of 1 MHz, 2 MHz, or 3 MHz can be used but a non-integer value such as 1.5 MHz cannot be used.

The frequency specified in the parameter (i\_u08\_cpu\_frequency) should be the actual frequency at which the CPU operates during flash memory reprogramming; it is not necessarily that the frequency of the high-speed on-chip oscillator should be specified.

- If the specified frequency differs from the actual CPU operating frequency, the subsequent operation is indeterminate. In this case, even if flash memory reprogramming is completed, the written data value and data retention period may not be guaranteed.
  - \* For the range of the CPU operating frequency, refer to "User's Manual: Hardware" of a target device.

## 5.7.1.2 R\_EES\_Open

### Information:

Syntax	R_EES_FAR_FUNC e_ees_ret_status_t R_EES_Open(void);	
Reentrancy	Non-reentrant	
Parameters	N/A	
(IN)		
Parameters	N/A	
(IN/OUT)		
Parameters	N/A	
(OUT)		
Return Value	e_ees_ret_status_t	R_EES_ENUM_RET_STS_OK: 0x00
		[Normal end]
		R_EES_ENUM_RET_ERR_ REJECTED: 0x87
		[Reject error]
Description	EEPROM emulation preparation processing. This function makes the EEPROM emulation executable.	
Preconditions	R_EES_Init function must have finished normally.	
Remarks	-	

## **Details of Specifications:**

• Execute the R\_EES\_EXRFD\_Open function to make the data flash memory accessible.

### Notes:

• When the R\_EES\_Init function is not executed and the internal variable has not been initialized, the return value will return a reject error (R\_EES\_ENUM\_RET\_ERR\_REJECTED).

## 5.7.1.3 R\_EES\_Close

### Information:

Syntax	R_EES_FAR_FUNC e_ees_ret_status_t R_EES_Close(void);	
Reentrancy	Non-reentrant	
Parameters (IN)	N/A	
Parameters (IN/OUT)	N/A	
Parameters (OUT)	N/A	
Return Value	e_ees_ret_status_t	R_EES_ENUM_RET_STS_OK: 0x00 [Normal end]
Description	EEPROM emulation end processing. This function makes the EEPROM emulation un-executable.	
Preconditions	-	
Remarks	-	

### **Details of Specifications:**

• Executes the R\_EES\_EXRFD\_Close function and finishes the EEPROM emulation.

#### Notes:

• If EEPROM emulation was executed, the R\_EES\_ENUM\_CMD\_SHUTDOWN command must be used to set EEPROM emulation to the stopped state (the open state).

### 5.7.1.4 R\_EES\_Execute

#### Information:

Syntax	R_EES_FAR_FUNC void R_EES_Execute(st_ees_request_tnear * ionp_st_ees_request);	
Reentrancy	Non-reentrant	
Parameters	N/A	
(IN)		
Parameters (IN/OUT)	st_ees_request_tnear * ionp_st_ees_request	Pointer to the request structure (st_ees_request_t)
Parameters	N/A	
(OUT)		
Return Value	N/A	
Description	EEPROM emulation execution function.  Each type of processing for performing EEPROM emulation operations is specified for this function as an argument in the command format, and the processing is executed.	
Preconditions	R_EES_Init and R_EES_Open function must have finished normally.	
Remarks	-	

### **Details of Specifications:**

• Starts processing of the command set in the Request structure.

#### Notes:

- The R\_EES\_Execute function starts command processing and then immediately returns the control to the user program. The command processing is continued by executing the R\_EES\_Handler function. Therefore, the R\_EES\_Handler function must be executed continuously until the command processing is completed.
- Execute the repeat the R\_EES\_Handler function while the e\_status of the Request structure(st\_ees\_request\_t) is R\_EES\_ENUM\_RET\_STS\_BUSY.
- It is not allowed to call R\_EES\_Execute function in an interrupt service routine.

## Command Execution States of R\_EES\_Execute/R\_EES\_Handler (e\_ees\_ret\_status\_t) (1/2)

Command Execution Status	Category	Description	Corresponding Commands	
R_EES_ENUM_RET_STS_	Meaning	Normal end		
OK	Cause	None	All commands	
	Action to	None		
	be taken			
R_EES_ENUM_RET_STS_	Meaning	A command is being executed.	Commands other than	
BUSY	Cause	None	R_EES_ENUM_CMD_	
	Action to be taken	Keep calling the R_EES_Handler function until the status changes.	SHUTDOWN	
R_EES_ENUM_RET_ERR_	Meaning	Initialization error		
INITIALIZATION	Cause	R_EES_Init, and R_EES_Open functions have not been finished normally.	All commands	
	Action to be taken	Normally finish the R_EES_Init, and R_EES_Open functions.		
R_EES_ENUM_RET_ERR_	Meaning	EEPROM emulation lock error	Commands other than	
ACCESS_LOCKED	Cause	EEPROM emulation cannot be executed.	R_EES_ENUM_CMD_	
	Action to be taken	Make sure that the R_EES_ENUM_CMD_STARTUP command has finished normally.	STARTUP and R_EES_ENUM_CMD_ FORMAT.	
R_EES_ENUM_RET_ERR_	Meaning	Parameter error		
PARAMETER	Cause	An incorrect command parameter has been specified.	All commands	
	Action to be taken	Check the specified parameter.	- All commands	
R_EES_ENUM_RET_ERR_	Meaning	Found weak data in the active block header or instances.		
WEAK	Cause	Write processing an active block header or stored data may have been interrupted.	R_EES_ENUM_CMD_ STARTUP	
	Action to be taken	Execute the R_EES_ENUM_CMD_REFRESH command.		
R_EES_ENUM_RET_ERR_	Meaning	Reject error		
REJECTED	Cause	A different command is being executed.		
	Action to be taken	Call the R_EES_Handler function to terminate the ongoing command.	All commands	

## Command Execution States of R\_EES\_Execute/R\_EES\_Handler (e\_ees\_ret\_status\_t) (2/2)

Command Execution Status	Category	Description	Corresponding Commands	
R_EES_ENUM_RET_ERR_	Meaning	No-write-data error		
NO_INSTANCE	Cause	The specified identifier data has not been written.	R_EES_ENUM_CMD_	
	Action to	Write data to the identifier specified using the	READ	
	be taken	R_EES_ENUM_CMD_WRITE command.		
R_EES_ENUM_RET_ERR_	Meaning	Pool full error		
POOL_FULL	Cause	There is no area that can be used to write the data.	R_EES_ENUM_CMD_	
	Action to be taken	Execute the R_EES_ENUM_CMD_REFRESH command and restart writing data.	WRITE	
R_EES_ENUM_RET_ERR_	Meaning	EES block inconsistency error		
POOL_INCONSISTENT	Cause	An EES block has the undefined state (such as there are no active blocks).	R_EES_ENUM_CMD_ STARTUP	
	Action to be taken	Execute the R_EES_ENUM_CMD_FORMAT command to initialize the EES blocks.	-STARTUP	
R_EES_ENUM_RET_ERR_	Meaning	EES block exhaustion error	R_EES_ENUM_CMD_	
POOL_EXHAUSTED	Cause	There are no more EES blocks that can be used to continue.	STARTUP R_EES_ENUM_CMD_	
	Action to be taken	Stop EEPROM emulation. You can try restoration by executing the R_EES_ENUM_CMD_FORMAT command (erasing all existing data) or read existing data	FORMAT  R_EES_ENUM_CMD_  REFRESH  R_EES_ENUM_CMD_  WRITE	
R_EES_ENUM_RET_ERR_	Meaning	Internal error		
INTERNAL	Cause	An unexpected error has occurred.	Commands other than R_EES_ENUM_CMD_	
	Action to	Exit the EEPROM emulation.	SHUTDOWN	
	be taken	Check the device state.		
R_EES_ENUM_RET_ERR_	Meaning	Flash area sequencer error		
FLASH_SEQ	Cause	EES failed to change flash memory mode or start flash sequencer.	Commands other than	
	Action to be taken	The EES should be stopped. Check whether flash memory operation using RFD RL78 Type 01 is executed besides operation of an EEPROM emulation.	R_EES_ENUM_CMD_ SHUTDOWN	

### 5.7.1.5 R\_EES\_Handler

#### Information:

Syntax	R_EES_FAR_FUNC void R_EES_Handler(void);	
Reentrancy	Non-reentrant	
Parameters	N/A	
(IN)		
Parameters (IN/OUT)	N/A	
Parameters (OUT)	N/A	
Return Value	N/A	
Description	Continuous EEPROM emulation execution processing.  This function is used to check for the completion of processing while allowing processing of EEPROM emulation specified by the R_EES_Execute function to continue.	
Preconditions	R_EES_Init and R_EES_Open function must have finished normally.	
Remarks	-	

### **Details of Specifications:**

• Continues processing the EEPROM emulation initiated by the R\_EES\_Execute function.

### Notes:

- While "e\_status" of the request structure (st\_ees\_request\_t) is R\_EES\_ENUM\_RET\_STS\_BUSY, execute this function repeatedly.
- It is not allowed to call R\_EES\_Handler() in an interrupt service routine.
- The command execution status of the R\_EES\_Handler function is set for the "st\_ees\_request\_t \* ionp\_st\_ees\_request" used as an argument of the R\_EES\_Execute function. Therefore, when using the R\_EES\_Handler function, do not free the "st\_ees\_request\_t \* ionp\_st\_ees\_request" variable.

### 5.7.1.6 R\_EES\_GetSpace

#### Information:

Syntax	R_EES_FAR_FUNC e_ees_ret_status_t R_EES_GetSpace(uint16_tnear * onp_u16_space);	
Reentrancy	Non-reentrant	
Parameters (IN)	N/A	
Parameters (IN/OUT)	N/A	
Parameters (OUT)	uint16_tnear * onp_u16_space	Pointer to variable that contains free space information for the current active block.
Return Value	e_ees_ret_status_t	R_EES_ENUM_RET_STS_OK: 0x00 [Normal end]  R_EES_ENUM_RET_ERR_INITIALIZATION: 0x83 [EES initialization error]  R_EES_ENUM_RET_ERR_ACCESS_LOCKED: 0x84 [EEPROM emulation lock error]  R_EES_ENUM_RET_ERR_REJECTED: 0x87 [Reject error]
Description	Gets the free space of the active block.	
Preconditions	R_EES_Init and R_EES_Open function must have finished normally.  R_EES_Execute function and the R_EES_ENUM_CMD_STARTUP command must be executed successfully before.	
Remarks		

### **Details of Specifications:**

• Calculate the free space of the active block.

#### Notes:

- When the R\_EES\_Init function is not executed and the internal variable has not been initialized, the return value will return a EES initialization error (R\_EES\_ENUM\_RET\_ERR\_INITIALIZATION).
- When the R\_EES\_ENUM\_CMD\_STARTUP command does not finish normally with the R\_EES\_Execute function, the return value will return a EEPROM emulation lock error (R\_EES\_ENUM\_RET\_ERR\_ACCESS\_LOCKED).
- When the R\_EES\_Execute function is executing a EES command, the return value will return a Reject error (R\_EES\_ENUM\_RET\_ERR\_REJECTED).
- In case the EES pool is exhausted the returned space value will always be 0x0000.
- When the write operation of the "active block header" or "stored data written" may have been interrupted, 0x0000 is returned to the free space.
- When an error value is returned, the free space information is not collected.

### 5.7.2 RFD Control API Functions for EES

This section describes the RFD control API functions for EES. These functions are called from the EES control function. Do not call it directly from a user program.

### Information:

Syntax	R_EES_FAR_FUNC e_ees_exrfd_ret_status_t R_EES_EXRFD_Init(	
	uint8_t i_u08_cpu_frequency);	
Description	Initializes RFD RL78 Type 01.	

### Information:

Syntax	R_EES_FAR_FUNC e_ees_exrfd_ret_status_t R_EES_EXRFD_Open(void);
Description	Set the data flash control register (DFLCTL) to the state where accessing the data flash memory is permitted(DFLEN = 1).

### Information:

Syntax	R_EES_FAR_FUNC e_ees_exrfd_ret_status_t R_EES_EXRFD_Close(void);
Description	Set the data flash control register (DFLCTL) to the state where access to the data flash memory is inhibited (DFLEN = 0). All ongoing EES processing stop.

### Information:

Syntax	R_EES_FAR_FUNC e_ees_exrfd_ret_status_t R_EES_EXRFD_Erase(
	uint8_t i_u08_virtual_block_number);
Description	Start erasing the EES block(one virtual block).

### Information:

Syntax	R_EES_FAR_FUNC e_ees_exrfd_ret_status_t R_EES_EXRFD_Write(
	uint16_t i_u16_offset_addr,
	uint8_tnear * inp_u08_write_data,
	uint16_t i_u16_size);
Description	Starts writing to the specified the data flash memory address(one byte).

Syntax	R_EES_FAR_FUNC e_ees_exrfd_ret_status_t R_EES_EXRFD_BlankCheck(
	uint16_t i_u16_offset_addr,
	uint16_t i_u16_size);
Description	Starts Blank check to the specified the data flash memory address.

### Information:

Syntax	R_EES_FAR_FUNC e_ees_exrfd_ret_status_t R_EES_EXRFD_Read(
	uint16_t i_u16_offset_addr,
	uint8_tnear * onp_u08_read_data,
	uint16_t i_u16_size);
Description	Reads the specified address in the data flash memory.

### Information:

Syntax	R_EES_FAR_FUNC e_ees_exrfd_ret_status_t R_EES_EXRFD_Handler(void);
Description	Continues processing of the RFD control function for EES that is executing, and confirms termination.

### Information:

Syntax	static R_EES_FAR_FUNC e_ees_exrfd_ret_status_t
	r_ees_exrfd_get_seq_error_status(void);
Description	Obtain the execution result from the flash memory sequencer.

### Information:

Syntax	static R_EES_FAR_FUNC e_ees_exrfd_ret_status_t r_ees_exrfd_finish_state(void);
Description	Sets the RFD control functions for EES to the end status.

### Information:

Syntax	static R_EES_FAR_FUNC e_ees_exrfd_ret_status_t
	r_ees_exrfd_check_cmd_executable(void);
Description	Check the status and flags of the RFD control functions for EES.

### Information:

Syntax	static R_EES_FAR_FUNC bool r_ees_exrfd_is_valid_byte_parameter(
	uint16_t i_u16_offset_addr,
	uint16_t i_u16_size);
Description	Check the parameters used by the RFD Control functions for EES.

### Information:

Syntax	static R_EES_FAR_FUNC void r_ees_exrfd_clear_cmd_workarea(void);
Description	Clears the data area used by the RFD control functions for EES.

Syntax	static R_EES_FAR_FUNC void r_ees_exrfd_blankcheck_byte_req(
	uint32_t i_u32_start_addr,
	uint16_t i_u16_size);
Description	Starts Blank check to the specified the data flash memory address

### 5.7.3 Internal Functions for the EES

This section describes the functions used by the EES functions. These functions are internal functions called from the EES functions. Do not call it directly from a user program.

#### Information:

Syntax	R_EES_FAR_FUNC bool r_ees_is_valid_configuration(void);
Description	Check the EES configuration and initialize the internal status.

### Information:

Syntax	R_EES_FAR_FUNC bool r_ees_is_valid_requester(
	st_ees_request_tnear * ionp_st_ees_request);
Description	Check "request structure" and "EES status" and update internal status.

#### Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_startup_state_00(void); ~  R_EES_FAR_FUNC void r_ees_fsm_startup_state_09(void);
Description	Updates the internal status for startup processing.

#### Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_write_state_00(void); ~  R_EES_FAR_FUNC void r_ees_fsm_write_state_04(void);
Description	Updates the internal status for write processing.

### Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_read_state_00(void); ~ R_EES_FAR_FUNC void r_ees_fsm_read_state_01(void);
Description	Updates the internal status for read processing.

### Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_refresh_state_00(void); ~ R_EES_FAR_FUNC void r_ees_fsm_refresh_state_17(void);
Description	Updates the internal status for refresh processing.

## Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_format_state_00(void); ~  R_EES_FAR_FUNC void r_ees_fsm_format_state_11(void);
Description	Updates the internal status for format processing.

Syntax	R_EES_FAR_FUNC void r_ees_fsm_shutdown_state_00(void);
Description	Execute the shutdown processing of the EEPROM emulation.

### Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_exrfd_cmd_erase_state_00(void);
Description	Start the erase processing.

### Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_exrfd_cmd_bw_state_00(void);
Description	Starts the blank check and write processing.

### Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_exrfd_cmd_inner_blankcheck_state_00(void);
Description	Start internal processing of the blank check.

#### Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_exrfd_cmd_write_state_00(void);	
Description	Start the write processing.	

### Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_exrfd_cmd_inner_write_state_00(void);	
Description	Start internal processing of the write.	

### Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_exrfd_cmd_read_state_00(void);	
Description	Start the read processing.	

### Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_exrfd_cmd_state_01(void);	
Description	Proceed with the internal processing of the executed RFD control functions for EES.	

#### Information:

Syntax	R_EES_FAR_FUNC void r_ees_fsm_exit_state(void);	
Description	Dummy processing.	

Syntax	static R_EES_FAR_FUNC uint8_t r_ees_calculate_next_a_flag(	
	uint8_t i_u08_a_flag_value);	
Description	Calculates the value of the A flag.	

### Information:

Syntax	static R_EES_FAR_FUNC void r_ees_fsm_finish_command(void);	
Description	Terminates the execution command.	

### Information:

Syntax	static R_EES_FAR_FUNC void r_ees_fsm_swap_acvive_block_info(void);	
Description	Swaps the active block information.	

## Information:

Syntax	static R_EES_FAR_FUNC bool r_ees_fsm_exrfd_cmd_detect_fatal_error(	
	e_ees_exrfd_ret_status_t i_e_ees_exrfd_ret_value);	
Description	Check the results of the RFD control function for the EES for errors that make the EES unsustainable.	

### Information:

Syntax	static R_EES_FAR_FUNC e_ees_block_status_t	
	r_ees_fsm_get_ees_block_status(void);	
Description	Obtains the state of the EES block.	

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EES RL78 Type 01 6. Sample Programs

# 6. Sample Programs

This chapter describes the sample programs provided together with EES RL78 Type 01. This chapter is explained in the sample program example for RL78/G23. When using a device other than RL78/G23, read "G23" to the target device.

### 6.1 File Structure

### 6.1.1 Folder Structure

Figure 6-1 shows the structure of sample program folders.

Figure 6-1 shows an example of using RL78/G23. The installed "sample" folder contains a folder for each device group (e.g. RL78\_G23, RL78\_G24). Read the folder name "RL78\_G23" of the sample of RL78/G23 as the folder name of a target device.

The folder name in the case of using RL78/G24: "RL78\_G24"

When using the sample programs, include only the folder for the target device.

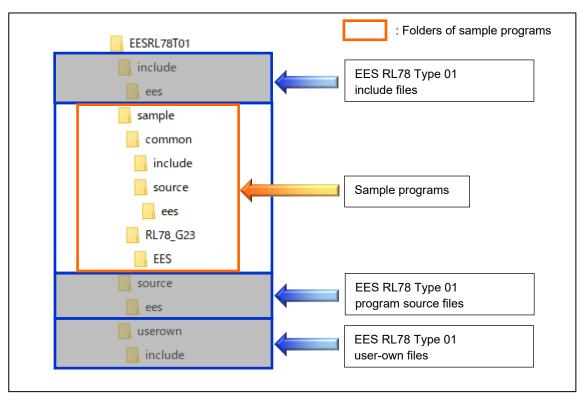


Figure 6-1 Structure of Sample Program Folders

#### 6.1.2 List of Files

#### 6.1.2.1 List of Source Files

Table 6-1 shows the program source file in the "sample\common\source\ees\" folder.

Table 6-1 Program Source File in the "sample\common\source\ees\" Folder

No.	Source File Name	Description
1	sample_control_ees.c	This file contains the functions for controlling the EEPROM emulation.

Table 6-2 shows the program source file of the main processing in the "sample\RL78\_G23" folder.

"sample\RL78\_G23\EES\[compiler name]\source\" folder

Table 6-2 Program Source File of the Main Processing

No.	Source File Name	Description
1	main.c	Sample file of the main processing functions

#### 6.1.2.2 List of Header Files

Table 6-3 shows the program header files in the "sample\common\include\" folder.

Table 6-3 Program Header Files in the "sample\common\include\" Folder

No.	Header File Name	Description
1	sample_control_ees.h	This file defines the prototype declarations of the sample functions for controlling the EEPROM emulation.
2	sample_ees_defines.h	This file defines the macros of the sample functions for controlling the EEPROM emulation.
3	sample_ees_memmap.h	This file defines the macros that describes the sections used by the sample program that controls the EEPROM emulation.

## 6.2 Data Type Definitions

### 6.2.1 Macro Defines

- Frequency setting macro

CPU frequency used in the sample program.

Symbol Name	Value	Description
SAMPLE_VALUE_U08_CPU_FREQUENCY	32u	CPU frequency (RL78_G23 folder)
	48u	CPU frequency (RL78_G24 folder)

EES RL78 Type 01 6. Sample Programs

## 6.3 Sample Program Functions

Table 6-5 shows the sample program functions.

**Table 6-4** List of Sample Program Functions

	API Function Name	Outline
1	main	Executes the main processing of the sample program for controlling the EES.
2	Sample_EES_Control	Write and read EES blocks according to the basic procedure for using EES.

### 6.3.1 Sample Program for Controlling the EEPROM Emulation

The EES RL78 Type 01 rewrite control sample follows the basic operation procedure for using EES and performs the rewrite and read processing of EES block.

Note: During EES command processing, the data in the data flash memory cannot be referenced.

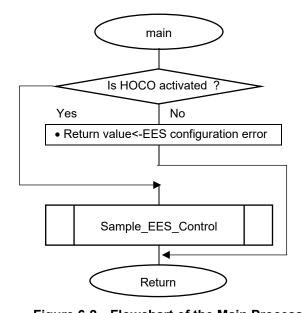
Copy the data to be referenced within the function to RAM in advance, and reference them in RAM.

Operating conditions (Example of a sample program for RL78/G23):

CPU operating frequency: 32 MHz
 (The high-speed on-chip oscillator clock (HOCO) is used for the main system clock.)

Figure 6-2 shows a flowchart of the main processing of the sample program for the EES.

#### 6.3.1.1 main Function



- Processing for controlling the EEPROM emulation
- Return value <- Value returned from the function

Figure 6-2 Flowchart of the Main Processing of the Sample Program for Controlling the EES.

EES RL78 Type 01 6. Sample Programs

### 6.3.1.2 Sample\_EES\_Control Function

- Figure 6-3 shows the pre-processing required to use the EES and the write and read processing flow.
- Initialize the EES.

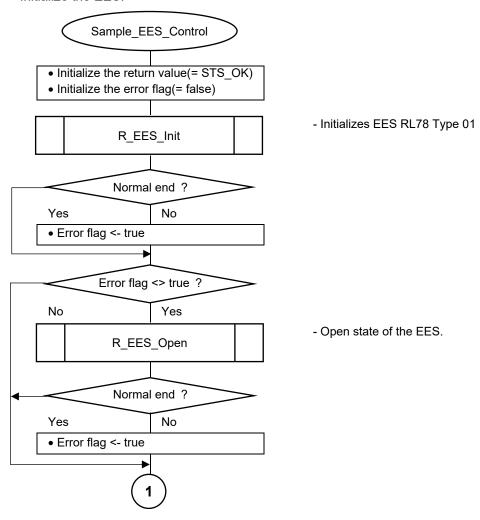


Figure 6-3 Flowchart of Sample Processing for Controlling EEPROM Emulation (1/5)

EES RL78 Type 01 6. Sample Programs

EEPROM emulation execution startup processing.

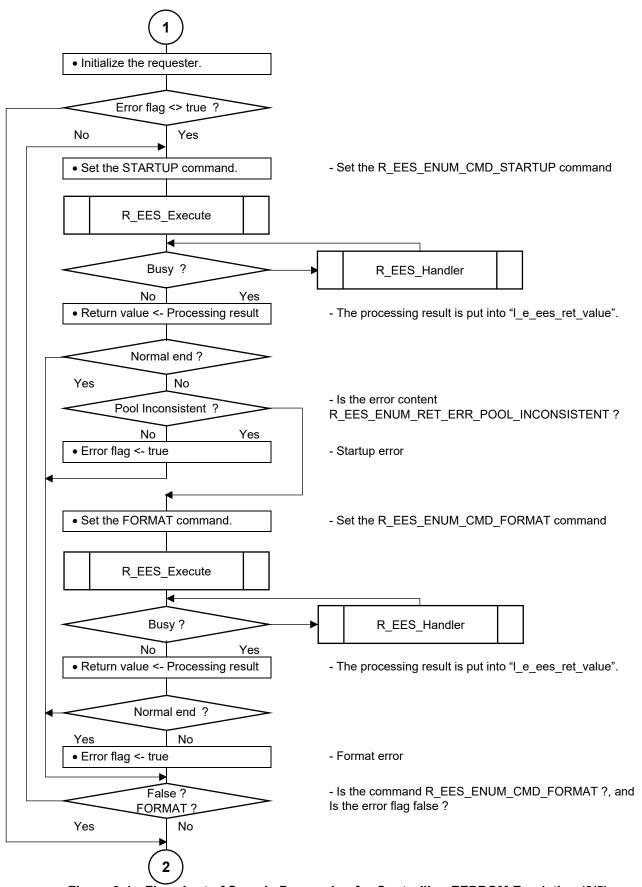


Figure 6-4 Flowchart of Sample Processing for Controlling EEPROM Emulation (2/5)

EES RL78 Type 01 6. Sample Programs

• EEPROM emulation data write processing.

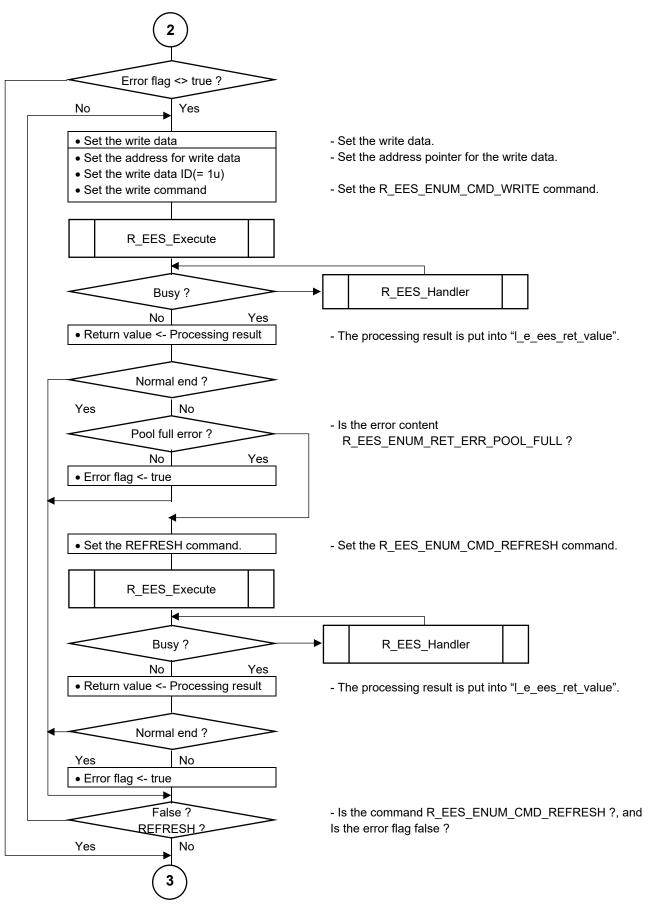


Figure 6-5 Flowchart of Sample Processing for Controlling EEPROM Emulation (3/5)

EES RL78 Type 01 6. Sample Programs

· EEPROM emulation data read processing.

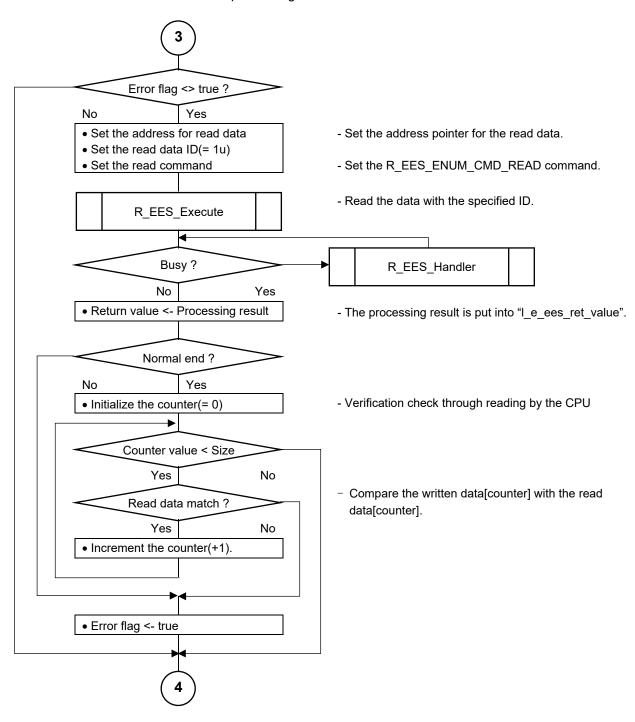


Figure 6-6 Flowchart of Sample Processing for Controlling EEPROM Emulation (4/5)

• EEPROM emulation shutdown processing.

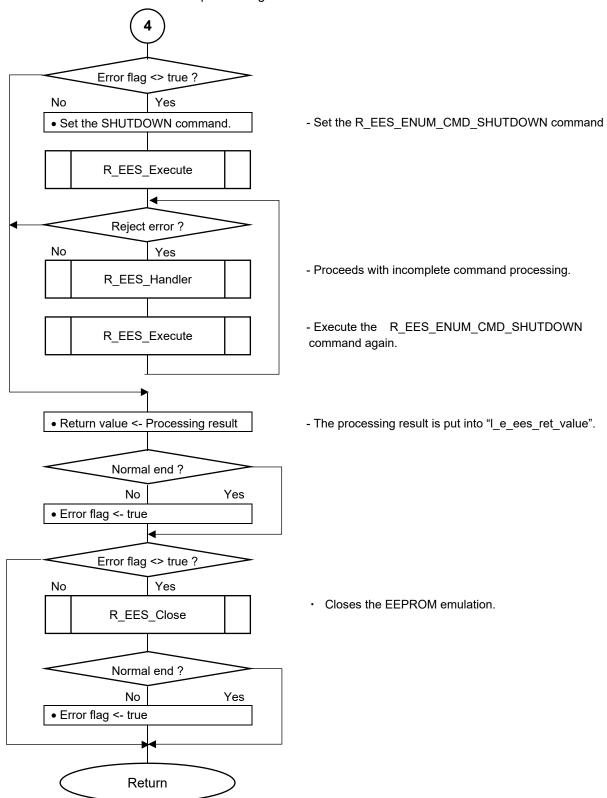


Figure 6-7 Flowchart of Sample Processing for Controlling EEPROM Emulation (5/5)

Note: Error handling and user processing for normal completion are omitted.

# 6.4 Specifications of Sample Program Functions

This section describes the specifications of the functions in the sample programs for EES RL78 Type 01. The sample programs for EEPROM emulation are examples of basic processing. The functions in the sample programs can be used as reference for developing an application program.

Please be sure to thoroughly check the operation of the developed application program.

# 6.4.1 Sample Program Functions for Controlling the EEPROM Emulation

#### 6.4.1.1 main

### Information:

Syntax	int main(void);	
Reentrancy	Non-reentrant	
Parameters	N/A	
(IN)		
Parameters	N/A	
(IN/OUT)		
Parameters	N/A	
(OUT)		
Return Value	int	R_EES_ENUM_RET_STS_OK: 0x00
		[Normal end]
	(e_ees_ret_status_t)	R_EES_ENUM_RET_STS_BUSY : 0x01 [Busy]
		R_EES_ENUM_RET_ERR_CONFIGURATION : 0x82 [EES configuration error]
		R_EES_ENUM_RET_ERR_INITIALIZATION : 0x83 [EES initialization error]
		R_EES_ENUM_RET_ERR_ACCESS_LOCKED : 0x84 [EEPROM emulation lock error]
		R_EES_ENUM_RET_ERR_PARAMETER : 0x85 [Parameter error]
		R_EES_ENUM_RET_ERR_WEAK : 0x86 [Weak error]
		R_EES_ENUM_RET_ERR_REJECTED : 0x87 [Reject error]
		R_EES_ENUM_RET_ERR_NO_INSTANCE : 0x88 [No instance]
		R_EES_ENUM_RET_ERR_POOL_FULL : 0x89 [Pool full error]
		R_EES_ENUM_RET_ERR_POOL_INCONSISTENT : 0x8A [EES block Inconsistency error]
		R_EES_ENUM_RET_ERR_POOL_EXHAUSTED : 0x8B [EES block exhaustion error]
		R_EES_ENUM_RET_ERR_INTERNAL : 0x8C [Internal error]
		R_EES_ENUM_RET_ERR_FLASH_SEQ : 0x8D [Flash sequencer error]
Description	Executes the main processing of the sample program for controlling the EES.	
Preconditions	-	
Remarks	-	
1.2		

EES RL78 Type 01 6. Sample Programs

# 6.4.1.2 Sample\_EES\_Control

# Information:

Syntax	R_EES_FAR_FUNC e_ees_ret_status_t	
Reentrancy	Non-reentrant	
Parameters (IN)	N/A	
Parameters (IN/OUT)	N/A	
Parameters (OUT)	N/A	
Return Value	e_ees_ret_status_t	R_EES_ENUM_RET_STS_OK: 0x00 [Normal end]  R_EES_ENUM_RET_STS_BUSY: 0x01 [Busy]  R_EES_ENUM_RET_ERR_CONFIGURATION: 0x82 [EES configuration error]  R_EES_ENUM_RET_ERR_INITIALIZATION: 0x83 [EES initialization error]  R_EES_ENUM_RET_ERR_ACCESS_LOCKED: 0x84 [EEPROM emulation lock error]  R_EES_ENUM_RET_ERR_PARAMETER: 0x85 [Parameter error]  R_EES_ENUM_RET_ERR_WEAK: 0x86 [Weak error]  R_EES_ENUM_RET_ERR_REJECTED: 0x87 [Reject error]  R_EES_ENUM_RET_ERR_NO_INSTANCE: 0x88 [No instance]  R_EES_ENUM_RET_ERR_POOL_FULL: 0x89 [Pool full error]  R_EES_ENUM_RET_ERR_POOL_INCONSISTENT: 0x8A [EES_BIOK Inconsistency error]  R_EES_ENUM_RET_ERR_POOL_EXHAUSTED: 0x8B [EES_BIOK exhaustion error]  R_EES_ENUM_RET_ERR_INTERNAL: 0x8C [Internal error]  R_EES_ENUM_RET_ERR_FLASH_SEQ: 0x8D [Flash sequencer error]
Description	Write and read EES blocks according to the basic procedure for using EES.	
Preconditions	-	
Remarks	When the verification check of the read data results in an error, it is not reflected in the return value.	

EES RL78 Type 01 6. Sample Programs

# 6.5 Precautions in Case of Using Sample Program

- The precautions in the case of using RL78/G24.

Only the case which sets an option byte(000C2H/040C2H) to 0xF0 and uses the clock frequency of CPU at 24 MHz is necessary for the following countermeasures. Modify into the comments or delete so that a part of sample program for RL78/G24 may not compile.

If a red character part is compiled, prefetch buffer will become valid and will operate at 48 MHz.

```
Target folder:
\EESRL78T01\sample\RL78_G24\EES\[Compiler name]\source\

Target file:
CC-RL and LLVM: hdwinit.c
IAR: low_level_init.c
```

The following red character parts are the examples which modified the source code to the comment.

```
/* Start HOCO. It must be started before flash control. */
HIOSTOP = 0u;
/* Check CPU frequency in the user option byte (0x000C2). */
/* 0xF0 : HS mode 48 MHz */
//if (0xF0u == (*(volatile unsigned char __far *)0x000C2u))
//
     /* Set CPU frequency 48 MHz (Enables the prefetch buffer). */
//
     HOCODIV = 0x00u;
     PFBE
//
              = 1u;
//
     FIHSEL = 1u;
//
//
     /* Confirm the switching status flag. */
     while (1u == FIHST)
//
//
//
          /* No operation */
//
//}
//else
//{
//
     /* No operation */
//}
```

# 7. Creating a Sample Project for EES RL78 Type 01

EES RL78 Type 01 includes a sample program to control EEPROM emulation. The compilers which can be used by EES RL78 Type 01 are a CC-RL compiler, an IAR compiler and a LLVM compiler. Users can create a sample project using the Integrated Development Environment (IDE) corresponding to each compiler.

The target sample programs differ in each device (e.g. RL78\_G23, RL78\_G24). This section is explained in the sample program example for RL78/G23. If you are using another device on the RL78/G23, change the G23 description to the target device. Section address settings must be changed by referring to the user's manual for the target device. In addition, Because the flash memory control scheme varies depending on the target device, the classification macro must be configured in the Integrated Development Environment (IDE). The setting method is described in "7.1.3.2 The Setting of User Definition Macro"(CC-RL), "7.2.3.2 The Setting of User Definition Macro"(LLVM).

If the RL78/G22 is used, the RL78/G23 sample program is available.

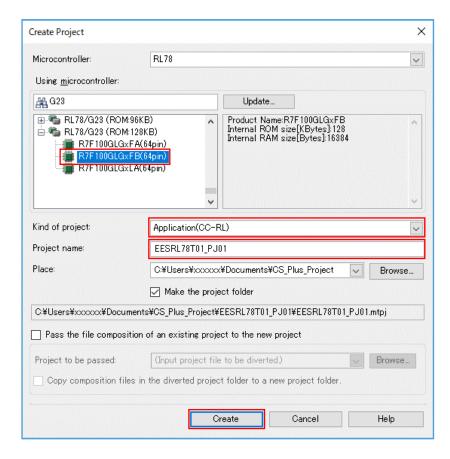
- Notes 1: The target Integrated Development Environment (IDE) and the compiler are premised on using the version for RL78/G2x. Be sure to use them, after confirming that RL78/G2x are target products.
  - 2: EES RL78 Type 01 uses the RFD RL78 Type 01 to control the data flash memory. However, it is not included in the EES RL78 Type 01 installer, RFD RL78 Type 01 must be installed before registering to the project. It describes the RFD RL78 Type 01 files and sections needed to register the project, however for more information on RFD RL78 Type 01, refer to the RFD RL78 Type 01 User's Manual.

# 7.1 Creating a Project in the Case of Using a CC-RL Compiler

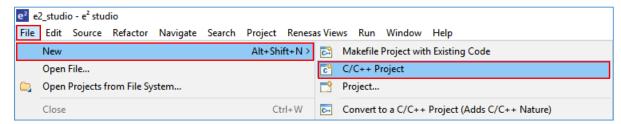
CS+ or e² studio can be used for a RENESAS CC-RL compiler as an IDE. EES RL78 Type 01 and RFD RL78 Type 01 are registered and built in the project created by the IDE. An example of creating a sample project in case each IDE is used is shown. Because to understand a CC-RL compiler and each IDE, it is necessary to refer to the user's manual of each tool product.

#### 7.1.1 Example of Creating a Sample Project

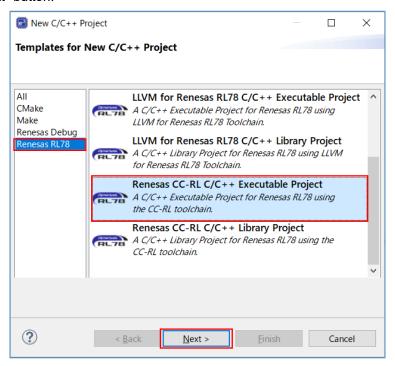
- (1) An example of creating a sample project which used CS+ (IDE)
- The CS+ starts and from the [Project] menu, select [Create New Project...], the "Create Project" window will open.
  - Select the product of "RL78/G23 (ROM: 128 Kbytes)" "R7F100GLGxFB(64pin)" as [Using microcontroller].
  - Select "Application(CC-RL)" as [Kind of project].
  - [Project name] is temporarily set to "EESRL78T01\_PJ01".
  - When you click the [Create] button, the new project is created.



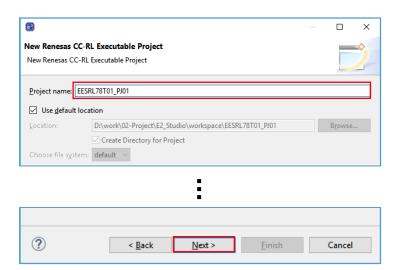
- (2) An example of creating a sample project which used e<sup>2</sup> studio (IDE)
- The e<sup>2</sup> studio starts and from the [File] menu, select [New] [C/C++ Project], the "Templates for New C/C++ Project" window will open.



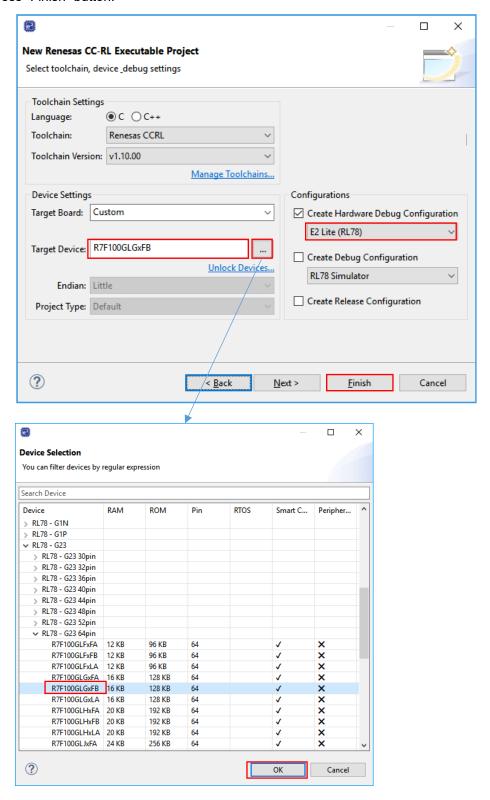
Select [Renesas CC-RL C/C++ Executable Project] displayed after selection in [Renesas RL78], and press
"next" button.



• Input "Project name" on "New Renesas CC-RL Executable Project" window, and press "next" button. [Project name] is temporarily set to "EESRL78T01\_PJ01".

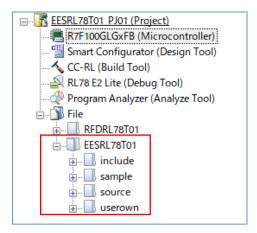


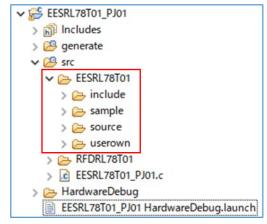
- Select the [Target Device] of [Device Settings], and select "RL78 G23" "RL78 G23 64pin" "R7F100GLGxFB".
- It is a premise that E2 Lite is selected as a debugging tool and on-chip debugging is executed. Put a check mark to "Create Hardware Debug Configuration" by [Configurations]. And select "E2 Lite(RL78)".
- · Press "Finish" button.



### 7.1.2 Example of Registration of Target Folders and Target Files

Using EES RL78 Type 01, when execute EEPROM emulation the example which registers necessary files is shown. Each folder of a "EESRL78T01" source program file is "include", "source", "userown", and "sample". As other registration methods, after all the folders of "include", "source", "userown", and "sample" are registered, unnecessary files and folders can be removed using the function of "Remove from Project" (CS+) or [Resource Configuration] – [Exclude from Build] (e² studio).





The registration tree screen of EES (CS+)

The registration tree screen of EES (e<sup>2</sup> studio)

• Registration of the latest I/O header file (iodefine.h) outputted to target products by IDE "iodefine.h" uses the I/O header file which CS+ or e² studio outputs for target products.

The folder to which an I/O header file (iodefine.h) is outputted by IDE:

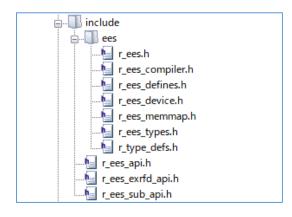
- CS+: [Project name] folder
- e<sup>2</sup> studio: [Project name]/generate folder
- Exclusion of the file automatically added by the function of IDE.
   There are files added automatically in the created project. The same file as these exists also in the "sample" folder of EES RL78 Type 01. Therefore, using the function of IDE, select those files from tree and excludes from a project.
  - CS+ : Click the right mouse button for the file of tree. And exclude target file using "Remove from Project" function. Targets are "hdwinit.asm, and main.c" in [project name] folder.
  - e<sup>2</sup> studio : Click the right mouse button for the file of tree. And on the [Settings] screen displayed by the "Properties", put a check mark to [Exclude resource from build] and exclude a target file (target folder). (Exclusion of a folder is also possible)

Target files are "hdwinit.asm" in a [Project name]/generate folder and a "[Project name] .c (EESRL78T01\_PJ01.c)" in a [Project name]/src folder.

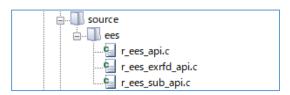
# (1) Registration the EES RL78 Type 01 target folders and target files.

The folders ("include", "source", "userown", "sample") and source program file which are included in EES RL78 Type 01 to register are shown below.

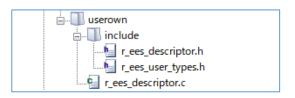
in the "include" folder



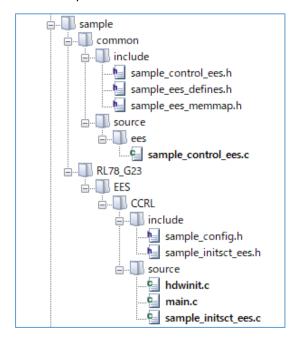
in the "source" folder



in the "userown" folder



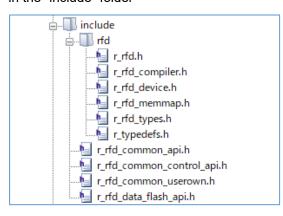
in the "sample" folder



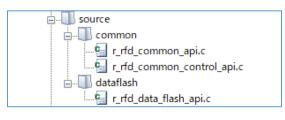
# (2) Registration the RFD RL78 Type 01 target folders and target files.

The folders ("include", "source", "userown") and source program file which are included in RFD RL78 Type 01 to register are shown below.

in the "include" folder



in the "source" folder



in the "userown" folder



#### 7.1.3 Build Tool Settings

Set IDE setting necessary in order to build EES RL78 Type 01 using a CC-RL compiler.

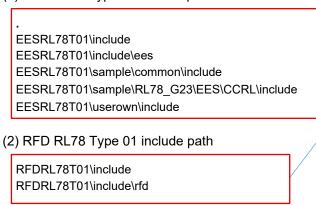
CS+: Click the right mouse button for the "CC-RL(Build tool)" in a tree, and select "Property". And set each setting of the build tool in the displayed window.

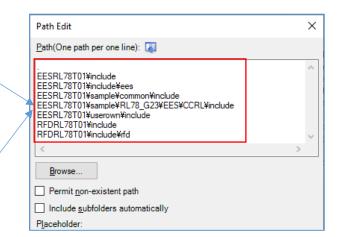
e² studio : Click the right mouse button for the project("EESRL78T01\_PJ01") in a tree, and select "Properties". And set each setting of the build tool in the displayed window.

#### 7.1.3.1 Include Path Settings

- Setting of the include path on CS+ inputs path in "Common Options" tab.
  - Input the Include directory path in the "Path Edit" window displayed by selection of [Frequently Used Options(for Compile)] [Additional include paths].

### (1) EES RL78 Type 01 include path





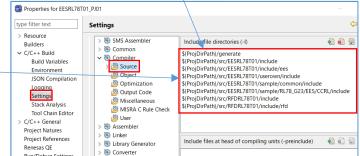
- Setting of the include path on e<sup>2</sup> studio inputs path in "Properties" window.
  - Input the Include directory path in the window displayed by selection of "C/C++ Build" [Settings] "Compiler" [Source].

#### (1) EES RL78 Type 01 include path



# (2) RFD RL78 Type 01 include path

\${ProjDirPath}\src\RFDRL78T01\include \${ProjDirPath}\src\RFDRL78T01\include\rfd



### 7.1.3.2 The Setting of User Definition Macro

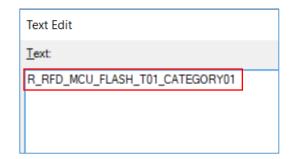
- On CS+, the macro for flash memory control system classification is defined in "Common Options" tab.
  - Define the following macro in the "Text Edit" window displayed by selection of [Frequently Used Options(for Compile)] [Macro definition]. Definition macro differs by each device to be used.

Macros defined when using RL78/G23 or RL78/G22:

R\_RFD\_MCU\_FLASH\_T01\_CATEGORY01

Macros defined when using RL78/G24:

R\_RFD\_MCU\_FLASH\_T01\_CATEGORY02



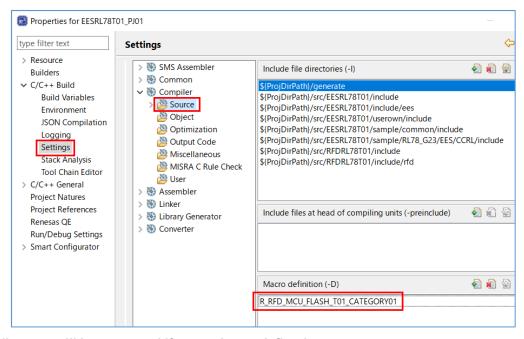
- On e<sup>2</sup> studio, the macro for flash memory control system classification is defined in "Properties" window.
  - Define the following macro in the "Macro Definition (-D)" displayed by selection of "C/C++ Build" [Settings] "Compiler" [Source]. Definition macro differs by each device to be used.

Macros defined when using RL78/G23, or RL78/G22:

R\_RFD\_MCU\_FLASH\_T01\_CATEGORY01

Macros defined when using RL78/G24:

### R\_RFD\_MCU\_FLASH\_T01\_CATEGORY02



Note: A compile error will be outputted if macro is not defined.

#### 7.1.3.3 Device Item Settings

- Setting of the device Items on CS+ inputs in the "Link Options" tab.
  - Setting the [Device] items

Select "Yes (-OCDBG)" in [Set enable/disable on-chip debug by link option].

Note: The example of a setting on condition of on-chip debugging execution.

Input the "85" into [Option byte values for OCD]. (Example of permission of operation for on-chip debugging)

Note: Be sure to confirm the contents of "User option byte" of the chapter of "Option Bytes", and "On-chip debug option byte" on the user's manual of a target device. And describe the set value used with user application.

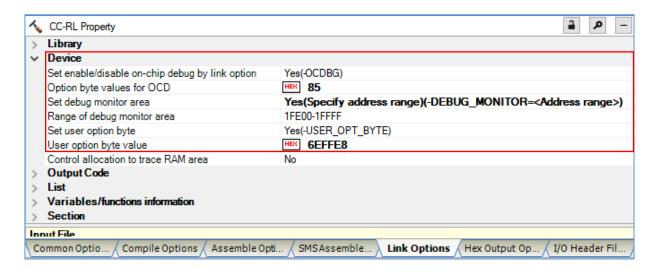
Select "Yes(Specify address range)(-OCDBG\_MONITOR=<Address range>)" in [Set debug monitor area]. Set "1FE00-1FFFF" to [Range of debug monitor area].

Note: The user needs to input the range of the area which the debugger uses with reference to description of the user's manual for a target device. And please refer to "Memory Spaces Allocated for Use by the Monitor Program for Debugging" in "Allocation of Memory Spaces to User Resources" on a user's manual.

Select "Yes(-USER\_OPT\_BYTE)" in [Set user option byte].

Set "6EFFE8" to [User option byte value]. (WDT stop, LVD reset mode, HS mode /32MHz [The example for RL78/G23])

Note: Be sure to confirm the contents of "User option byte" of the chapter of "Option Bytes", and "User option bytes" on the user's manual of a target device. And describe the set value used with user application.



- Setting of the device Items on e<sup>2</sup> studio inputs in the "Properties" window.
  - Select "C/C++ Build" [Settings] "Linker" [Device]. And set device items on the displayed screen.

Put in a check mark to [Secure memory area of OCD monitor(-debug\_monitor)] in the screen.

Note: The example of a setting on condition of on-chip debugging execution.

Set "1FE00-1FFFF" to [Memory area(-debug\_monitor=<start address>-<end address>)].

Note: The user needs to input the range of the area which the debugger uses with reference to description of the user's manual for a target device. And please refer to "Memory Spaces Allocated for Use by the Monitor Program for Debugging" in "Allocation of Memory Spaces to User Resources" on a user's manual.

Put a check mark to [Set user option byte(-user\_opt\_byte)].

Set "6EFFE8" to [User option byte value(-user\_opt\_byte=<value>)]. (WDT stop, LVD reset mode, HS mode /32MHz [The example for RL78/G23])

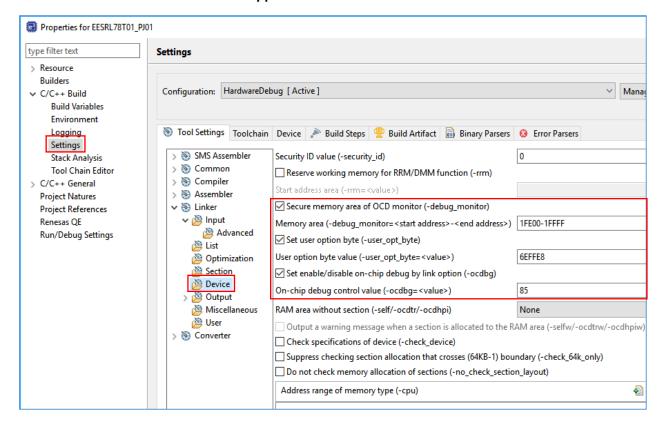
Note: Be sure to confirm the contents of "User option byte" of the chapter of "Option Bytes", and "User option bytes" on the user's manual of a target device. And describe the set value used with user application.

Put a check mark to [Set enable /disable on-chip debug by link option(-ocdbg)].

Note: The example of a setting on condition of on-chip debugging execution.

Input the "85" into [On-chip debug control value(-ocdbg=<value>)]. (Example of permission of operation for on-chip debugging)

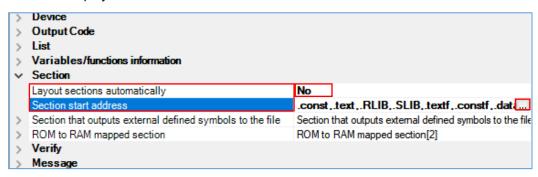
Note: Be sure to confirm the contents of "User option byte" of the chapter of "Option Bytes", and "On-chip debug option byte" on the user's manual of a target device. And describe the set value used with user application.



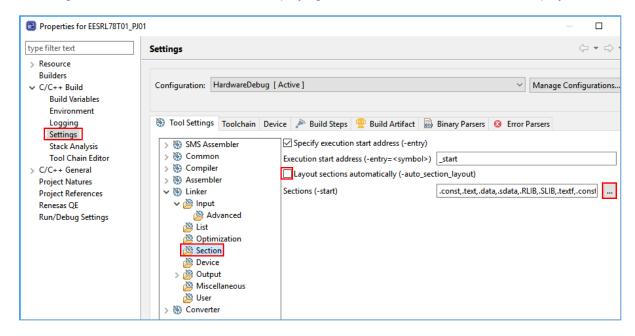
#### 7.1.3.4 Section Item Settings

- Setting of the section Items on CS+ inputs in the "Link Options" tab.
- Setting the [Section] items

Set "No" to [Layout sections automatically]. And sections come to be displayed on [Section start address]. Press the "...." button of the right-hand side which sections are displaying, and a "Section settings" screen is displayed.



- Setting of the section Items on e<sup>2</sup> studio inputs in the "Properties" window.
  - Select "C/C++ Build" [Settings] "Linker" [Section]. And set section items on the displayed screen. Remove a check mark to [Layout sections automatically(-auto\_section\_layout)]. Press the " ...." button of the right-hand side which sections are displaying, and a "Section viewer" screen is displayed.



 Section setting operation for CS+ and e<sup>2</sup> studio Set "0x03000" to a top address. Add the sections defined by "#pragma section" in EES RL78 Type 01 to the program area (code flash

Note: In this description, it is a premise to select a medium model as Memory Model of Compile Options. (It is the same as the "auto select" in R7F100GLG) Refer to the user's manual of CC-RL for the section name of each program when a "small model" is selected.

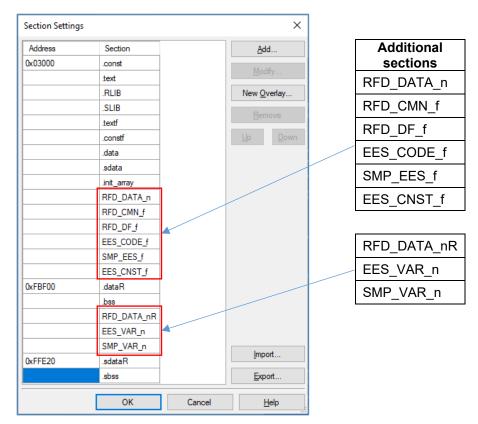
memory) and the RAM area. Refer to "Table 2-10 Sections Used in EES" for the details of each section.

- (1) The addition of the sections for EEPROM emulation
- The addition of the sections for EEPROM emulation on CS+

Add sections necessary for code flash memory reprogramming on a "Section Settings" screen. It also includes a section for the RFD RL78 Type 01.

Add to the program area : RFD\_DATA\_n, RFD\_CMN\_f, RFD\_DF\_f, EES\_CODE\_f, SMP\_EES\_f, EES\_CNST\_f

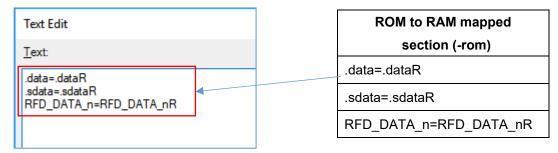
Add to the RAM area: RFD\_DATA\_nR, EES\_VAR\_n, SMP\_VAR\_n



Be sure to return [Layout sections automatically] to "Yes", after pressing the "OK" button.



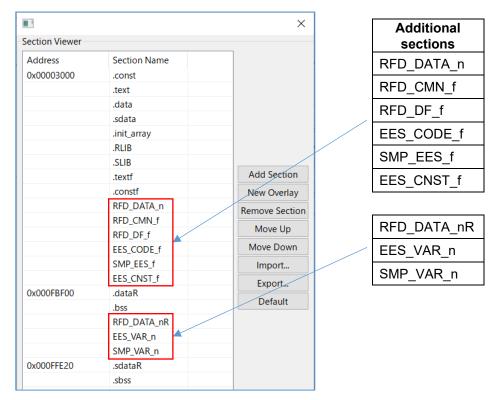
Press the right-hand side " \_\_\_\_ " button by [ROM to RAM mapped section], display the "Text Edit" screen, and add the section for copying to RAM from ROM.



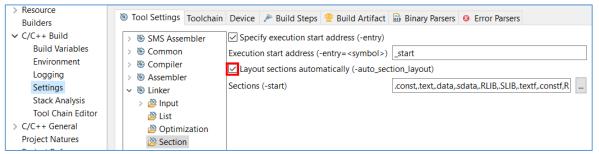
 The addition of the sections for EEPROM emulation on e<sup>2</sup> studio
 Add sections necessary for EEPROM emulation on a "Section Viewer". It also includes a section for the RFD RL78 Type 01.

Add to the program area : RFD\_DATA\_n, RFD\_CMN\_f, RFD\_DF\_f, EES\_CODE\_f, SMP\_EES\_f, EES\_CNST\_f

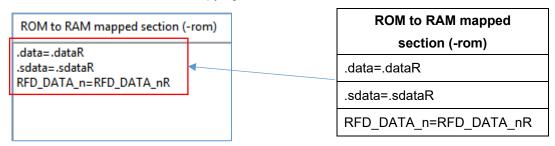
Add to the RAM area: RFD DATA nR, EES VAR n, SMP VAR n



Be sure to put a check mark to [Layout sections automatically (-auto\_section\_layout)], after pressing the "OK" button.



Select "C/C++ Build" [Settings] - "Linker" [Output], display the "ROM to RAM mapped section (-rom)" screen, and add the section for copying to RAM from ROM.



#### 7.1.4 Debug Tool Settings

This section describes the contents of connection setting on a target board necessary in order to execute onchip debugging. As a debugging tool, it is a premise that E2 Lite is selected. Refer to the user's manual for each IDE for the details of other debugging tool setting.

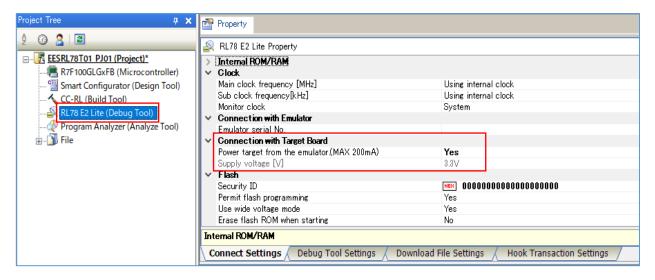
On CS+, right-click a mouse by "RL78 simulator (Debug Tool)" [initial setting] of a tree. And select the "RL78 E2 Lite" by "Using Debug Tool" displayed there. And a "RL78 E2 Lite Property" screen is displayed, and select each tab, and perform debugging tool setting.

On e<sup>2</sup> studio, right-click a mouse in the target project of a tree. Selection of [Debug As] - [Debug Configurations...] will display the "Debug Configurations" screen. On the tree of a screen, select the target project ("EESRL78T01\_PJ01 HardwareDebug") of [Renesas GDB Hardware Debugging]. And the displayed "Debugger" tab performs debugging tool setting.

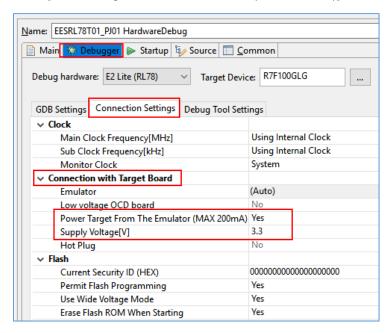
Note: The power is already supplied to the target board, or when power supply capacity is insufficient, the emulator including E2 Lite may be unable to supply power to a target board. Be sure to refer to "the user's manual and Additional Document for User's Manual (Notes on Connection of RL78)" for the emulator for target devices, and use an emulator.

### 7.1.4.1 Setting of Connection with Target Board

- On CS+, set up the connection with target board(via E2 Lite) with "Connect Settings" tab.
  - [Connection with Target Board] item In order to let power supply(Supply voltage : 3.3V) from E2 Lite to a target board, it is necessary to set "Yes" to [Power target from the emulator (MAX 200mA)].



- On e<sup>2</sup> studio, set up the connection with target board(via E2 Lite) with "Connection Settings" tab.
  - [Connection with Target Board] item In order to let power supply(Supply Voltage : 3.3V) from E2 Lite to a target board, it is necessary to set "Yes" to [Power Target From The Emulator (MAX 200mA)].



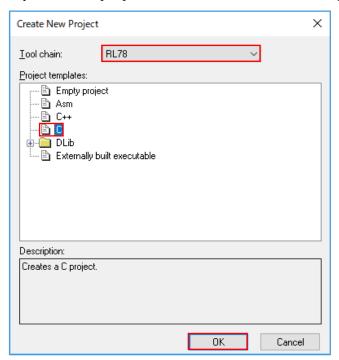
# 7.2 Creating a Project in the Case of Using IAR Compiler

IAR Embedded Workbench can be used for an IAR compiler as an IDE. EES RL78 Type 01 and RFD RL78 Type 01 are registered and built in the project created by the IDE. An example of creating a sample project in case each IDE is used is shown. Because to understand a IAR compiler and each IDE, it is necessary to refer to the user's manual of each tool product.

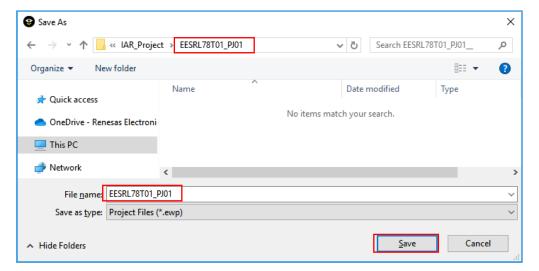
IAR Systems, IAR Embedded Workbench, C-SPY, IAR, and the logotype of IAR Systems are trademarks or registered trademarks owned by IAR Systems AB.

#### 7.2.1 **Example of Creating a Sample Project**

- (1) An example of creating a sample project which used IAR Embedded Workbench (IDE)
- The IAR Embedded Workbench starts and from the [Project] menu, select [Create New Project...], the "Create Project" window will open.
  - Select the "C" as [project template].
  - When you click the [OK] button, the "Save As" window will open.

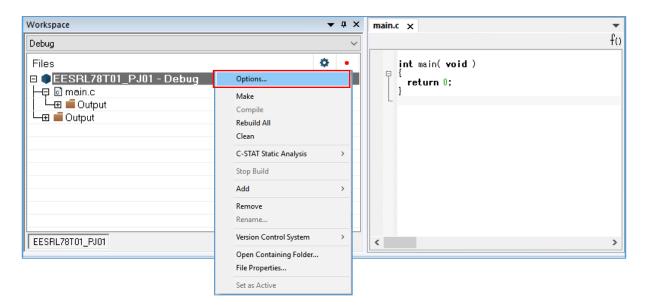


- Create "EESRL78T01\_PJ01" folder temporarily, and move into a folder.
- The Project File name is temporarily set to "EESRL78T01\_PJ01".

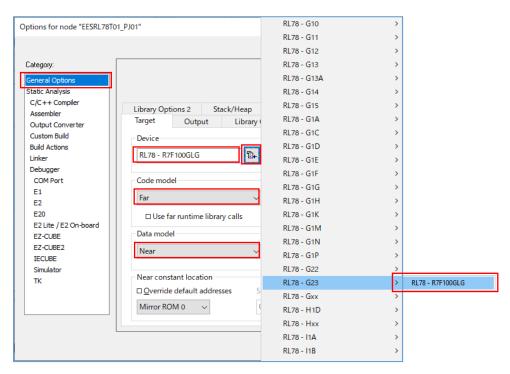


#### (2) Selection of a target device

 On IAR Embedded Workbench, I click the right mouse button of the project ("EESRL78T01\_PJ01 – Debug") in a tree. When an "Options" is selected, the "Options for node [Project name]" window is displayed.



- Input setting in the [General Options] [Target] tab of "Options for node [Project name]" window.
- Press " button of [Device]. And Select "RL78 G23" "RL78 R7F100GLG". Select "Far" as [Code model] and select "Near" as [Data model].

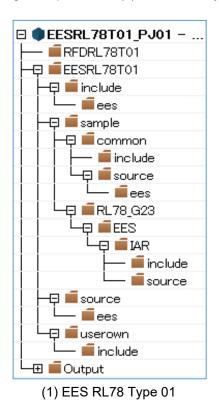


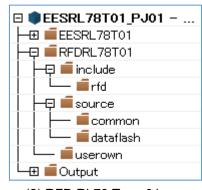
#### 7.2.2 Example of Registration of Target Folders and Target Files

This describes an example of file registration required to execute EEPROM emulation.

Instead of registering a folder by IAR Embedded Workbench, select [Add Group] of the [Project] menu, and add a group. The example into which I add the group of the same structure as the folder for EES RL78 Type 01 and RFD RL78 Type 01, and files are registered is shown.

The following example shows (1) EES RL78 Type 01 and (2) RFD RL78 Type 01 groups added:





(2) RFD RL78 Type 01

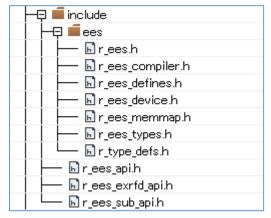
- Exclusion of the file automatically added by the function of IDE.

  There are files added automatically in the created project. The same file as these exists also in the "sample" folder of EES RL78 Type 01. Therefore, using the function of IDE, Select those files from tree and excludes from a project.
  - IAR Embedded Workbench: Clicks the right mouse button for the file of tree. And exclude the target "main.c" file by "Remove" function.

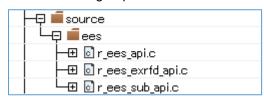
#### (1) Registration of the EES RL78 Type 01 files.

The groups ("include", "source", "userown", "sample") and source program file which are included in EES RL78 Type 01 to register are shown below.

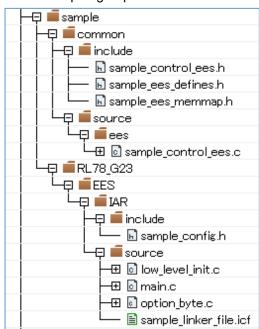
# in the "include" group



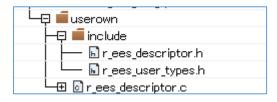
#### in the "source" group



#### in the "sample" group



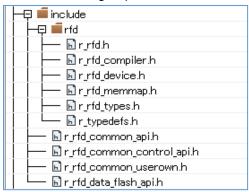
#### in the "userown" group



# (2) Registration of the RFD RL78 Type 01 files

The groups ("include", "source", "userown") and source program file which are included in RFD RL78 Type 01 to register are shown below.

#### in the "include" group



in the "source" group



in the "userown" group



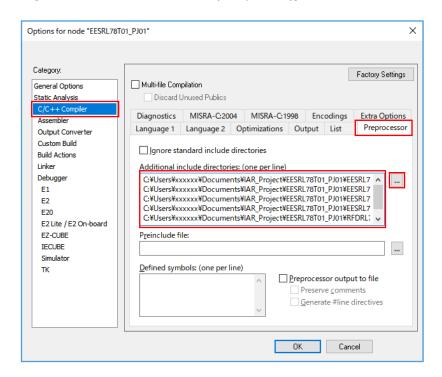
#### 7.2.3 Integrated Development Environment(IDE) Settings

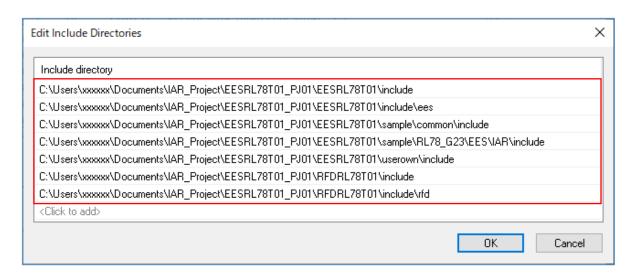
Set IDE setting necessary in order to build EEPROM emulation using an IAR compiler.

IAR Embedded Workbench: Click the right mouse button for the project("EESRL78T01\_PJ01") in a tree, and select "Options". And set each setting of the "Category" in the displayed window.

#### 7.2.3.1 Include Path Settings

- Setting of the include path on IAR Embedded Workbench selects "C/C++ Compiler" of "Category", and inputs path in "Preprocessor" tab.
  - Input the Include directory path in the "Edit Include Directories" window displayed by selection of [Additional include directories: (one per line)].





- The example of directory path setting.

It is the example when the project director is placed in "C:\Users\xxxxx\Documents\IAR Project\".

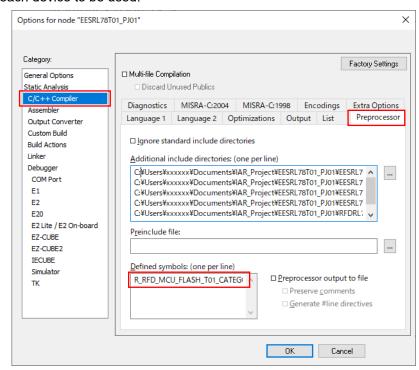
- (1) EES RL78 Type 01 include directories
  - C:\Users\xxxxxx\Documents\IAR\_Project\EESRL78T01\_PJ01\EESRL78T01\include
  - C:\Users\xxxxxx\Documents\IAR Project\EESRL78T01 PJ01\EESRL78T01\include\ees
  - C:\Users\xxxxxx\Documents\IAR\_Project\EESRL78T01\_PJ01\EESRL78T01\sample\common\include
  - C:\Users\xxxxx\Documents\IAR\_Project\EESRL78T01\_PJ01\EESRL78T01\sample\RL78\_G23\EES\IAR\include
  - C:\Users\xxxxxx\Documents\IAR\_Project\EESRL78T01\_PJ01\EESRL78T01\userown\include
- (2) RFD RL78 Type 01 include directories
  - C:\Users\xxxxxx\Documents\IAR\_Project\EESRL78T01\_PJ01\RFDRL78T01\include
  - C:\Users\xxxxxx\Documents\IAR Project\EESRL78T01 PJ01\RFDRL78T01\include\rfd

#### Note: About the path setting of include directories.

When the project is copied in the case appointed by the absolute path, the setup is needed again. It is possible to appoint a relative path (\$PROJ\_DIR\$) so that it can be used, even if it copies the project. Refer to each reference manual of IAR Embedded Workbench about how to appoint the relative path.

#### 7.2.3.2 The Setting of User Definition Macro

- On IAR Embedded Workbench, the macro for flash memory control system classification is defined in "Preprocessor" tab.
  - Define the following macro in the column of [Defined symbols: (one per line)]. Definition macro differs by each device to be used.



Macros defined when using RL78/G23 or RL78/G22:

### R\_RFD\_MCU\_FLASH\_T01\_CATEGORY01

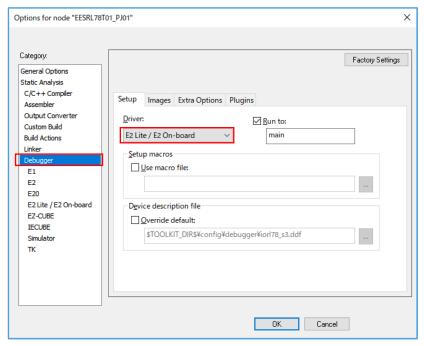
Macros defined when using RL78/G24:

R\_RFD\_MCU\_FLASH\_T01\_CATEGORY02

Note: A compile error will be outputted if macro is not defined.

### 7.2.3.3 Debugger Settings

• Select "E2 Lite/E2 On-Board" from [Driver] of [Debugger] – [Setup] tab on the assumption that on-chip debugging is implemented.

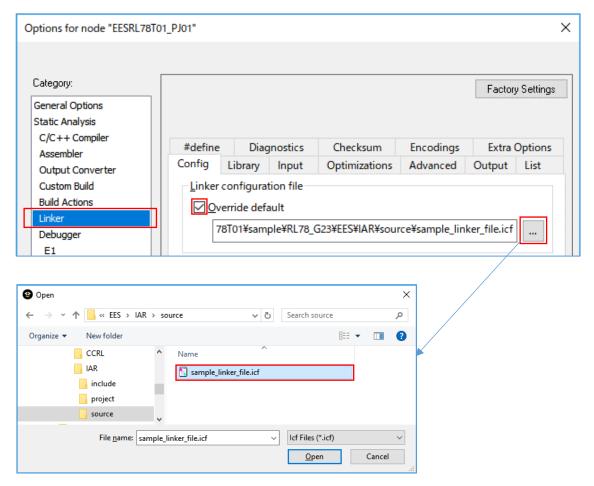


Note: Refer to each reference manual of IAR Embedded Workbench about the other items to be set.

#### 7.2.4 Linker Configuration File(.icf) Settings

On IAR Embedded Workbench, Linker configuration file (\*. icf) describes link setting executed by building. Select "Options" by the click right mouse button of project with tree. Select [Linker] by "Category" in the displayed window, And put a check mark to "Override default" of the [Config] tab. Select Linker configuration file (\*. icf) in the "Open" window of " button. Select the "sample\_linker\_file.icf" file prepared for EES RL78 Type 01.

- sample\_linker\_file.icf (\sample\RL78\_G23\EES\IAR\source\)



Note: Refer to each reference manual of IAR Embedded Workbench about the descriptive content of Linker configuration file, and the details of the description method.

### 7.2.4.1 Section Settings

The outline of the section added to Linker configuration file (\*. icf) currently prepared by EES RL78 Type 01 explained.

Note: Refer to each reference manual of IAR Embedded Workbench about the section setting method and the detail of functions for Linker configuration file.

- (1) The addition of the sections for EES RL78 Type 01.
  Add the initial value of each section of EES\_CODE, SMP\_EES, and EES\_CNST to ROM area (ROM\_far).
  - The additional section of the ROM\_far area:
     EES\_CODE, SMP\_EES, EES\_CNST
  - The additional section of RAM\_near area: EES\_VAR, SMP\_VAR
- (2) The addition of the sections for RFD RL78 Type 01.
  Add the initial value of each section of RFD\_DATA, RFD\_CMN, and RFD\_DF to ROM area (ROM\_far). It is necessary to copy RFD\_DATA to the section of RAM area (RAM\_near).
  - The additional section of the ROM\_far area (The program and The data for copying to RAM area to be placed in ROM area):
     RFD\_DATA\_init, RFD\_CMN, RFD\_DF
  - The additional section of RAM\_near area (Data copied from ROM area):
     RFD\_DATA

#### 7.2.4.2 Option Bytes Settings

The Option bytes definition of RL78 is described in Linker configuration file (\*. icf) of IAR Embedded Workbench attachment or the "sample\_linker\_file.icf" file prepared for EES RL78 Type 01. The Option Bytes value for EES RL78 Type 01 is described by the "option\_byte.c" file.

Note: Refer to each reference manual of IAR Embedded Workbench about the option bytes setting method for Linker configuration file.

The example of an Option Bytes definition of Linker configuration file for EES RL78 Type 01 (\*. icf).

```
define block OPT_BYTE with size = 4 { R_OPT_BYTE, ro section .option_byte, ro section OPTBYTE };

place at address mem:0x000C0 { block OPT_BYTE };
```

The example of description of the Option Bytes value in an "option\_byte.c" file.

```
pragma location = "OPTBYTE"
   oot const_unsigned char option_bytes[4] = {
   0×6E,
            /* 01101110 */
            /*
                         */
            /*
                           Watchdog timer
            /#
                           operation stopped
            /*
                            in HALT/STOP mode
                                                */
            /*
                           Watchdog timer
            /*
                           overflow time is
                           2^17 / fIL = 3478.26 ms
            /*
            /*
                                                #/
            /*
                           Watchdog timer
            /*
                            operation disabled */
            /*
                            100% window open
                           period
            /*
                           Interval interrupt */
            /*
                            is not used
   0xFF,
            /* 11111111
                         */
                           LVD reset mode */
            /* HS mode 32 MHz */
   0xE8.
   0 \times 85
            /* OCD: enables on-chip debugging function */
```

- Description of user option byte value:

```
The value of User option byte (000C0H-000C2H) in "option_byte.c" file is "0x6EFFE8". (WDT stop, LVD reset mode, HS mode /32MHz [The example for RL78/G23])
```

The value of on-chip debug option byte(000C3H/040C3H) in "option\_byte.c" file is "0x85". (The example of enable on-chip debug operation)

Note: Be sure to confirm the contents of "User option byte" of the chapter of "Option Bytes", and "On-chip debug option byte" by the user's manual of a target device. And describe the set value used with user application.

#### 7.2.5 On-chip Debug Settings

After executing building of a target project, connect E2 Lite, select [Download and Debug] from [Project] menu, and start debugging.

#### 7.2.5.1 Example of How to Deal with Connection Errors

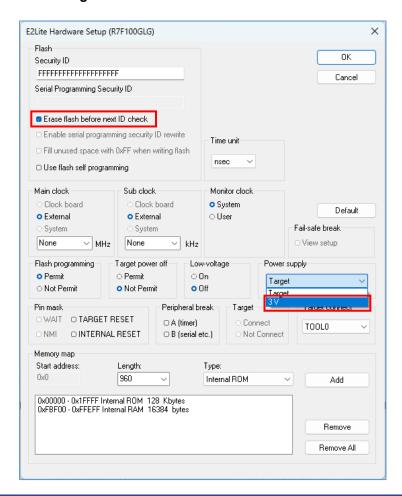
Explain the common examples of how to deal with an error which happened by connection in on-chip run debug. This is the case when an ID code mismatch or power failure occurs.

Note: In cases where a target cannot be connected by other causes, please confirm each reference manual from [Help] of IAR Embedded Workbench.

When selecting [Download and Debug] and starting debugging, an "E2 Lite hardware setting" screen may be displayed. The cause may be ID code mismatch or power setting error.

- In the case of the ID code mismatch:
  - "Cannot verify the ID code." etc. may be displayed as a message. In this case, put a check mark to "Erase flash before next ID check" in an "E2 Lite HardwareSetup" window, and continue. And the flash memory is erased and debugger may be connected.
- In the case of power setting error:
   Initial setting of "Power supply" is "Target". When supplying power supply from E2 Lite, select "3V" by the pull down menu for "Power supply".

Caution: Be sure not to set "3V" (supply power from E2 Lite), when the power is supplied to the target.



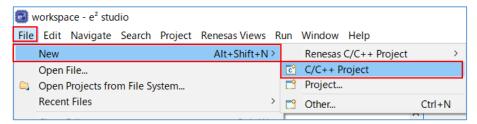
#### 7.3 Creating a Project in the Case of Using LLVM Compiler

e<sup>2</sup> studio can be used for a LLVM compiler as an IDE. EES RL78 Type 01 and RFD RL78 Type 01 are registered and built in the project created by the IDE. An example of creating a sample project in case e2 studio is used is shown. Because to understand a LLVM compiler and e2 studio, it is necessary to refer to the user's manual of each tool product.

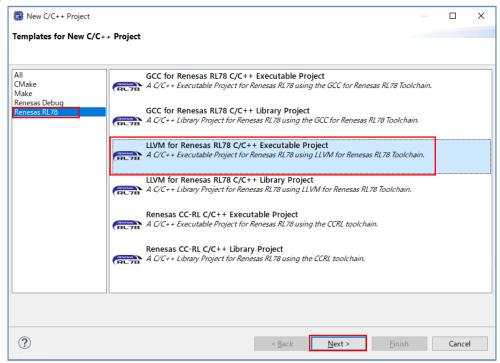
#### **Example of Creating a Sample Project** 7.3.1

An example of creating a sample project which used e<sup>2</sup> studio (IDE).

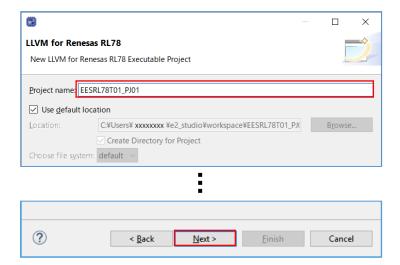
• The e<sup>2</sup> studio starts and from the [File] menu, select [New] – [C/C++ Project], the "Templates for New C/C++ Project" window will open.



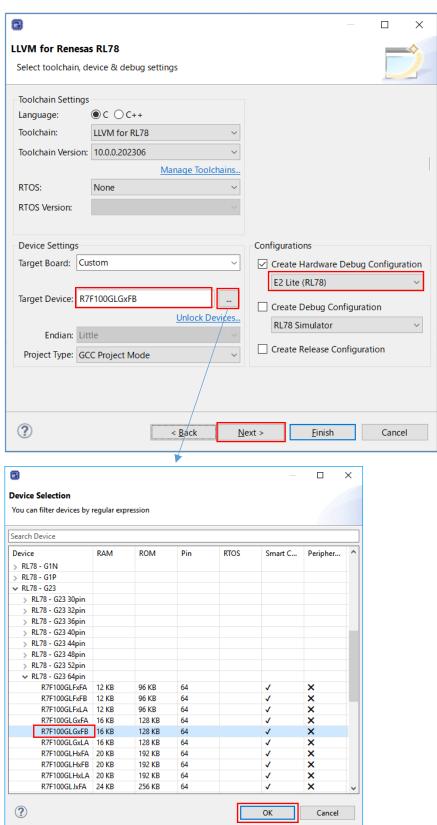
• Select [LLVM for Renesas RL78 C/C++ Executable Project] displayed after selection in [Renesas RL78], and press "Next" button.



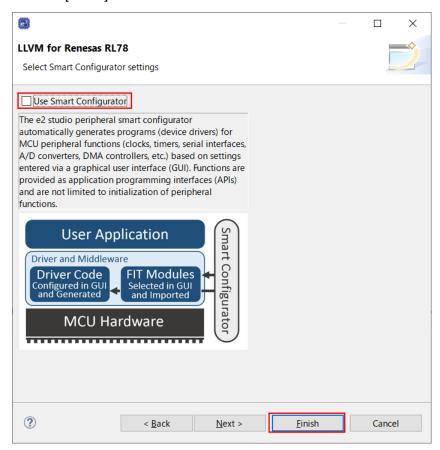
• Input "Project name" on "New LLVM for Renesas RL78 Executable Project" window, and press "Next" button. [Project name] is temporarily set to "EESRL78T01\_PJ01".



- Select the [Target Device] of [Device Settings], and select "RL78 G23" "RL78 G23 64pin" "R7F100GLGxFB".
- It is a premise that E2 Lite is selected as a debugging tool and on-chip debugging is executed. Put a check mark to "Create Hardware Debug Configuration" by [Configurations]. And select "E2 Lite (RL78)".
- · Press "Next" button.



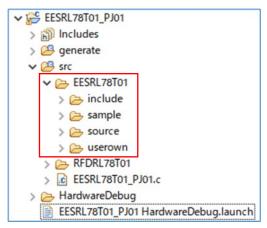
- · Uncheck the "Use Smart Configurator".
- Press the [Finish] button.



#### 7.3.2 **Example of Registration of Target Folders and Target Files**

Using EES RL78 Type 01, when execute EEPROM emulation the example which registers necessary files is shown. Each folder of a "EESRL78T01" source program file is "include", "source", "userown", and "sample".

As other registration methods, after all the folders of "include", "source", "userown", and "sample" are registered, unnecessary files and folders can be removed using the function of [Resource Configuration] – [Exclude from Build].



The registration tree screen of EES RL78 Type01(e<sup>2</sup> studio)

Note: Register the "generate" folder output by e<sup>2</sup> studio as necessary.

• Registration of the vector table file outputted to target products by e<sup>2</sup> studio

"vects.c" file is that contain vector tables that e2 studio outputs for the target product. Since it depends on the product, please replace "vects.c" included in EES RL78 Type 01.

When these are replaced, change the option byte values in the "vects.c" file. Refer to "7.3.4 Option Bytes Settings" for details on setting option byte values.

The folder to which "vects.c" file is outputted by e<sup>2</sup> studio:

- [Project name]/generate

The folder with which a user replaces the "vects.c" file:

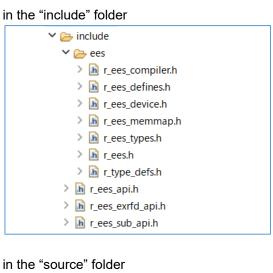
- \[Project name]\src\EESRL78T01\sample\RL78 G23\EES\LLVM\source

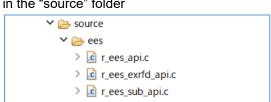
- Exclusion of the file automatically added by the function of e² studio.

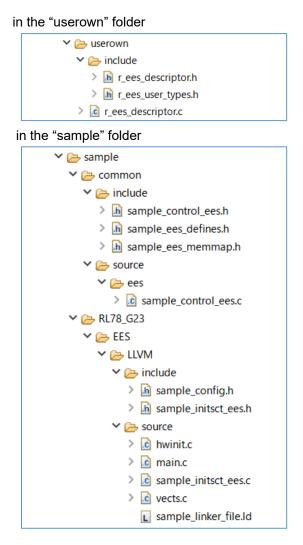
  There are files added automatically in the created project. The same files as these exists also in the "sample" folder of EES RL78 Type 01. Therefore, using the function of e² studio, select those files from tree and excludes from a project.
  - e<sup>2</sup> studio: Clicks the right mouse button for the file of tree. And on the [Settings] screen displayed by the "Properties", put a check mark to [Exclude resource from build] and exclude a target file (target folder). (Exclusion of a folder is also possible)
  - Target files are "hwinit.c", and "linker\_script.ld" in the [project name]/generate folder, and [project name].c ("EESRL78T01\_PJ01.c") in the [project name]/src folder.

(1) Registration the EES RL78 Type 01 target folders and target files.

The folders ("include", "source", "userown", "sample") and source program file which are included in EES RL78 Type 01 to register are shown below.



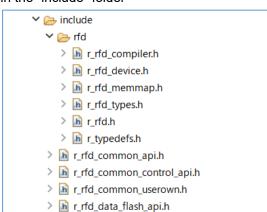




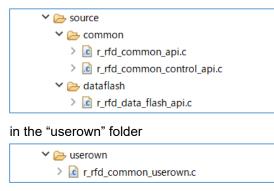
(2) Registration the RFD RL78 Type 01 target folders and target files.

The folders ("include", "source", "userown") and source program file which are included in RFD RL78 Type 01 to register are shown below.





in the "source" folder



#### 7.3.3 Build Tool Settings

Set e<sup>2</sup> studio setting necessary in order to build EES RL78 Type 01 using a LLVM compiler. Click the right mouse button for the project ("EESRL78T01\_PJ01") in a tree, and select "Properties". And set each setting of the build tool in the displayed window.

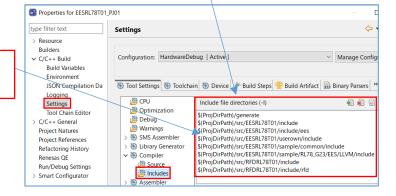
#### 7.3.3.1 Include Path Settings

- Setting of the include path on e<sup>2</sup> studio inputs path in "Properties" window.
  - Input the include directory path in the window displayed by selection of "C/C++ Build" [Settings] "Compiler" [Includes].
- (1) EES RL78 Type 01 include path

```
${ProjDirPath}\generate
${ProjDirPath}\src\EESRL78T01\include
${ProjDirPath}\src\EESRL78T01\include\ees
${ProjDirPath}\src\EESRL78T01\sample\common\include
${ProjDirPath}\src\EESRL78T01\sample\RL78_G23\EES\LLVM\include
${ProjDirPath}\src\EESRL78T01\userown\include
```

#### (2) RFD RL78 Type 01 include path

\${ProjDirPath}\src\RFDRL78T01\include \${ProjDirPath}\src\RFDRL78T01\include\rfd



#### 7.3.3.2 The Setting of User Definition Macro

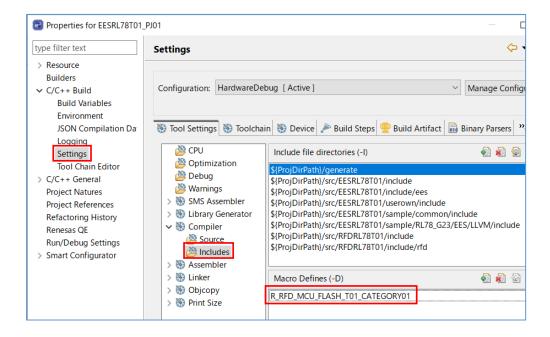
- On e<sup>2</sup> studio, the macro for flash memory control system classification is defined in "Properties" window.
  - Define the following macro in the "Macro Defines (-D)" displayed by selection of "C/C++ Build" [Settings] "Compiler" [Includes]. Definition macro differs by each device to be used.

Macros defined when using RL78/G23, or RL78/G22:

R\_RFD\_MCU\_FLASH\_T01\_CATEGORY01

Macros defined when using RL78/G24:

R\_RFD\_MCU\_FLASH\_T01\_CATEGORY02



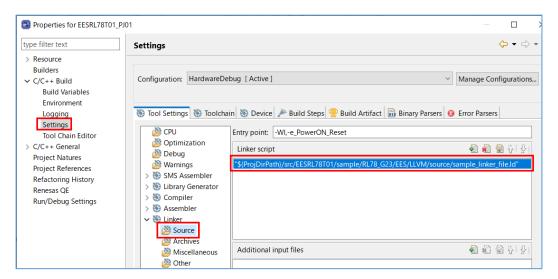
Note: A compile error will be outputted if macro is not defined.

#### 7.3.3.3 Linker Script File (.ld) Settings

On LLVM, linker script file (\*.ld) describes link setting executed by building. Click the right mouse button for the project ("EESRL78T01\_PJ01") in a tree, and select "Properties". And set each setting of the build tool in the displayed window. Input the include linker script file path in the window displayed by selection of "C/C++ Build" [Settings] – "Linker" [Source].

Input the path to the "sample\_linker\_file.ld" file contained in the EES RL78 Type 01 sample program. The linker script file (\*.ld) for EES RL78 Type 01 is as follows:

- sample\_linker\_file.ld (\sample\RL78\_G23\EES\LLVM\source\)



Note: Refer to each reference manual of LLVM about the descriptive content of linker script file, and the details of the description method.

#### 7.3.3.4 Section Settings

The setting outline of the section item described to linker script file (\*.ld) of EES RL78 Type 01.

- (1) The sections for EES RL78 Type 01.
  - The section of code to be placed in the ROM area:

```
EES_CODE, SMP_EES (EES_ROM_CODE)
```

- The section of const data to be placed in the ROM area:

```
EES CNST
```

- The section of data to be placed in the RAM area:

```
EES_VAR, SMP_VAR
```

- (2) The sections for RFD RL78 Type 01.
  - The section of code to be placed in the ROM area:

```
RFD_CMN, RFD_DF (RFD_ROM_CODE)
```

- Section of data that is copied from the ROM area to the RAM area:

```
RFD_DATA
```

Note: When using the LLVM compiler, the compiler may automatically add subsections with different names when common processing is detected within the same section. Therefore, the following sections are added to the description in the sample\_linker\_file.ld file.

```
EES_XXXX.* and SMP_XXXX.* ("XXXX" = "CODE", "EES", "VAR" or "CNST")
```

Examples of subsections that could be added: EES\_CODE.outlined-functions (etc.) Refer to each reference manual of LLVM about the section setting method and the detail of functions for linker script file.

#### 7.3.4 Option Bytes Settings

"Option Bytes" settings when using the LLVM compiler are set in the "vects.c" file.

Target file name: vects.c

- \[Project name]\src\EESRL78T01\sample\RL78\_G23\EES\LLVM\source\vects.c

Description of user option byte value:

In the "vects.c" file provided in the sample program, the option byte value and user option byte value are set in "Option\_Bytes" as follows.

[The example for RL78/G23]

"0x6e, 0xff, 0xe8, 0x85" (WDT stop, LVD reset mode, HS mode/32MHz, Enable on-chip debug operation)

Note: Be sure to confirm the contents of "User option byte" of the chapter of "Option Bytes", and "On-chip debug option byte" by the user's manual of a target device. And describe the set value used with user application.

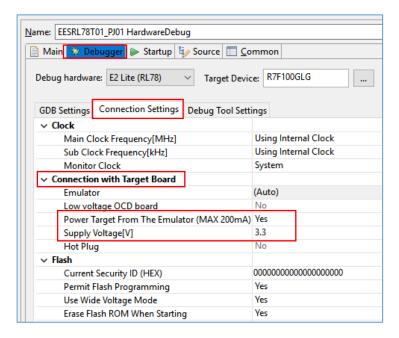
#### 7.3.5 **Debugger Settings**

This section describes the contents of connection setting on a target board necessary in order to execute onchip debugging. As a debugging tool, it is a premise that E2 Lite is selected. Refer to the user's manual for IDE for the details of other debugging tool setting.

On e<sup>2</sup> studio, right-click a mouse in the target project of a tree. Selection of [Debug As] - [Debug Configurations...] will display the "Debug Configurations" screen. On the tree of a screen, select the target project ("EESRL78T01 PJ01 HardwareDebug") of [Renesas GDB Hardware Debugging]. And the displayed "Debugger" tab performs debugging tool setting.

Note: The power is already supplied to the target board, or when power supply capacity is insufficient, the emulator including E2 Lite may be unable to supply power to a target board. Be sure to refer to "the user's manual and Additional Document for User's Manual (Notes on Connection of RL78)" for the emulator for target devices, and use an emulator.

- On e<sup>2</sup> studio, set up the connection with target board(via E2 Lite) with "Connection Settings" tab.
  - [Connection with Target Board] item In order to let power supply(Supply Voltage: 3.3V) from E2 Lite to a target board, it is necessary to set "Yes" to [Power Target From The Emulator (MAX 200mA)].



## 7.4 Configurations Modify Procedure for Changing Device

When using devices other than those targeted by the EES RL78 Type 01 sample program, ROM, RAM, and data flash memory sizes are different, so section addresses and some of the sample programs must be modified. This section describes the procedure to modify and where to modify.

Target device in a "sample" folder:

- "RL78\_G23" folder [CATEGORY01]. Target device for the prepared file: RL78/G23 (R7F100GLG ROM: 128 Kbytes, RAM: 16 Kbytes, DF: 8 Kbytes)
- "RL78\_G24" folder [CATEGORY02]. Target device for the prepared file : RL78/G24 (R7F101GLG ROM: 128 Kbytes, RAM: 12 Kbytes, DF: 4 Kbytes)

To modify the setting values, refer to "Renesas Flash Driver and EEPROM Emulation Software for RL78 Target MCU List" (here after "Target MCU List") and change into the set value which suited the device used.

If the folder name of the target device group exists in the "sample" folder, use that folder. If the folder name of the target device group does not exist, the folder of the device with the same "CATEGORY" number described in the target MCU list is used. A "RL78\_G22" sample folder does not exist in the case which uses RL78/G22. Therefore, use "RL78\_G23" folder for RL78/G23 of the same "CATEGORY01".

#### - The extract of a target MCU list

Target MCUs

	Co	de Flash memory		User RAM	Data F	
MCU Group	Size (bytes)	Start/End Address	Size (bytes)	Start/End Address	Size (bytes)	S
RL78/G22	32K	0x00000 - 0x07FFF	4K	0xFEF00 - 0xFFEFF	2K	0x
RL / 6/03/2	64K	0x00000 - 0x0FFFF	4K	0xFEF00 - 0xFFEFF	A Address   (bytes)   S	0x
	96K	0x00000 - 0x17FFF	12K	0xFCF00 - 0xFFEFF	8K	0x
	128K	0x00000 - 0x1FFFF	16K	0xFBF00 - 0xFFEFF	8K	0x
	192K	0x00000 - 0x2FFFF	20K	0xFAF00 - 0xFFEFF	8K	0x
RI 78/G23	256K	0x00000 - 0x3FFFF	24K	0xF9F00 - 0xFFEFF	8K	0x
	384K	0x00000 - 0x5FFFF	32K	0xF7F00 - 0xFFEFF	8K	0x
	512K 0x00000 - 0x7FF	0x00000 - 0x7FFFF	48K	0xF3F00 - 0xFFEFF	8K	0x
	768K	0x00000 - 0xBFFFF	48K	0xF3F00 - 0xFFEFF	8K	0x
RL78/G24	64K	0x00000 - 0x0FFFF	12K	0xFCF00 - 0xFFEFF	4K	0x
KL/8/G24	128K	0x00000 - 0x1FFFF	12K	0xFCF00 - 0xFFEFF	4K	0x



	[R-7]	[R-8]					
М	END_BLOCK	CATEGORY	Target MCU name				
	16	01	R7F102GxC(x = 4, 6, 7, 8, A, B, C, E, F, G)				
	32	01	R7F102GxE(x = 4, 6, 7, 8, A, B, C, E, F, G)				
	48	01	R7F100GxF(x = A, B, C, E, F, G, J, L)				
	64	01	R7F100GxG(x = A, B, C, E, F, G, J, L, M, P)				
	96	01	R7F100GxH(x = A, B, C, E, F, G, J, L, M, P)				
	128	01	R7F100GxJ(x = A, B, C, E, F, G, J, L, M, P, S)				
	192	01	R7F100GxK(x = F, G, J, L, M, P, S)				
	256	01	R7F100GxL(x = F, G, J, L, M, P, S)				
	384	01	R7F100GxN(x = F, G, J, L, M, P, S)				
	32	02	R7F101GxE(x = 6, 7, 8, A, B, E, F, G, J, L)				
	64	02	R7F101GxG(x = 6, 7, 8, A, B, E, F, G, J, L)				

An example of referencing the Target MCU List and an example of where to modify is shown below.

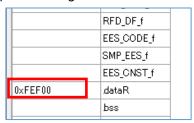
- Example of reference of the Target MCU List

For example, when modifying the setting value indicated by [R-1] (the start address of RAM) as shown in the following figure. Here, refer to the setting value of the start address [R-1] (RAM Start Address) of RAM shown in the Target MCU List and set the value of RL78/G22(R7F102GGE).

Example of where to modify the start address of RAM: RL78/G23(R7F100GxG RAM: 16 Kbytes).



Example of setting the start address value of RAM when using RL78/G22 (R7F102GxE RAM: 4 Kbytes).



The value to be set in [R-1] refers to the Target MCU List and sets the start address value of RAM of the target device.

In the column "Target MCU name" of the Target MCU List, search for the row for R7F102GxE. Next, find the cell in the [R-1] column that intersects the row of R7F102GxE.

- Example of displaying the "Target MCU List"

	Code Flash memory		User RAM		Data Flash memory		[R-1]	[R-2]	[R-3]	[R-4]	[R-5]	[R-6]	[R-7]	[R-8]	
MCU Group	Size (bytes)	Start/End Address	Size (bytes)	Start/End Address	Size (bytes)	Start/End Address	RAM Start Address	ROM End Address 1	ROM End Address 2	Data Flash End Address	OCD_ROM	Trace_RAM	END_BLOCK	CATEGORY	Target MCU name
RL78/G22	32K	0x00000 - 0x07FFF	4K	0xFEF00 - 0xFFEFF	2K	0xF1000 - 0xF17FF	0xFEF00	0x07FFF		0xF17FF	0x07E00	0xFF300	16	01	R7F102GxC(x = 4, 6, 7, 8, A, B, C, E, F, G)
RE76/022	64K	0x00000 - 0x0FFFF	4K	0xFEF00 - 0xFFEFF	2K	0xF1000 - 0xF17FF	0xFEF00	0x0FFFF	-	0xF17FF	0x0FE00	0xFF300	32	01	R7F102GxE(x = 4, 6, 7, 8, A, B, C, E, F, G)

Since "0xFEF00" applies, the setting value of [R-1] is RL78/G22 (R7F102GxE) value "0xFEF00".

	[R-1]	[R-2]	[R-3]	[R-4]	[R-5]	[R-6]	[R-7]	[R-8]	
	RAM Start Address	ROM End Address 1	ROM End Address 2	Data Flash End Address	OCD_ROM	Trace_RAM	END_BLOCK	CATEGORY	Target MCU name
Т	0xFFF00	0x07FFF	_	0xF17FF	0x07F00	0xFF300	16	01	R7F102GxC(x = 4, 6, 7, 8, A, B, C, F, F, G)
	0xFEF00	0x0FFFF	-	0xF17FF	0x0FE00	0xFF300	32	01	R7F102GxE(x = 4, 6, 7, 8, A, B, C, E, F, G)
70									

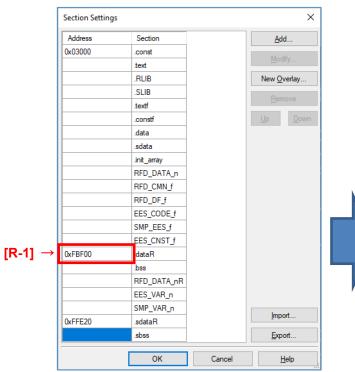
- Example of where to modify

Points that need to be modified from the RL78/G23 (R7F100GLG) settings are listed from "7.3.1". Points that need to be modified are indicated with "[R-x]  $\rightarrow$ ". Refer to the Target MCU List to find the appropriate [R-x] setting for your device. Enter the searched value in [R-x]. (x = 1, 2, 3...)

Example of modifying section settings (start address of RAM)
 (CS+: CC-RL compiler):

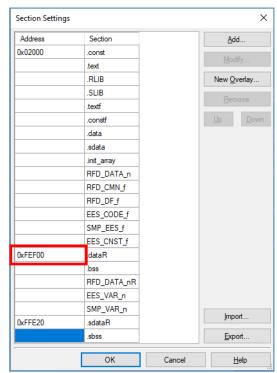
Setting for RL78/G23(RAM: 16 Kbytes)

Example: R7F100GxG



Setting for RL78/G22(RAM: 4 Kbytes)

Example: R7F102GGE



#### 7.4.1 CC-RL Compiler Environment Settings

Points of modifies and examples of modifies when using the CC-RL compiler environments (CS+ and e<sup>2</sup> studio) are described.

#### 7.4.1.1 Section Settings

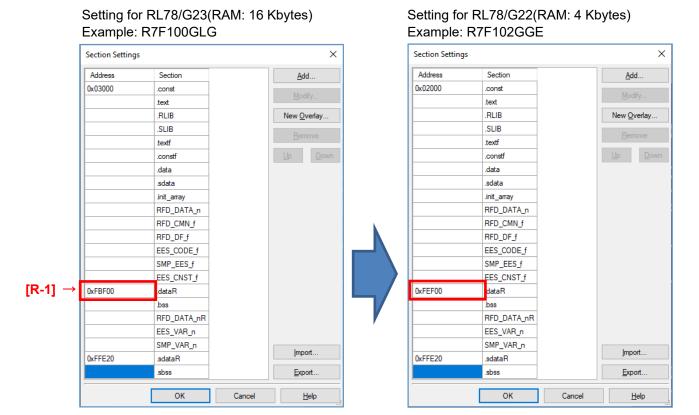
Modify the start address of the RAM area in the section settings.

This example shows the change from RL78/G23 (R7F100GLG) to RL78/G22 (R7F102GGE).

Since the RAM size is changed from 16 Kbytes to 4 Kbytes, modify the start address of RAM from "0xFBF00" to "0xFEF00".

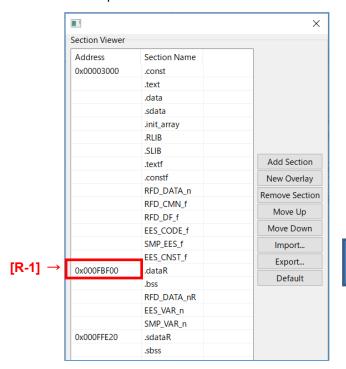
Note: For the start address of the RAM for each product, refer to "R-1" column in the Target MCU List.

- Example of modifying section settings (start address of RAM) in CS+:

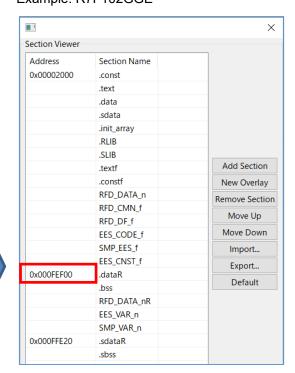


- Example of modifying section settings (start address of RAM) in e<sup>2</sup> studio:

Setting for RL78/G23(RAM: 16 Kbytes) Example: R7F100GLG



Setting for RL78/G22(RAM: 4 Kbytes) Example: R7F102GGE



#### 7.4.1.2 Debug Settings

When using a device other than the one targeted by the sample program, the range of the debug monitor area when using the debugger is different.

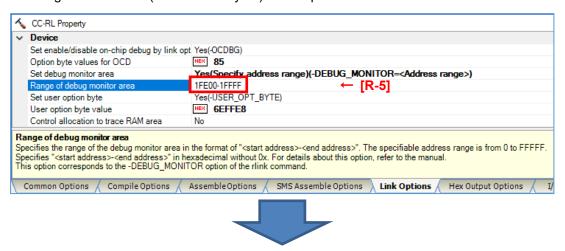
- The start of the "debug monitor area" address sets the address obtained by subtracting "511 bytes (0x1FF)" from the end address of the ROM area. If the end address is "0x1FFFF", set it to "0x1FE00".

This example shows the modify from RL78/G23 (R7F100GLG) to RL78/G22 (R7F102GGE).

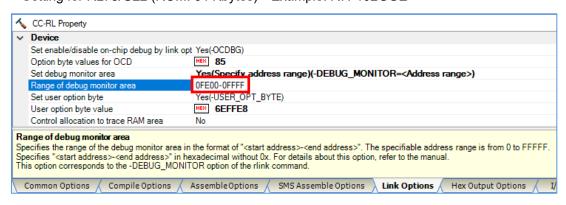
- Set the debug monitor area range to "0x0FE00 - 0x0FFFF".

Note: For information on The start address of the "debug monitor area" for each product, refer to "[R-5]" column in the Target MCU List.

- To set the debug monitor area in CS+, select the [Device] on the "Link Options" tab. Setting for RL78/G23 (ROM: 128 Kbytes) Example: R7F100GLG

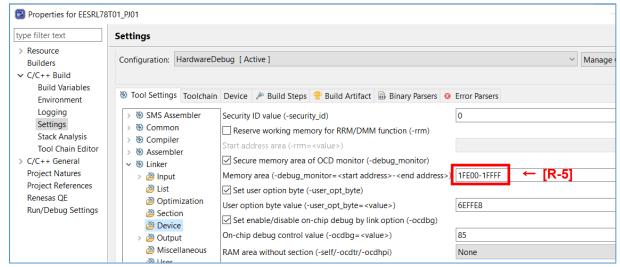


Setting for RL78/G22 (ROM: 64 Kbytes) Example: R7F102GGE



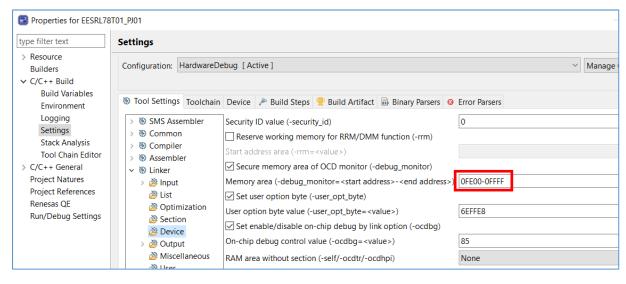
- To set the debug monitor area in e² studio, select the [Device] in the "Linker".

Setting for RL78/G23 (ROM: 128 Kbytes) Example: R7F100GLG





#### Setting for RL78/G22 (ROM: 64 Kbytes) Example: R7F102GGE



#### 7.4.2 IAR Compiler Environment Settings

Points of modifies and examples of modifies when using the IAR compiler environment (Embedded Workbench) is described.

#### 7.4.2.1 Setting Up Header Files for Target Device

The "main.c" and "low\_level\_init.c" provided with EES RL78 Type 01 includes the header files for the target device "RL78/G23: R7F100GLG". When using other RL78/G23 products or RL78/G22 products, the included header file must be changed to the header file for the device used.

```
For RL78/G23(R7F100GLG):
<main.c>
#include "ior7f100glg.h"
<low_level_init.c>
#include "ior7f100glg.h"
#include "ior7f100glg_ext.h"
Example for RL78/G22 (R7F102GGE):
<main.c>
#include "ior7f102gge.h"
<low_level_init.c>
#include "ior7f102gge.h"
#include "ior7f102gge_ext.h"
```

Note: For the device type name of the product, refer to "Target MCU name" column in the Target MCU List.

#### 7.4.2.2 Linker Configuration File Settings

In the sample program "RL78\_G23" folder provided by EES RL78 Type 01, The sections (ROM, RAM, and Data flash range) for RL78/G23 (R7F100GLG) are set.

When using other RL78/G23 products or RL78/G22 products, modify the contents of the sample linker file "sample\_linker\_file.icf" provided for the RL78/G23 of EES RL78 Type 01, because the range of the section settings, and "TraceRAM area" and "debug monitor area" when using the debugger are different.

Target file name: sample\_linker\_file.icf

This example shows the modify from RL78/G23 (R7F100GLG) to RL78/G22 (R7F102GGE).

- Modify the ROM area to the range of 64 Kbytes [0x00000 0x0FFFF]
- Modify the start address to "0xFEF00" because the RAM area is 4 Kbytes [0x0FEF00 0x0FFEFF]
- Modify the end address to "0xF17FF" because the data flash area is 2 Kbytes [0x0F1000 0x0F17FF]

Page 126 of 137

#### (1) Section Settings

Setting for RL78/G23 (ROM: 128 Kbytes, RAM: 16 Kbytes, DF: 8 Kbytes) Example: R7F100GLG

- Notes 1: If the ROM size is larger than 64 Kbytes, the description must be changed as the ROM size increases. For details, please refer to "Examples of ROM\_far" on the next page.
  - 2: Sets the value [R-3] when there is an address value in [R-3] on the Target MCU List. In the case of "-", set the value of [R-2].



Setting for RL78/G22 (ROM: 64 Kbytes, RAM: 4 Kbytes, DF: 2 Kbytes) Example: R7F102GGE

```
define region ROM_near = mem:[from 0x000D8 to 0x0FFFF];
define region ROM_far = mem:[from 0x000D8 to 0x0FFFF];
define region ROM_huge = mem:[from 0x000D8 to 0x0FFFF];
define region SADDR = mem:[from 0xFE20 to 0xFFEDF];
define region RAM_near = mem:[from 0xFEF00 to 0xFFE1F];
define region RAM_far = mem:[from 0xFEF00 to 0xFFE1F];
define region RAM_huge = mem:[from 0xFEF00 to 0xFFE1F];
define region VECTOR = mem:[from 0x00000 to 0x0007F];
define region CALLT = mem:[from 0x00080 to 0x0008F];
define region EEPROM = mem:[from 0xF1000 to 0xF17FF];
```

### - Examples of ROM\_far

The following is an example of entries in ROM\_far for each ROM size. Refer to the row with the same ROM size as the target device. Colored areas indicate values for [R-2] or [R-3].

### When ROM size is 64 Kbytes or less ([R-3] is "-").

ROM [R-2] Value		mem:[from 0x000D8 to [R-2]];
32 Kbytes	0x07FFF	mem:[from 0x000D8 to 0x07FFF];
64 Kbytes	0x0FFFF	mem:[from 0x000D8 to 0x0FFFF];

### When ROM size exceeds 64 Kbytes ([R-3] is not "-").

ROM [R-3] Value		mem:[from 0x000D8 to [R-2]]   mem:[from 0x10000 to 0x1FFFF]  Omitted   mem:[from 0xX0000 to [R-3]];					
96 Kbytes	0x17FFF	mem:[from 0x000D8 to 0x0FFFF]   mem:[from 0x10000 to 0x17FFF];					
128 Kbytes	0x1FFFF	mem:[from 0x000D8 to 0x0FFFF]   mem:[from 0x10000 to 0x1FFFF];					
192 Kbytes	0x2FFFF	mem:[from 0x000D8 to 0x0FFFF]   mem:[from 0x10000 to 0x1FFFF]					
		mem:[from 0x20000 to 0x2FFFF];					
256 Kbytes	0x3FFFF	mem:[from 0x000D8 to 0x0FFFF]   mem:[from 0x10000 to 0x1FFFF]					
		mem:[from 0x20000 to 0x2FFFF]   mem:[from 0x30000 to 0x3FFFF];					
384 Kbytes	0x5FFFF	mem:[from 0x000D8 to 0x0FFFF]   mem:[from 0x10000 to 0x1FFFF]					
		mem:[from 0x20000 to 0x2FFFF]   mem:[from 0x30000 to 0x3FFFF]					
		mem:[from 0x40000 to 0x4FFFF]   mem:[from 0x50000 to 0x5FFFF];					
512 Kbytes	0x7FFFF	mem:[from 0x000D8 to 0x0FFFF]   mem:[from 0x10000 to 0x1FFFF]					
		mem:[from 0x20000 to 0x2FFFF]   mem:[from 0x30000 to 0x3FFFF]					
		mem:[from 0x40000 to 0x4FFFF]   mem:[from 0x50000 to 0x5FFFF]					
		mem:[from 0x60000 to 0x6FFFF]   mem:[from 0x70000 to 0x7FFFF];					
768 Kbytes	0xBFFFF	mem:[from 0x000D8 to 0x0FFFF]   mem:[from 0x10000 to 0x1FFFF]					
		mem:[from 0x20000 to 0x2FFFF]  Omitted					
		mem:[from 0xA0000 to 0xAFFFF]   mem:[from 0xB0000 to 0xBFFFF];					

#### (2) Debug Settings

- The start of the "debug monitor area" address sets the address obtained by subtracting "511 bytes (0x1FF)" from the end address of the ROM area. If the end address is "0x1FFFF", set "0x1FE00".
- The start address of the "TraceRAM area" sets the address obtained by adding "1 Kbyte (0x400)" to the start address of the RAM area. If the start address is "0xFBF00", set "0xFC300".

This example shows a modify from RL78/G23 (R7F100GLG) to RL78/G22 (R7F102GGE).

- Modify the "debug monitor area" range to [from 0x0FE00 size 0x0200]
- Modify the "TraceRAM area" range to [from 0xFF300 size 0x0400]

The point where modifications to the "TraceRAM area" and "debug monitor area" when using the debugger are to be implemented.

Setting for RL78/G23 (ROM: 128 Kbytes, RAM: 16 Kbytes, DF: 8 Kbytes) Example: R7F100GLG



Setting for RL78/G22 (ROM: 64 Kbytes, RAM: 4 Kbytes, DF: 2 Kbytes) Example: R7F102GGE

#### 7.4.3 LLVM Compiler Environment Settings

Points of modifies and examples of modifies when using the LLVM compiler environment (e<sup>2</sup> studio) is described.

#### 7.4.3.1 Linker Script File Settings

In the sample program "RL78\_G23" folder provided by EES RL78 Type 01, The sections (ROM, RAM, and Data flash range) for RL78/G23 (R7F100GLG) are set.

When using other RL78/G23 products or RL78/G22 products, modify the contents of the sample linker script file "sample\_linker\_file.ld" provided for the RL78/G23 of EES RL78 Type 01, because the range of the section settings, "TraceRAM area" and "debug monitor area (OCDROM)" when using the debugger are different.

The following shows the modified part in red text. Refer to the "Target MCU List" and modify the setting values for the target device.

Target file name: sample\_linker\_file.ld

This example shows the modify from RL78/G23 (R7F100GLG) to RL78/G22 (R7F102GGE).

- The start address of the OCDROM (debug monitor area) is set to the address obtained by subtracting "511 bytes (0x1FF)" from the end address of the ROM area. If the end address of the ROM area is "0xFFFF", set the ORIGIN of the OCDROM to "0xFE00" [R-5].
- The size of the ROM area is the area from "0xD8" to the start address of the OCDROM. If the OCDROM start address is "0xFE00", set the ROM LENGTH to "64808", which is the decimal value obtained by subtracting "0xD8" from the OCDROM start address "0xFE00".
- The start address ([R-4]+1) and size of "MIRROR (mirror area)" differs depending on the device. For RL78/G22 (R7F100GGE), set "0xF2000", the start address of the mirror area, to the ORIGIN of the MIRROR. For the LENGTH, set "52992", the decimal value from the start address "0xF2000" to the end address "0xFEEFF" of the mirror area.

For more information about the "Mirror area", please refer to the hardware manual of the device.

- Set the start address of the RAM area "0xFEF00" [R-1] to ORIGIN in the RAM area, and set the LENGTH to "4096", which is 4 KB in decimal.
- "TRACERAM" area uses an area of 1024 bytes from the address obtained by adding 1024 bytes to the start address of RAM, so set the ORIGIN to "0xFF300" [R-6]. Also, since the trace function may not be used or may not be available for some devices, please refer to the hardware manual of the device for details on the TRACERAM area.

Note: The trace function is not available using RL78/G22. The above is described as a configuration example, but is commented out so that the target line is not compiled.

#### (1) MEMORY setting

Setting for RL78/G23 (ROM: 128 Kbytes, RAM: 16 Kbytes, DF: 8 Kbytes) Example: R7F100GLG

```
MEMORY
VEC : ORIGIN = 0x0, LENGTH = 4
IVEC: ORIGIN = 0x4, LENGTH = 188
CALLT0: ORIGIN = 0x80, LENGTH = 0x40
OPT: ORIGIN = 0xC0, LENGTH = 4
SEC_ID: ORIGIN = 0xC4, LENGTH = 10
OCDSTAD: ORIGIN = 0xCE, LENGTH = 10
                                                ← [R-5]
OCDROM: ORIGIN = 0x1FE00, LENGTH = 512
ROM: ORIGIN = 0xD8, LENGTH = 130344
MIRROR: ORIGIN = 0xF3000, LENGTH = 36608
                                                ← [R-4]+1
SADDR: ORIGIN = 0xffe20, LENGTH = 0x000a0
RAM: ORIGIN = 0xFBF00, LENGTH = 16384
                                                ← [R-1]
TRACERAM : ORIGIN = 0xFC300, LENGTH = 1024 \leftarrow [R-6]
```



Setting for RL78/G22 (ROM: 64 Kbytes, RAM: 4 Kbytes, DF: 2 Kbytes) Example: R7F102GGE

```
MEMORY
{

VEC : ORIGIN = 0x0, LENGTH = 4

IVEC : ORIGIN = 0x4, LENGTH = 188

CALLT0 : ORIGIN = 0x80, LENGTH = 0x40

OPT : ORIGIN = 0xC0, LENGTH = 4

SEC_ID : ORIGIN = 0xC4, LENGTH = 10

OCDSTAD : ORIGIN = 0xCE, LENGTH = 10

OCDROM : ORIGIN = 0xFE00, LENGTH = 512

ROM : ORIGIN = 0xD8, LENGTH = 64808

MIRROR : ORIGIN = 0xF2000, LENGTH = 52992

SADDR : ORIGIN = 0xF600, LENGTH = 0x000000

RAM : ORIGIN = 0xFEF00, LENGTH = 4096

/* TRACERAM : ORIGIN = 0xFF300, LENGTH = 1024 */
}
```

Note: The RL78/G22 is not included in compilation because the trace function cannot be used, but only the value should be modified on devices that support the trace function.

#### (2) Set the start address of the RAM area

Setting for RL78/G23 (ROM: 128 Kbytes, RAM: 16 Kbytes, DF: 8 Kbytes) Example: R7F100GLG



Setting for RL78/G22 (ROM: 64 Kbytes, RAM: 4 Kbytes, DF: 2 Kbytes) Example: R7F102GGE

#### 7.4.4 Modifying the Sample Program (Common to CC-RL, IAR and LLVM Compilers)

#### 7.4.4.1 Modifying the Number of Data Flash Memories Used for EES Block

The number of blocks of flash memory differs between RL78/G23 and RL78/G22, which is targeted by the EES RL78 Type01 sample program folder "RL78\_G23". Therefore, to use the number of EEPROM emulation block at least 3 blocks (recommended), the EES block size must be modified to 512 bytes.

Modify the number of data flash memory used for the EES block of RL78/G22 in the "r\_ees\_descriptor.h" file. Modify the EES block size from 4u (1024 bytes) to 2u (512 bytes).

Target file name: r\_ees\_descriptor.h

Setting for RL78/G23 (DF: 8 Kbytes) Example: R7F100GLG

/\* Specifies the number of physical data flash blocks per one virtual block \*/
#define R\_EES\_EXRFD\_VALUE\_U08\_PHYSICAL\_BLOCKS\_PER\_VIRTUAL\_BLOCK (4u)



Setting for RL78/G22 (DF: 2 Kbytes) Example: R7F102GGE

/\* Specifies the number of physical data flash blocks per one virtual block \*/
#define R\_EES\_EXRFD\_VALUE\_U08\_PHYSICAL\_BLOCKS\_PER\_VIRTUAL\_BLOCK (2u)

#### 7.4.4.2 Data Resizing for Each Identifier (data ID)

When the EES block size is modified to 512 bytes, Modify the data size of "type\_Z" in the "r\_ees\_user\_types.h" file because the total data will exceed the recommended size (251 bytes).

For details of the recommended size, Refer to "4.1 Number of Stored User Data Items and Total User Data Size".

Target file name: r\_ees\_user\_types.h

Setting for RL78/G23 (DF: 8 Kbytes) Example: R7F100GLG

```
typedef
          uint8_t
                   type_A[2];
typedef
          uint8_t
                   type_B[3];
typedef
          uint8_t
                   type_C[4];
typedef
         uint8_t
                  type_D[5];
typedef
          uint8_t
                   type_E[6];
typedef
          uint8 t
                   type_F[10];
typedef
          uint8_t
                   type_X[20];
typedef
          uint8 t
                   type_Z[255];
```



#### Setting for RL78/G22 (DF: 2 Kbytes) Example: R7F102GGE

```
typedef
          uint8_t
                   type_A[2];
typedef
          uint8_t
                   type_B[3];
typedef
          uint8 t
                   type_C[4];
typedef
         uint8_t
                   type_D[5];
typedef
         uint8_t
                   type_E[6];
typedef
          uint8_t
                   type_F[10];
typedef
          uint8_t
                   type_X[20];
typedef
          uint8_t
                   type_Z[30];
```

EES RL78 Type 01 8. Revision History

# 8. Revision History

## 8.1 Major Modifications in this Revision

			Description					
Rev.	Date	Page	Summary					
1.00	Jan.12.22	-	Newly created.					
1.01	Dec.28.22	_	Add support of RL78/G22.					
1.10	Apr.28.23		Add support of RL78/G24.					
			Added "7.1.3.2 The Setting of User Definition Macro".					
			Added "7.2.3.2 The Setting of User Definition Macro".					
			Added "7.3 Configurations Modify Procedure for Changing Device".					
1.20	Sep.28.23	-	Add support of LLVM compiler					
		-	Added "7.3 Creating a Project in the Case of Using LLVM Compiler".					
		-	Added "7.4.3 LLVM Compiler Environment Settings".					
1.21	Nov.14.25	-	In the case where a CC-RL compiler or a LLVM compiler is used, the structure of the sample was modified so that the file automatically added by the function of the Integrated Development Environment could be used preferentially.					
		-	Minor errors are corrected, and some descriptions have been improved.					

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